Advanced Power Management Unit

Check for Samples: TPS658600

1 INTRODUCTION

1.1 MAIN FEATURES

- BATTERY CHARGER
 - Complete Charge Management Solution for a Single Cell Li-lon/Li-Pol Cell With Dynamic Power Management and Thermal Foldback.
 - Maximum 1.0A charge current
 - Programmable Adapter and USB Charge Operation
- INTEGRATED POWER SUPPLIES
 - 3 Programmable Step-Down converters
 - Software Controlled Enable/Forced PWM Mode
 - Automatic Power Saving Mode
 - Maximum 1.2A Outputs
 - 11 Programmable General Purpose LDOs
 - 7 With Output Voltages of 1.25V to 3.3V
 - 2 With Output Voltages of 0.725V to 1.5V or 1.25V to 2.586V (factory configurable)
 - 1 "Always On" With Output Voltages of 1.25V to 3.3V
 - 1 With Output Voltage of 1.70V–2.475V
- DISPLAY SUPPORT FUNCTIONS
 - 4 PWM Outputs With Programmable Frequency and Duty Cycle
 - Dual RGB LED Drivers
 - Constant Current WLED Driver
 - 26.5V (max) at 25mA
 - Over-Voltage Protection
 - Programmable Current Level and Brightness Control
- HOST INTERFACE
 - Interrupt Controller With Maskable Interrupts
 - External ADC Triggering and Step-Down Converter Mode Control
- SYSTEM MANAGEMENT
 - Dual Input Power Path
 - USB Current Limiting

- Max 18V Over-Voltage Protection
- Power Good Monitoring on all Supply Outputs
- Software Reset Function
- Hardware On/Off and Reboot Control
- 11 Channel ADC With 3 Operating Modes
 - Single Conversion
 - Peak Detection
 - Averaging

1.2 APPLICATIONS

- Smart Phones
- Portable Navigation Devices
- Portable Media Players





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



1.3 OVERVIEW

The TPS658600 provides an easy to use, fully integrated solution for handheld devices, integrating charge management, multiple regulated power supplies, system management and display functions in a small 6x6 package. The I²C interface enables control of a wide range of subsystem parameters. Internal registers have a complete set of status information, enabling easy diagnostics and host-controlled handling of fault conditions.

1.4 ORDERING INFORMATION(1)

T _A	PART NUMBER (2) (3)	PACKAGE ⁽⁴⁾	PACKAGE DESIGNATOR	ORDERING ⁽²⁾	PACKAGE MARKING
–40°C to 85°C	TPS658600	MicroStar BGA	ZQZ	TPS658600	TPS658600

⁽¹⁾ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

⁽²⁾ The TPS658600 is only available taped and reeled. Quantities are 2,500 devices per reel.

⁽³⁾ Devices with distinct part numbers have unique factory configurations for supply defaults, sequencing and other functions. Consult the factor for configuration information for each part number.

⁽⁴⁾ This product is RoHS compatible, including a lead concentration that does not exceed 0.1% of total product weight, and is suitable for use in specified lead-free soldering processes. In addition, this product uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.



2 ELECTRICAL SPECIFICATIONS

2.1 ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted) (1)

	VALUE / UNITS
AC and USB with respect to AGND1	–0.3 V to 18 V
ANLG1, ANLG2, ANLG3 with respect to AGND2	–0.3 V to 6.5 V
V(SYS), V(VIN_CHG) with respect to AGND1	–0.3 V to 6.5 V
VIN_LDO01, VIN_LDO23, VIN_LDO4, VIN_LDO678, VIN_LDO9 with respect to AGND1	–0.3 V to 6.5 V
ADC_REF with respect to AGND2	-0.3 V to 3.6 V
RTC_OUT with respect to V(SYS)	–5.5 V to 3.6 V
RTC_OUT with respect to AGND1	–0.3 V to 3.6 V
LDO0, LDO1, LDO2, LDO3, LDO4, LDO5, LDO6, LDO7, LDO8, LDO9, V2V2 and TS with respect to AGND1	-0.3 V to 3.6 V
V32K with respect to AGND1	-0.3 V to 3.6 V
TS with respect to V2V2	–2.3 V to 0.3 V
SM0, L0, VIN_SM0 with respect to PGND0	–0.3 V to 6.5 V
SM1, L1, VIN_SM1 with respect to PGND1	–0.3 V to 6.5 V
SM2, L2, VIN_SM2 with respect to PGND2	–0.3 V to 6.5 V
SM3 , L3 with respect to PGND3	–0.3 V to 29 V
SM3SW with respect to PGND3	-0.3 V to 29 V
FB3 with respect to PGND3	-0.3 V to 0.5 V
V(BAT) with respect to AGND1, Battery power only	-0.3 V to 4.6 V
All other pins (except AGNDn and PGNDn) with respect to AGND1	–0.3 V to 6.5 V
AGND2, AGND3, , DGND1, DGND2DT, PGND0, PGND1, PGND2, PGND3 with respect to AGND1	-0.3 V to +0.3 V
Input Current, AC pin	Defined by ILIM
Input Current, USB pin	Defined by ILIM
Output continuous current, SYS, VIN_CHG pins	2500 mA
Output continuous current, BAT pin	-3000 mA
Continuous Current at L0, PGND0, L1, PGND1	1500 mA
Continuous Current at L3, PGND3	1000 mA
Continuous Current at L2, PGND2	2000 mA
Operating free-air temperature, T _A	-40°C to 85°C
Maximum junction temperature, T _J	125°C
Storage temperature, T _{STG}	-65°C to 150°C
Lead temperature 1,6 mm (1/16-inch) from case for 10 seconds	260°C
HBM rating , all pins	2 kV
MM rating, all pins	100 V

⁽¹⁾ Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2.2 DISSIPATION RATINGS

PACKAGE	Psi_Jb	T _A ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 55°C POWER RATING	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING
ZQZ	25°C/W	4000 mW	40.0°C/W	2800 mW	2200 mW	1600 mW



2.3 RECOMMENDED OPERATING CONDITIONS

	MIN	MAX	UNIT
AC and USB with respect to AGND1	4.30	16.5 ⁽¹⁾	V
V(SYS) with respect to AGND1	2.9	5.5	V
V(BAT) with respect to AGND1, battery power only	2.9	4.6	V
V(BAT) with respect to AGND1, battery connected, AC or USB power selected, Selected power source >2.9V	2.15	4.6	V
ANLG1,ANLG2, ANLG3 with respect to AGND2	0	2.6	V
VIN_LDO01, VIN_LDO23, VIN_LDO678, VIN_LDO4, VIN_LDO9 with respect to AGND1	Greater of : 1.7V OR Minimum input voltage required for LDO/Converter operation outside dropout region	5.5	V
VIN_SM0 with respect to PGND0	Greater of: 2.3V OR Minimum input voltage required for LDO/Converter operation outside dropout region. 2.9V to meet parametric specifications.	5.5	V
VIN_SM1 with respect to PGND1		28	V
VIN_SM2 with respect to PGND2		28	V
VIN_SM4 with respect to PGND4		28	V
SM3 with respect to PGND3		28	V
GPIOx with respect to AGND1	0	5.5	V
All other pins (except AGNDn and PGNDn) with respect to AGND1	0	5.5	V
Operating free-air temperature, T _A	-40	85	°C
Maximum junction temperature, T _J , functional operation	-40	125	°C
Maximum junction temperature, T _J , electrical characteristics	0	125	°C
External supply ramp rate, AC or USB pins	1 V/mSec	1 V/µSec	

⁽¹⁾ Thermal operating restrictions are reduced or avoided if input voltage does not exceed 5V.



2.4 **ELECTRICAL CHARACTERISTICS**

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
QUIESCENT (CURRENT - V(BAT) = 4.2V NO EXTERNAL LOADS A	T SYS PIN OR SUPPLY OUTPUTS				
Q(ON)	Quiescent current, 6586x in normal or sleep mode. All supplies, peripherals and charger off	Power path active, control logic in low power mode ⁽¹⁾			375	μΑ
Q(DIGITAL)	Quiescent current, control logic	Control logic in high power mode ⁽²⁾	584	716	870	μΑ
		SM0, SM1: enabled, PFM mode, from SYS pin		14	25	μΑ
	ONO ONA ONO secretical existence of secret	SM2: enabled, PFM mode, from SYS pin		19	32	μΑ
Q(SMn)	SM0, SM1, SM2 operating quiescent current	SM0, SM1, SM2: enabled, PWM mode, from VINSMn pin		6		mA
		disabled via I ² C		1		μΑ
		I(LDOx) = no external load		24	29	μΑ
	LDO quiescent current, All but one LDOx	I(LDOx) = -1 mA		24	150	μΑ
Q(LDOx)	disabled	I(LDOx) = -50 mA		160		μΑ
		LDO disabled, T _J = 85°C		1	3	μΑ
		SM3 enabled, not switching		15	30	μΑ
Q(SM3)	SM3 operating quiescent current ⁽³⁾	Enabled, switching			200	μΑ
		Disabled via I ² C		1		μΑ
		Conversion active		1	1	mA
I _{Q(ADC)}	ADC operating quiescent current	Not converting, waiting for trigger		170	1	μΑ
		ADC disabled via I ² C		1		μA
		RTC_OUT LDO enabled		27	45	μA
I _{Q(RTC)}	RTC_OUT pin quiescent current	RTC_OUT disabled via I^2 C, T_J = 85°C . Externally applied ⁽⁴⁾ $V(RTC_OUT)$ = 2 V supplies real time clock counters and xtal oscillator			15	μΑ
		32k buffer enabled, 100 pF external load			24	μA
Q(V32K)	V32K supply bias current , 32k buffer enabled	Disabled via I ² C			8	μA
		Charger enabled, termination detected		40	50	μA
I _{Q(CHG)}	Charger quiescent current	Charger enabled, termination disabled, charge current=0 ⁽³⁾			2	mA
.,		Charger disabled		10	20	μA
² C INTERFAC	E TIMING – SDA, PSDA, PSCLK, SCLK ⁽³⁾					
T _R	SCLK/SDATA rise time				300	ns
T _F	SCLK/SDATA fall time				300	ns
T _{W(H)}	SCLK pulse width high		600			ns
T _{W(L)}	SCLK Pulse Width Low		1.3			μs
T _{SU(STA)}	Setup time for START condition		600			ns
T _{H(STA)}	START condition hold time after which first clock pulse is generated	Pull-up resistors connected to 2.2V	600			ns
T _{SU(DAT)}	Data setup time		100			ns
T _{H(DAT)}	Data hold time		0			ns
T _{SU(STOP)}	Setup time for STOP condition		600			ns
$T_{(BUF)}$	Bus free time between START and STOP condition		1.3			μs
F _{SCL}	Clock Frequency	_			400	kHz
² C BUFFERS	– SDA, PSDA, PSCLK, SCLK					
V _{IL(I2C)}	Low level input voltage				0.4	V
V _{IH(I2C)}	High level input voltage		1.15			V
V _{OL(I2C)}	Low level output voltage	SDA, PSDA configured as output, I _{OL} =3mA			0.4	V
I _{O(I2C)}	Maximum load current(3)	SDA, PSDA configured as output			8	mA
LKG(I2C)	Input current	V(pin)=5V or 0V			1.0	μΑ
C _{I2C}	Input pin capacitance	SDAT, SCLK, PSDAT, PSCLK pins		10		pF
C _{I2CBUS}	I ² C bus capacitance	SDAT, SCLK, PSDAT, PSCLK		400		pF

- (1) Control logic in low power mode when all functions are off and no I²C communication is on going
 (2) Control logic in high power mode when one of the following events happen: 6586x in power-up/rtc/rtc_on/supplyseq states, any converter in PWM mode, SM3 enabled, PWM driver enabled, ADC conversion on-going, I²C communication on-going, voltage transition for DVM supplies on-going, charger on, AC or USB supply detected, initial power-up cycle.
- Not production tested.
- External voltage supplied by supercap or coin cell connected to RTC_OUT pin, see application diagram for details.



ELECTRICAL CHARACTERISTICS (continued)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
DIGITAL INPU	T BUFFERS: RESUME, SM0EN, SM1EN, HOTRST, L	LDO4EN, SYNCEN				
V _{IL(DIG)}	Low level input voltage				0.4	V
/ _{IH(DIG)}	High level input voltage		1.15			V
LKG(DIG)	Input current	V(pin)=5V			0.1	μΑ
	Internal recistor	RESUME pin , pull-down to AGND	55	100	150	kΩ
R _{DIG}	Internal resistor	HOTRST pin, pull-up to V2V2	55	100	150	K12
PUSH-PULL C	OUTPUT BUFFERS, USER SELECTABLE OUTPUT V	OLTAGE – NORTC, NOPOWER	•		-	
V _{BFRPWR}	Buffer positive supply	Internally connected to V32K pin	1.1	to 3.3		V
.,	Law law Law tank with an	I _{OL} = 3 mA, V32K = 1.5 V			0.6	
V _{OL(OBFR)}	Low level output voltage	I _{OL} = 10 μA, V32K > 1.1 V			0.1	V
· · · · · · · · · · · · · · · · · · ·	High level output voltage, referenced to output	I _{OH} = 1.4 mA, V32K = 1.5 V	V32K-0.6			V
V _{OH(OBFR)}	buffer supply, NORTC	I _{OH} = -10 μA, V32K = 1.1 V	V32K-0.11			V
V	High level output voltage, referenced to output	I _{OH} = 1.4 mA, V32K = 1.5 V	V32K-0.6			
V _{OH(OBFR)}	buffer supply,NOPOWER	I _{OH} = -10 μA, V32K = 1.1 V	V32K-0.11			V
I _{OL(OBFR)}	Maximum low level sink current load ⁽¹⁾	V(pin) = 2.5 V			5	mA
I _{OH(OBFR)}	Maximum high level source current load ⁽¹⁾	V(pin) = 0 V	-5			mA
	OUTPUT BUFFERS – INT		•			
	Landard colored and	I _{OL} = 3 mA, V32K = 1.5 V			0.6	
$V_{OL(OBFR)}$	Low level output voltage	I _{OL} = 10 μA, V32K > 1.1 V			0.1	V
I _{LKG(OBFR)}	Output leakage current	Output buffer, open-drain mode, V(pin)=5.5V			0.1	μΑ
	OUTPUT BUFFERS - LDO4PG, SM0PG, SM1PG, CH0	GSTAT				
		I _{OL} = 3 mA			0.6	
V _{OL(DBFR)}	Low level output voltage	I _{OL} = 10 μA			0.1	V
	High level output voltage , buffer configured as	I _{OH} = 3 mA	1.5			
$V_{OH(DBFR)}$	push-pull via I ² C	I _{OH} = -10 μA	1.8			V
I _{OL(DBFR)}	Maximum low level sink current load ⁽¹⁾	V(pin) = 2.5 V			5	mA
I _{OH(DBFR)}	Maximum high level source current load ⁽¹⁾	V(pin) = 0 V	-5			mA
	T BUFFER , V(32K)=1.7V (min), UNLESS OTHERWI	SE STATED	1			
V _{32B}	Externally applied bias rail for output driver ⁽¹⁾	Buffer supply voltage	1.0		3.6	V
		V(32K) = 1.1 V, I _{OL} = 100 μA			0.05	
V _{OL}	Output low level	V(32K) = 1.1 V, I _{OL} = 1 mA			0.2	V
02	·	V(32K) = 1.5 V, I _{OL} = 5 mA			0.5	
		V(32K) = 1.1 V, I _{OH} = -1 μA	V32K-0.05			
V _{OH}	Normal operation	V(32K) = 1.5 V, I _{OH} = 5 mA	V32K-0.5			V
T _F , T _R	Rise/fall time	32 kHz clock driving 50pF load cap		15		ns
r - 1X		Peak to peak		15		
V_{JITTER}	Output jitter	RMS	<u> </u>	15		ns
32kHz CLOCK	AND 32K SWITCHING TIMING	<u> </u>	1			
-		Frequency within 2% of typical value, frequency defined by XTAL			٦	_
I _{XTAL}	XTAL oscillator stabilization time ⁽¹⁾	characteristics			2	S
F _{32K}	Internal 32 kHz clock	Frequency	28	32	36	kHz
INTERNAL RE	FERENCES AND POR					
V _{UVLO}	Internal UVLO detection threshold	V(2V2) decreasing	-3%	1.85	3%	V
V _{UVLO_HYS}	UVLO detection hysteresis	V(2V2) increasing from decreasing trigger point		120		mV
V _{O(2V2)}	Output Voltage	Always on,	2.1	2.2	2.3	V
I _{SH2V2}	Short Circuit current limit	V(2V2)=0v	18			mA

⁽¹⁾ Not production tested.



ELECTRICAL CHARACTERISTICS 2.5

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
RTC_OUT LDO						
		Output Voltage, Selectable via I ² C ⁽¹⁾	V _{O(RTC_OUT)} TYP 2.7,2	=1.25, 1.50, .85,3.1,3.3	1.8, 2.5,	V
		Dropout voltage, I(RTC_OUT) = -15 mA V(SYS) = 2.8 V			600	mV
V _{O(RTC_OUT)}	RTC_OUT output voltage	Total accuracy, V(AC):2V to 4.7V, -15mA load, V(BAT1)=V(BAT2)=V(USB)=0V	-5%		5%	
		Load regulation, V(AC)=3.5V, load: $1mA \rightarrow -15mA$		1%		
		Line regulation, 5mA load,V(AC): 3.5V→18V, V(BAT1) =V(BAT2) =V(USB) =0V		1%		
SHRTC	Short Circuit current limit		20			mA
V _(RTCGOOD)	RTC_OUT power good fault detection	Falling RTC_OUT pin voltage, set via I ² C	2.3	2.35	2.45	V
*(RTCGOOD)	threshold	railing KTC_OOT pill voltage, set via TC	1.8	1.90	2.0	•
V _{HYS(RTC)}	Power good fault detection hysteresis	Rising RTC_OUT pin voltage (Referenced to $V_{(RTCGOOD)}$ threshold)	50	75	131	mV
V_{UVLO_RTC}	Internal RTC UVLO detection threshold	VRTC Decreasing	-10%	1.5	10%	V
V _{UVLO_RTC_HYS}	UVLO detection hysteresis	VRTC Increasing	100	150	200	mV
BOOT-UP TIMIN	G					
T _{POR}	Power-on-reset delay ⁽²⁾	Fixed time, measured from 2V2>UVLO	7.2	8	8.8	ms
т	Doct up time	Fixed time		500		
Т _{воот}	Boot-up time	Accuracy, referenced to T _{BOOT(tTYP)}	-10%		10%	ms
T _{HOTPLUG}	Hot plug deglitch time	Fixed time	675	750	825	ms
T _{WAKEUP}	Wakeup pulse width	Fixed time	225	250	275	μs
T _{CHECK}	RTC check wait time	Fixed time	2.7	3	3.3	ms
T _{MAX}	RTC_ON watchdog timer	Fixed time	4:	×T _{NORTC}	1	ms
-	NOTE IN THE L	Fixed time		10		
T _{NORTC}	NORTC pin pulse width value	Accuracy, relative to T _{NORTC (TYP)} (2)	-10%		10%	ms
	NOROUSE : I III	$T_{NOPOWER} = K_{NOPOWER} \times C_{NOPOWER}$		0.25		
K _{NOPOWER}	NOPOWER pin pulse width const.	Pulse width accuracy, C _{NOPOWER} < 400nF	-25%		25%	ms/nF
T _{WAIT}	Reboot and sleep request timeout	Fixed time	18	20	22	ms
T _{WAIT1}			4.5	5	5.5	ms
T _{SYNCEND}	Synchronization complete delay	Measured from all supplies synchronized	4.5	5	5.5	ms
T _{SYNCDLY}	Supply sync delay time	Regulator specific. See Table 3-17	T _{SYNCDLY(TYP)} = 20,	1.25, 2.5, 3 32, 40, 64	.75, 15,	ms
	,	Accuracy, relative to T _{SYNCDLY(TYP)} (2)	-10		+10	
POWER GOOD	AND THERMAL FAULT DETECTION					
T _{DGL(PGFLT)}	Power good deglitch time	Applies to all non-masked power good signals, output voltage falling edge.	4	5	6	ms
T _{SHUT}	Thermal shutdown	Increasing junction temperature		150		°C
T _{HYS(SHUT)}	Thermal shutdown hysteresis	Decreasing junction temperature		30		°C
T _{DGL(TSHUT)}	Thermal shutdown detection delay	Rising temperature	15	20	25	μs

⁽¹⁾ Setting the RTC_OUT output voltage below the RTC_OUT power good threshold will result in a NORTC pulse being always generated during reboot cycles or when exiting sleep.

Setting the RTC_OUT output voltage below VUVLO_RTC disables the use of the internal real time clock counter and xtal oscillator.

(2) Not production tested.



ELECTRICAL CHARACTERISTICS (continued)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
ROL TIMING					
RESUME pulse width high ⁽¹⁾		550			ms
RESUME pulse width low ⁽¹⁾		1500			ms
EBOOT CONTROL				•	
Reboot control threshold	Reboot started when normal state is set and V(HOT_RST) < V_REBOOT for t > T_DT(HRST)			0.4	V
HOT_RST max pulse width				60	ms
HOT_RST min detection pulse width	HOT_RST deglitch	4		16	μs
PPLY DETECTION AND STATUS					
Minimum austam valtam datastica threahald	System voltage V(SYS) decreasing.		3.0		V
Minimum system voltage detection threshold	Total accuracy, referenced to V(LOWSYS)TYP	-2		2	%
Minimum system voltage detection hysteresis	V(SYS) increasing from decreasing trigger point		200		mV
Minimum system voltage detection deglitch time	V(SYS) decreasing		5		ms
Input voltage detection threshold. Input voltage increasing, referenced to battery voltage	AC detected when V(AC)–V(BAT) > $V_{\rm IN(DT)}$ AND V(AC) > $V_{\rm ACMIN}$ USB detected when V(USB)–V(BAT) > $V_{\rm IN(DT)}$	180			mV
Input voltage removal threshold. Input voltage decreasing, referenced to battery voltage	AC not detected: when V(AC)–V(BAT) < $V_{IN(NDT)}$ USB not detected when V(USB)–V(BAT) < $V_{IN(NDT)}$			65	mV
AC detection threshold relative to CND	AC voltage decreasing , AC not detected when V(AC) < V _{ACMIN}		3.5		V
AC detection threshold, relative to GND	Hysteresis, AC voltage increasing		200		mV
AC Power detected deglitch	AC voltage increasing		22.5		ms
USB Power detected deglitch	USB voltage increasing		5.5		ms
Input over voltage detection		5.8	6.0	6.3	V
Input over voltage detection delay	Rising AC or USB voltage		100		μs
PARATOR					
Voltage threshold	Enabled at sleep mode not set	1.21	1.245	1.28	V
Bias current ⁽¹⁾	Always On			5	μΑ
Propagation time	V(COMP):0→1.5V→0, measured from input to NOPOWER:HI→LO		50		μs
	RESUME pulse width high ⁽¹⁾ RESUME pulse width low ⁽¹⁾ EBOOT CONTROL Reboot control threshold HOT_RST max pulse width HOT_RST min detection pulse width PPLY DETECTION AND STATUS Minimum system voltage detection threshold Minimum system voltage detection deglitch time Input voltage detection threshold. Input voltage increasing, referenced to battery voltage Input voltage removal threshold. Input voltage decreasing, referenced to battery voltage AC detection threshold, relative to GND AC Power detected deglitch USB Power detected deglitch Input over voltage detection Input over voltage detection delay PARATOR Voltage threshold Bias current ⁽¹⁾	RESUME pulse width high ⁽¹⁾ RESUME pulse width low ⁽¹⁾ Reboot control Reboot control threshold Reboot started when normal state is set and V(HOT_RST) < V_REBOOT for t > TDT(HRST) HOT_RST max pulse width HOT_RST min detection pulse width HOT_RST deglitch PPLY DETECTION AND STATUS Minimum system voltage detection threshold Minimum system voltage detection hysteresis Minimum system voltage detection deglitch time Input voltage detection threshold. Input voltage increasing, referenced to battery voltage AC detected when V(USB)-V(BAT) > V_INIOT) AND V(AC) > V_ACMIN USB detected when V(USB)-V(BAT) > V_INIOT) USB not detected when V(USB)-V(BAT) < V_INIOT) USB not dete	RESUME pulse width high ⁽¹⁾ RESUME pulse width low ⁽¹⁾ REBOOT CONTROL Reboot control threshold Reboot started when normal state is set and V(HOT_RST) < V_{REBOOT} for V(SST) V(HOT_T) V(HOT_T)	RESUME pulse width high ⁽¹⁾ RESUME pulse width low ⁽¹⁾ REBOOT CONTROL Reboot control threshold V(FIOT_RST) < V_REBOOT for t > T_DTYHIST) HOT_RST max pulse width HOT_RST deglitch 4 PPLY DETECTION AND STATUS Minimum system voltage detection threshold Time with time V(SYS) increasing from decreasing trigger point 200 Minimum system voltage detection deglitch time V(SYS) decreasing trigger point 200 Minimum system voltage detection threshold. Input voltage increasing, referenced to battery voltage decreasing, referenced to battery voltage decreasing, referenced to battery voltage decreasing, referenced to battery voltage by V(SYS) decreasing V(SYS) V _{N(N(DT)} AND V(AC) > V _{ACMIN} USB detected when V(AC)-V(BAT) > V _{N(N(DT)} AND V(AC) > V _{ACMIN} USB detected when V(LOSB)-V(BAT) > V _{N(N(DT)} AND V(AC) > V _{ACMIN} USB detected when V(LOSB)-V(BAT) > V _{N(N(DT)} AND V(AC) > V _{ACMIN} USB detected when V(LOSB)-V(BAT) > V _{N(N(DT)} AND V(AC) > V _{ACMIN} USB detected when V(LOSB)-V(BAT) > V _{N(N(DT)} AND V(AC) > V _{ACMIN} USB detected when V(LOSB)-V(BAT) > V _{N(N(DT)} AND V(AC) > V _{ACMIN} USB detected when V(LOSB)-V(BAT) > V _{N(N(DT)} AND V(AC) > V _{ACMIN} USB detected when V(LOSB)-V(BAT) > V _{N(N(DT)} AND V(AC) > V _{ACMIN} USB detected when V(LOSB)-V(BAT) > V _{N(N(DT)} AND V(AC) > V _{ACMIN} USB detected when V(LOSB)-V(BAT) > V _{N(N(DT)} AND V(AC) > V _{ACMIN} USB detected when V(LOSB)-V(BAT) > V _{N(N(DT)} AND V(AC) > V _{ACMIN} USB detected when V(LOSB)-V(BAT) > V _{N(N(DT)} AND V(AC) > V _{ACMIN} USB detected when V(LOSB)-V(BAT) > V _{N(N(DT)} AND V(AC) > V _{ACMIN} USB detected when V(LOSB)-V(BAT) > V _{N(D(DT)} AND V(AC) > V _{ACMIN} USB detected detected: when V(AC) < V _{ACMIN} V _{AC} A C not detected when V(AC) < V _{ACMIN} USB detected when V(AC) < V _{ACMIN} USB detected when V(AC) < V _{ACMIN} USB detected when V(AC) < V _{ACMIN} V _{AC} A C not detected when V(AC) < V _{ACMIN} V _{AC} A C not detected when V(AC) < V _{ACMIN} USB S detected when	RESUME pulse width high ⁽¹⁾ RESUME pulse width low ⁽¹⁾ REBOOT CONTROL Reboot control threshold Reboot control threshold REDOT CONTROL Reboot control threshold Reboot started when normal state is set and V(HOT_RST) < V_REBOOT for t > To Trevest) O.4 HOT_RST max pulse width ROT_RST deglitch A 1 16 PPLY DETECTION AND STATUS System voltage V(SYS) decreasing. Total accuracy, referenced to V(LOWSYS)TYP -2 2 V(SYS) increasing from decreasing trigger point 200 V(SYS) decreasing Input voltage detection thysteresis Roterasing, referenced to battery voltage Input voltage detection threshold. Input voltage decreasing, referenced to battery voltage Input voltage removal threshold. Input voltage decreasing, referenced to battery voltage AC detected when V(AC)-V(BAT) > V_NOOT) AC ont detected: V(USB)-V(BAT) < V_NONDT) AC voltage increasing AC not detected when V(AC) < V_ACMIN AC voltage decreasing, AC not detected when V(AC) < V_ACMIN AC voltage decreasing, AC not detected when V(AC) < V_ACMIN AC voltage decreasing AC voltage increasing AC voltage incr

⁽¹⁾ Not production tested.



2.6 **ELECTRICAL CHARACTERISTICS**

	PARAMETER	TEST CONDITIONS	3	MIN	TYP	MAX	UNIT
POWER PA	TH CURRENT LIMIT AND PROTECTION FUNCTIO	NS					
		Selected Input switch not in dropout 12C	-40°C < T _A < 85°C	90		100	
USB100	Selected input current limit, applies to USB input only	Selected Input switch not in dropout. I ² C settings: USBMODE=HI, USBLIMIT=LO	-25°C < T _A < 85°C	92		100	mA
USB500	Only	Selected Input switch not in dropout. I ² C setting: USBLIMIT=HI	s: USBMODE=HI,	435		500	mA
	Colorated input august limit applies to AC input	Input current limit range, AC input			2.75		Α
	Selected input current limit, applies to AC input	Total accuracy, relative to I _{INLIM(TYP)}		-20%		20%	
INLIM	Colorated input augment limit applies to LICD input	Input current limit range, USB input configured v	with USBMODE=LO		2.11		Α
	Selected input current limit, applies to USB input	Total accuracy, relative to I _{INLIM(TYP)}		-12.5%		12.5%	
T _{OVSH}	Input current limit transient time	Load at SYS pin: 80% of current limit value to 1 ($I_{\rm INLIM}$, $I_{\rm USB100}$ or $I_{\rm USB500}$). Time measured from lo within regulation limits.			20		μs
I _{OVSHPKUSB}	Input current limit overshoot	Load at SYS pin: 80% of current limit value to 1. ($I_{\rm INLIM}$, $I_{\rm USB100}$ or $I_{\rm USB500}$), t < $T_{\rm OVSH}$	20% of regulation value		20%		
V _{SH(SYS)}	SYS power path Short Circuit detection threshold	All power path switches set to OFF if V(SYS) <	V _{SH(SYS)}	1.6	1.8	2.0	V
R _{FLT(USB)}	SYS short circuit recovery pull-up resistor	V(SYS) < V _{SH(SYS)} , internal resistor connected from	om USB to SYS		550		Ω
R _{FLT(AC)}	SYS short circuit recovery pull-up resistor	V(SYS) < V _{SH(SYS)} , internal resistor connected from	om AC to SYS		550		Ω
I _{BATSYS}	Battery switch over-current detection			2.18		2.54	Α
T _{DGL(BATSYS)}	Battery switch over-current detection delay	Short circuit detection blanked for TDGL(BATS) switch: OFF->ON or initial sys power path enable		100	110	120	ms
DOL(BATOTO)	····· ,	Battery switch already turned on or sys power p	ath enabled		1		ms
I _{FLT(SYS)}	Battery switch over-current recovery pull-up current source	$V(BAT) - V(SYS) > V_{OC(SYS)}$, internal current sou SYS	rce connected from BAT to		30		mA
V _{SUP(SYS)}	Supplement detection threshold	Battery switch ON at V(BAT)-V(SYS) > VSUP(SYS)		40			mV
V _{SUPNDT(SYS)}	Supplement mode not detected threshold	Battery switch OFF at V(BAT)-V(SYS) <v<sub>SUPNDT(3</v<sub>	SYS)	7			mV
POWER PA	TH INTEGRATED MOSFETS CHARACTERISTICS					<u> </u>	
V _{ACDO}	AC switch dropout voltage	$V_{ACDO} = V(AC)-V(SYS)$; $V(AC)=4V$ AC input curl $I_{O(SYS)} = 1.0A$	rent limit set to 2.0A (typ)			190	mV
V _{USBDO}	USB switch dropout voltage	V _{USBDO} = V(USB)-V(SYS); V(USB)=4.6V	I(SYS)+I(BAT)= 0.425A I(SYS)+I(BAT)= 85mA			240 240	mV
V _{BATDODCH}	Battery Switch dropout voltage, discharge	V _{BATDODCH} = V(BAT)-V(SYS), V(BAT)=3V, I(BAT)= 1A	(, (40	155	mV
POWER PA	TH TIMING CHARACTERISTICS	, · · · ·				<u> </u>	
T _{SW(ACBAT)}	Switching from AC to BAT	No USB, AC power removed			150		μs
T _{SW(USBBAT)}	Switching from USB to BAT	No AC, USB power removed			150		μs
	TH DISCHARGE SWITCHES						
I _{DCH(AC)}	AC pin discharge current	Always ON, V(AC) > 1 V			100		μA
I _{DCH(USB)}	USB pin discharge current	Always ON, V(USB) > 1 V			100		μA
	SM2 DC/DC CONVERTERS					I	
	Low input voltage detection threshold, input voltage	Converter turned OFF at V(VIN_SMn) < V _{SMUV}				2.0	V
V _{SMUV}	decreasing	Hysteresis , rising input voltage			100		mV
	High side MOSFET on-resistance	V _{IN_SMx} = 3.6V, 100% duty cycle			200		mΩ
R _{DS(ON)}	Low side MOSFET on-resistance	V _{IN_SMx} = 3.6V, 0% duty cycle			200		mΩ
I _{LK_HS}	High side leakage current					1	μA
I _{LK_LS}	Low side leakage current	T _J = 85°C				1	μA
I _{LIM}	High side and low side current limit	2.9V ≤ V _{IN_SMx} ≤ 5.5V	SM0, SM1 SM2 (snubber enabled)	1550 1550	1860		mA
¢	Oscillator fraguency	PWM mode	OWIZ (SHUDDEL EHADIEU)	1550	1860	0.475	NAL I-
t _{sw}	Oscillator frequency	Power fault detection, Voltage decreasing, refer	enced to programmed	2.025 -13.0%	2.25 -10%	2.475 -7.0%	MHz
V_{SMPG}	Power good threshold	output voltage					
		Hysteresis, voltage increasing, referenced to V_S	MPG		5%		



ELECTRICAL CHARACTERISTICS (continued)

	PARAMETER	TEST CONDITIONS	5	MIN	TYP	MAX	UNIT
			SM0, low range, 25mV steps	V _{O(SMx)TYP} = 0).725 to 1.	.50	
	Adjustable output voltage range, Selectable via I ² C	VIN_SMx = 2.9V to 5.5V	SM1, high range, 50mV steps	V _{O(SMx)TYP} =	1.45 to 3.	0	٧
V _{O(SMx)}			SM2, high range, 50mV steps	V _{O(SMx)TYP} =	:3.0 to 4.5	5	
	Output Voltage Accuracy, relative to VO(SMx)TYP	$V_{IN_SMx} = 2.9V$ to 5.5V, PFM mode		-1%	1%	3%	
	output voltage / toodide); Toldino to vo (olim/)***	V_{IN_SMx} = 2.9V to 5.5V, PWM mode, 0mA < I_{OUT}	< 1A	-2%		2%	
	DC output voltage load regulation	PWM mode, VIN_SMn>2.7V, Load<1A			0.25		%/A
	DC output voltage line regulation	V_{IN_SMx} = VOUT + 0.5V (min. 2.5V), PWM mode	VIN_SMn>2.7V, Load<1A		0.1		%/V
K _{RAMP(SMx)}	Voltage change ramp constant	Value set via I ² C, available options:		SM0, SM values:Instant 0.22, 0.44, 0.8 7.	38, 1.76, 3		mV/μs
t _{Start}	Start-up time	Time to start switching, measured from end of I ² C command enabling converter			210		μs
t _{Ramp}	V _{OUT} Ramp UP time	Time to ramp from 5% to 95% of V_{OUT}			250		μs
R _{DCH}	Discharge switch resistance	SMx disabled			250		Ω
I _{PFM(ENTER)}	Load current to enter PFM mode	V _{IN_SMx} = 2.9V to 5.5V, duty cycle > 85%		VIN_SM x/ 34Ω			А
C _{LC}	External LC capacitor ⁽¹⁾			4.7		22	μF
L _{LC}	External LC inductor ⁽¹⁾			1.5		4.7	μH
C _{SMINP}	External Input capacitor ⁽¹⁾			10		47	μF
LDO'S : LD	00, LD01, LD02, LD03, LD04, LD05, LD06, LD07	7, LDO8, LDO9					
V _{INMIN}	Input voltage range ⁽¹⁾	Electrical characteristics over the output current	range IO(LDOx)	2.3		5.5	٧
VINMIN	input voltage range	Electrical characteristics specified , max load cu	rrent = 75mA	1.7		5.5	· ·
I _{O(LDOx)}	Output current ⁽¹⁾					300	mA
		Output Voltage, Selectable via I ² C. LDO6, LDO6 LDO7,LDO8,LDO9), LDO3, LDO5,	Available out V _{(LDO6)TYP} = only), 1.25, 1.5 2.85, 3	1.20 (LDC 5, 1.8, 2.5,	es: 00 2.7,	V
		LDO1 Output Voltage, Selectable via I ² C	Low range, 25mV steps	$V_{(LDO1)TYP} =$	0.725 to 1	.5	
		LDO4 Output Voltage, Selectable via	High range, 25mV steps	V _{(LDO4)TYP} =	1.7 to 2.47	75	V
		LDO2 Output Voltage, Selectable via I ² C	Low range, 25mV steps	V _{(LDO2)TYP} =	0.725 to 1	.5	
V _(LDOx)	LDOx Output Voltage, Selectable via I ² C	Dropout, V(IN)= V _{(LDOx)TYP} - 0.1V , V(IN)=2.3V, 2 a time per input pin group ⁽²⁾	250mA load. 1 LDO active at			415	mV
(LDOX)		Total accuracy, V(VIN_LDOx)= V _{(LDOx)TYP} + 0.5\	⁷ , 10mA → 250 mA	See (3)	;	3.5%	
		Line Regulation, 100mA load, V(VIN_LDOx): $V_{(LDOx)\ TYP} + 0.5V \rightarrow 4.7V$		-0.5%	(0.5%	
		Load regulation, load change from 10mA \rightarrow 250 V(VIN_LDOx)> V _{(LDOx) TYP} + 0.5V) mA	See (4)			%
PSRR#50.3	PSRR at 20 kHz	250mA load, 1V input to output , $C_L = 4.7 \mu F$			40		dB
· ····(LDOX)		100mA load, 0.5V input to output, CL = 1 μ F			40		20
I _{SC(LDOx)}	Short circuit current limit	Output grounded	LDOnILIM=HI	350		700	mA
R _{DCH(LDOx)}	Discharge resistor	LDOx disabled			415		Ω
K _{RAMP(LDOx)}	Voltage change ramp constant	LDO2, LDO4 only. Fixed value, hardwired at top			7.04		mV/μs
C _{COMP}	External output capacitor value ⁽¹⁾	Stable operation	load <100 mA load>100 mA	1 0.01µF/mA, m 1µ		ue =	μF
	Power good threshold	LDO output voltage increasing	1		95%		

⁽¹⁾ Not production tested

 ⁽²⁾ Dropout not measured for devices with V(IN)<2.3V because minimum VIN is 2.3V
 (3) MIN = -3.2 - (0.105 × I_{LOAD} / V_(LDOX)TYP), I_{LOAD} = load current in mA
 (4) MIN = -2.5 - (0.105 × I_{LOAD}, I_{LOAD} = load current in mA



ELECTRICAL CHARACTERISTICS (continued)

	PARAMETER	TEST CONDITIONS	3	MIN	TYP	MAX	UNIT
BATTERY \	VOLTAGE THRESHOLDS AND CHARGER TIMING	•					
T _{CHGDLY}	Charger turn-off delay	Time delay to turn off charger or set suspend mo	ode		25		ms
V_{LOWBAT}	Precharge to fast-charge transition , selectable via	Fast charge at V(BAT) > V _{LOWBAT}		Selectable via I ² C, 2 2.5V		2.9V or	V
	I ² C	Total accuracy, relative to selected value		-3%		3%	
T _{DGL(PRE)}	Deglitch time for fast charge to precharge transition	Decreasing battery voltage			25		ms
V _{RCH}	Recharge threshold voltage	New charge cycle starts if $V(BAT) < V_{O(BATREG)} - V_{RCH}$, after termination wa	as detected	38	100	170	mV
T _{DGL(RCH)}	Deglitch time for battery recharge detection				65		ms
PACK INSE	RTION AND PACK TEMPERATURE FAULT DETEC	CTION , V(VTSBIAS)>2V					
K _{THOT}	Pack hot temperature detection constant	Pack hot temp detected and charge suspended	at V(TS) < V(2V2) × K _{THOT}	0.189	0.203	0.222	
K _{TCOLD}	Pack cold temperature detection constant	Pack cold temp detected and charge suspended	I at $V(TS) > V(2V2) \times K_{TCOLD}$	0.610	0.625	0.641	
K _{NOPACK}	Pack not detected threshold	$V(TS) > V(2V2) \times K_{NOPACK}$		0.935	0.95	0.965	
T _{DGLTEMP}	Pack temperature fault/no fault detection deglitch				15		ms
T _{DGL(DT)}	Pack insertion detection deglitch				10		ms
T _{DLY(NDT)}	Pack removal detection delay				100		μs
R _{DSTSBIAS}	Integrated switch resistance	Measured from VTSBIAS to V2V2				210	Ω
I _{TS(DET)}	TS pin bias current	VTSBIAS to V2V2 switch open			-1		μΑ
CHARGER	INTEGRATED MOSFET CHARACTERISTICS						
V _{BATDOCH}	Battery Switch dropout voltage, charge	$V_{BATDODCH} = V(VIN_CHG) - V(BAT)$, $V(BAT)$:3\	/, I(BAT) = -1A		100	200	mV
I _{DCH(BAT)}	BAT pin discharge current	ON at battery not detected and discharge switch (BATDCH=HI), V(BAT) > 1 V	enabled via I ² C	5		10	mA
CHARGER	PROTECTION AND RECOVERY FUNCTIONS						
V _{SH(VIN_CHG)}	VIN_CHG Short Circuit detection threshold	BATCHG switch set to OFF if V(VIN_CHG) < V _{SH(VIN_CHG)}		1.0	1.2	1.4	V
V _{SH(BAT)}	BAT Short Circuit detection threshold	BATCHG switch set to OFF if V(BAT) < V _{SH(BAT)}		1.6	1.8	2.0	V
R _{SH(BAT)}	BAT short circuit recovery pull-up resistor	V(BAT) < V _{SH(BAT)} , Internal resistor connected be	etween VIN_CHG and BAT2		1		kΩ
T _{CHG}	Charge safety timer	Safety timer value, thermal and DPPM loops not disabled	active or DTC function	Selectable	via I ² C: 4 hours	1, 5,6,8	hours
	•	Total accuracy		-15%		15%	
_		Pre charge timer range, thermal and DPPM	TPCH=LO	25	30	35	
T _{PRECHG}	Precharge timer	loops not active or DTC function disabled	TPCH=HI	50	60	70	min
R _{TMR(FLT)}	Timer fault recovery pull-up resistor	Internal resistor connected from VIN_CHG to BA detected	AT when timer fault is		1		kΩ
T _{STRCHG}	Charger thermal loop threshold	Charge current reduced for T _J > T _{STRCHG}			125		°C



2.7 ELECTRICAL CHARACTERISTICS

	PARAMETER	TEST CONDITIONS	3		MIN	TYP	MAX	UNIT
FAST CHARG	E CURRENT , V(VIN_CHG) > V(BAT) + 0.2	V , V(BAT) > V _{LOWBAT} , t< T _{CHG}						
I _{O(BAT)}	Charge current range	$I_{O(BAT)} = K_{SET}/R_{ISET}$ DPPM/Thermal loops not active	e		0.1		1.03	Α
			11, 100% scaling		703	865	1020	
IZ	Charge surrent act factor	$R_{ISFT} = 1 \text{ k}\Omega$, scalable via I ² C, (ISET_1, ISET_0)	10, 75% scaling		506	648	773	ΑΩ
K _{SET}	Charge current set factor	=	01, 50% scaling		325	432	530	AΩ
			00, 25% scaling		145	215	293	
PRE CHARGE	CURRENT , V(VIN_CHG) > V(BAT) + 0.1\	/ , V _{SH(BAT)} < V(BAT) < V _{LOWBAT} , t < T _{PRECHG}	•				-	
I _{O(PRECHG)}	Precharge current range	$I_{O(PRECHG)} = K_{PRECHG}/R_{ISET}$ DPPM/Thermal loops n	ot active		10		170	mA
			00		13	43	71	
14	Decilioned and forting	0C <t<sub>J<125°C RISET=I kΩ,scalable via I²C,</t<sub>	01		48	85	110	4.0
K _{PRECHG}	Precharge current set factor	(IPCH_1, IPCH_0)=	10		80	126	159	ΑΩ
			11		85	166	200	
CHARGE CUR	RENT REDUCTION - THERMAL, DPPM L	OOPS ACTIVE (T _J > T _{STRCHG} , V(SYS) < V _{SYSDPPM})	1					
K _{THERMAL}	Thermal loop factor	Charge Current (I_{CHG}) = $I_{O(BAT)} \times (1 - K_{THERM} \times (T_J))$	J - T _{STRCHG})/100)			10		%/°C
K _{DPPM}	DPPM loop factor	Charge Current (I _{CHG}) = I _{O(BAT)} × (1 − K _{DPPM} × 10 :	× (V _{SYS(DPPM)} - V _(SYS)))		0.8		%/mV
CHARGE REG	GULATION VOLTAGE , V(VIN_CHG) > V _{O(B}							
		Voltage options, Selection via I ² C RSVD4B4= RSVD4B4=			4.3, 4.	35, 4.4, 4.4	ŀ5	
					4.1, 4.	15, 4.2 , 3.9	15	V
V _{O(BATREG)}	Battery charge voltage, selectable via I ² C	Accuracy, T _A = 25°C, relative to selected value	•		-0.55%		0.95%	
	10	Total Accuracy, relative to selected value		-0.85			1.2	
		Total Accuracy range for selected value of 4.2 V			4.16		4.25	V
CHARGE TER	MINATION, V(BAT) > V _{RCH} , t < T _{TERM} , VOL	TAGE REGULATION MODE SET						
I _{TERM}	Charge termination current range	$I_{TERM} = K_{TERM}/R_{ISET}$			10		170	mA
			00		18	40	50	
			AC input selected	01	42	82	112	
				ו ויטן	42	02	112	
			or USBMODE=HI	10	70	140	188	
K _{TERM}	Charge termination detection factor	40mA <i<sub>TERM<!--=170mA, scalable via I<sup-->2C, ((TERM 1, ITERM 0)=</i<sub>	or USBMODE=HI					ΑΩ
K_TERM	Charge termination detection factor		or USBMODE=HI	10	70	140	188	ΑΩ
K _{TERM}	Charge termination detection factor Deglitch time, termination detection		or USBMODE=HI 170mA USB input selected (USBMODE=LO ar	10	70 85	140 165	188 208	AΩ
$T_{DGL(TERM)}$		(ITERM_1, ITERM_0)=	or USBMODE=HI 170mA USB input selected (USBMODE=LO ar	10	70 85	140 165 40	188 208	
$T_{DGL(TERM)}$	Deglitch time, termination detection	(ITERM_1, ITERM_0)=	or USBMODE=HI 170mA USB input selected (USBMODE=LO ar	10	70 85	140 165 40	188 208	
$T_{DGL(TERM)}$	Deglitch time, termination detection	(ITERM_1, ITERM_0)= I(BAT) < I _{TERM}	or USBMODE=HI 170mA USB input selected (USBMODE=LO ar USBLIM=LO) ⁽²⁾	10 11 ,	70 85 18	140 165 40 25	188 208 50	ms
$T_{DGL(TERM)}$	Deglitch time, termination detection PPM LOOP AND SM2 CONTROL	(ITERM_1, ITERM_0)=	or USBMODE=HI 170mA USB input selected (USBMODE=LO ar USBLIM=LO) ⁽²⁾	10 11 , ad	70 85 18	140 165 40 25	188 208 50 3.588	
T _{DGL(TERM)} CHARGER DP	Deglitch time, termination detection PM LOOP AND SM2 CONTROL SYS DPPM detection threshold ,	(ITERM_1, ITERM_0)= I(BAT) < I _{TERM} Charge current reduced for V(SYS) <v<sub>SYS(DPPM), V</v<sub>	or USBMODE=HI 170mA USB input selected (USBMODE=LO ar USBLIM=LO) ⁽²⁾	10 11 11 00 01	70 85 18 3.413 3.656	140 165 40 25 3.5 3.75	188 208 50 3.588 3.844	ms



2.8 ELECTRICAL CHARACTERISTICS

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SM3 BOOST CO	NVERTER – CONTROL CIRCUIT AND POWER ST	AGE				
V _{VIN(SM3)}	Input Voltage range ⁽¹⁾	V(VIN)	2.5		6.5	V
V _{O(SM3)}	Output voltage range ⁽¹⁾	V(SM3)	V _{VIN(SM3)}		26.5	V
V _(OVP3)	Output over-voltage trip	OVP detected at V(SM3) > V _(OVP3)	26.5	28	29	V
V _{HYS(OVP3)}	Output over-voltage hysteresis	OVP not detected at V(SM3) < V _(OVP3) - V _{HYS(OVP3)}		1.8		٧
V _(SM3REF)	FB3 voltage sense threshold ⁽¹⁾	V(FB3) below regulation point at V(FB3) < V _(SM3REF)	238 1.237	248 1.25	258 1.263	mV V
I _{O(SM3)}	LED current ⁽¹⁾	$I_{O(SM3)} = \frac{V_{(SM3REF)}}{R_{FB3}}$	0		25	mA
D _(SM3SW)	LED switch duty cycle, selectable via I ² C	Duty cycle range	D _(SM3SW) = 0% to 99. 2048 steps 0.05%	96%, set minimum	via I ² C, step	%
F _(REP_SM3)	LED switch duty cycle pattern repetition rate, selectable via I ² C	2048 pulses within repetition rate time, repetition rate set via I ² C	F _{(REP_SM3)TYP} = 550H or 220	z, 366Hz, Hz	275Hz	Hz
	Solosiasio via i O	Total accuracy, relative to $F_{(REP_SM3)TYP}$	-12%		12%	
R _{DSON(SM3SW)}	LED switch FET on-resistance ⁽¹⁾	V(VIN)=3.8 V; I(SM3SW)=20 mA		1	2	Ω
I _{LKG(SM3SW)}	LED switch FET leakage			1	4	μΑ
R _{DSON(L3)}	Power stage FET on-resistance	V(VIN)=3.8 V; I(L3)=200 mA		300	600	mΩ
I _{LKG(L3)}	Power stage FET leakage			1	4	μA
I _{MAX(L3)}	Power stage FET current limit	2.5V< V(IN) <5.5V	400	500	600	mA
T _{SM3PWR(ON)}	Maximum on time detection threshold		5	6	15	μs
T _{SM3PWR(OFF)}	Minimum off time detection threshold		310	400	480	ns
HIGH/LOW BRIG	HTNESS CONTROL		•			
R _{DSON(ISM3G)}	Output buffer switch on resistance	V(VIN)=2.5V, I(ISM3G)=25mA		1	2	Ω
I _{LKG(ISM3G)}	Leakage current	Hi-Z mode, V(ISM3G)=5V			1	μΑ
SWITCHING FRE	EQUENCY	•				
F _{SM3}	Maximum switching frequency ⁽¹⁾	At nominal load			1	MHz
GPIO1-4 – DIGIT	AL OUTPUT BUFFER	•				
		I _{OL} = 3 mA			0.6	
V _{OL(GPIO)}	Low level output voltage	I _{OL} = 10 μA			0.1	V
		$I_{OH} = -3 \text{ mA}$	1.5			
V _{OH(GPIO)}	High level output voltage GPIO	$I_{OH} = -10 \mu A$	1.8			V
I _{OL(GPIO)}	Maximum low level sink current	V(GPIOn)=2.5V			5	mA
I _{OH(GPIO)}	Maximum high level source current ⁽¹⁾	V(GPIOn)=0V	-5			mA
, ,	TAL INPUT BUFFER	•	1			
V _{IL(GPIO)}	Low level input voltage				0.4	V
V _{IH(GPIO)}	High level input voltage		1.15			V
I _{LKG(GPIO)}	Input current	V(GPIOn)=5V or 0V, GPIO configured, GPIO input current sink OFF			0.5	μA
GPIO1-4 - INPUT	CURRENT SINK	•	1			
I _{SNK(GPIO)}	Input current sink	ON if TPS658600 is not in sleep mode and GPIO is not configured.		2.5	3.5	μA

⁽¹⁾ Not production tested



2.9 ELECTRICAL CHARACTERISTICS (Continued)

	PARAMETER	TES	ST CONDITIONS	MIN	TYP	MAX	UNIT		
PWM DRIVER, P	WM OPEN DRAIN OUTPUT					•			
I _{PWM}	Maximum operating current ⁽¹⁾	PWM driver ON				200	mA		
V _{OL}	Low level output voltage	IOL = 100mA , V(AVDD6)=3V			0.2	V		
F _(PWM)	PWM driver frequency	Frequency range		Set via I ² C F _{(PWM)TYP} = 0.75, 1.5, 2.3, 3.0, 4.5, 6.7,11.7,23.4			kHz		
D _(PWM)	PWM driver duty cycle	Duty cycle range		$D_{(PWM)} = 6.25\%$ I ² C, 15 steps, 6.	s to 100%,	set via	%		
I _{LKG(PWM)}	Output off leakage current	Output voltage = 5V, drive	er set to OFF		1	5	μA		
	ER, LED_PWM OPEN DRAIN OUTPUT			1			•		
I _{LEDPWM}	Maximum operating current ⁽¹⁾	PWM driver ON				200	mA		
D _(LEDPWM)	LED_PWM driver duty cycle		Duty cycle range, 128Hz repetition rate				%		
- (LEDPWM)		Total accuracy, relative to	selected value	I ² C, 255 steps, 0		10%			
V _{OL(LEDPWM)}	Low level output voltage	$I_{OL} = 50 \text{mA}$, $V_{(AVDD6)} = 3$				0.2	V		
I _{LKG(LEDPWM)}	Output off leakage current	Output voltage = 5 V, driv			1	5	μA		
- ' '	ED/GREEN/BLUE OPEN DRAIN OUTPUTS		-		•	Ğ	L		
T _{FLASH(RGB)}	RGB1, RGB2 Flashing period	Flashing period range	Flashing period range				s		
T _{FLASH(ON)}	RGB1, RGB2 Flash On Time	Flash on time range, valu	Flash on time range, value selectable by I ² C				s		
D _(RGB)	RGB1, RGB2 Duty Cycle	Duty cycle range, value s	Duty cycle range, value selectable via I ² C				%		
			Sink current, set via I ² C	I _{SINK(RGB1)TYP} =	0, 3.7, 7.4	, 11.1	mA		
I _{SINK(RGB1)}	RGB1 output sink current	V(RED1) = V(GREEN1) = V(BLUE1) = 0.25V	V(RED1) = Absolute accuracy relative to selected value			35%			
		V(BLUE1) = 0.23V	Relative accuracy between sink current outputs	-10%		10%			
			Sink current, set via I ² C	I _{SINK(RGB at TYP} = 14.9, 18.6	= 0, 3.7, 7.4 6, 23.2, 27.3	, 11.1, 3,	mA		
I _{SINK(RGB2)}	RGB2 output sink current	V(RED2) = V(GREEN2) = V(BLUE2) = 0.25V	Absolute accuracy relative to selected value	-35%		35%			
			Relative accuracy between sink current outputs	-10%		10%			
$V_{LO(RGB1)}$	Low level output voltage	Output low voltage, RED source ON (4 or 8 or 12m V(AVDD6)=3V	1/GREEN1/BLUE1 pins, one current nA source) ON at a time,			0.25	V		
$V_{LO(RGB2)}$	Low level output voltage		A load, RED2/GREEN2/BLUE2 pins, s or 8 or 16mA source) ON at a time,			0.25	V		
I _{LKG(RGB)}	Output off leakage current	Output voltage = 5V, drive	Output voltage = 5V, driver set to OFF				μA		
DIG_PWM , DIG	_PWM1 DRIVER , PUSH PULL OUTPUT	•		-					
F	DIAMA dei con for accessor	Frequency range		110	125	140	Hz		
F _(PWM)	PWM driver frequency	Total accuracy, relative to	selected value	-10%		10%			
.,		V(DIG_PWM) at I(DIG_P	WM) = −5 mA	1.7					
$V_{HI(DIGPWM)}$	Output level, HI	V(DIG_PWM) at I(DIG_P	•	2.0			V		
		V(DIG_PWM) at I(DIG_P		†		0.5			
$V_{LO(DIGPWM)}$	Output level, LO	V(DIG_PWM) at I(DIG_P	•	1		0.1	V		

⁽¹⁾ Not production tested



2.10 ELECTRICAL CHARACTERISTICS

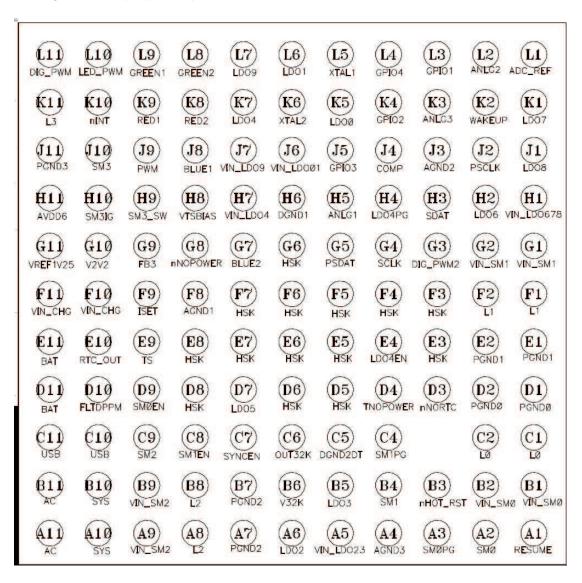
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
ADC REFEREN	CE						
V	Internal ADC reference valters	T _A = 25°C		2.595	2.6	2.605	V
V _{REF(ADC)}	Internal ADC reference voltage	Over full temp range		2.577	2.595	2.607	V
SHRT(ADCREF)	Internal reference short circuit limit	V(ADC_REF)=AGND1		3.0	4.5		mA
C _{REFADC}	Maximum capacitance for internal ADC reference supply ⁽¹⁾					6.8	μF
ADC ANALOG I	NPUTS	•					
V _{RNG(CH1_6)}	Full scale input range Channels 1–6 ⁽¹⁾	Positive inputs, Full scale ~ 2.60 V		0		$V_{REF(ADC)}$	V
V _{RNG(CH7_10)}	Full scale input range Channels 7, 10 ⁽¹⁾	Positive inputs, Full scale ~ 4.622 V		0		$V_{REF(ADC)} \times 1.78$	V
V _{RNG(CH8_9)}	Full scale input range Channels 8, 9 ⁽¹⁾	Positive inputs , Full scale ~ 5.54 V		0		V _{REF(ADC)} × 2.13	V
C _{IN(ADC)}	Input capacitance (all channels)						pF
R _{INADC(CH1_6)}	Input resistance (all channels)	AVDD6-V(ANLG) >= 500mV		1			ΜΩ
I _{LKGADC(CH1_6)}	Leakage current (all channels)	ADC disabled			0.1	1	μΑ
ADC – DC ACCI	URACY			<u> </u>		•	
RES _(ADC)	Resolution	SAR ADC			10		Bits
MCD _(ADC)	Missing codes		None	None	None		
INL _(ADC)	Integral Linearity Error			±3		LSB	
DNL _(ADC)	Differential non-linearity error				±1		LSB
OFF _{ZERO(ADC)}	Offset error	Deviation from the first code transition (0000) to (00.001) fro m the ideal AGND + 1LSB			1	5	LSB
OFF _{CH(ADC)}	Offset error match between channels ⁽¹⁾				1	5	LSB
GAIN _(ADC)	Gain error	Deviation in code from the ideal full scale co (11111) for the full scale voltage	ode		±8		LSB
GAIN _{CH(ADC)}	Gain error match	Any two channels			2		LSB
ADC THROUGH	PUT SPEED			<u> </u>		•	
ADC _{CLK}	Sampling Clock ⁽¹⁾			506	562	619	kHz
400	0 " 1 "	Sampling time - 9X ADCCLK			16		μs
ADC _{TCONV}	Sampling and conversion time	conversion and settling time -11X ADCCLK			20		μs
ANLGx (USER_	DEFINED INPUTS) BIAS CURRENTS					L	
			00 =		0		
		ADC channel 1 bias current, set via I ² C	01 =	3			
I _(ANLGx)	ANLG1, 2, or 3 pin internal pull-up current source	register ADC_WAIT bits (ADICH2_1, ADICH2_2) 10 = 11 =		10		μA	
•					50		
		Total Accuracy	-20%		20%		

⁽¹⁾ Not production tested

TEXAS INSTRUMENTS

2.11 PIN DESCRIPTION, REQUIRED EXTERNAL COMPONENTS

2.11.1 Package Pinout (Top View)



PIN FUNCTIONS

NAME			DESCRIPTION	EXTERNAL REQUIRED COMPONENTS (See Application Diagram)						
SYSTEM POWE	R PATH									
AC	A11, B11	I Adapter Charge Input Voltage, connect to AC_DC adapter positive output terminal (DC voltage)		1uF(minimum) capacitor to AGND1 pin to minimize over-voltage transients during AC power hot-plug events.						
USB	C10, C11	I	USB charge input voltage, connect to USB port positive power output	1µF(minimum) capacitor to AGND1 pin, to minimize over-voltage transients during USB power hot-plug events.						
BAT	D11, E11	I/O	Battery power	Connect to battery positive terminal. Connect 4.7µF capacitor (minimum) from BAT2 pin to clean analog ground plane						
SYS	A10, B10	0	AC/BAT/USB Power path output. Connect to System main power rail (system power bus)	10μF capacitor to AGND1 pin						
REFERENCE S	YSTEM									
TNOPOWER	D4	I	NOPOWER pin pulse width	Capacitor to AGND1. Capacitor value sets pulse width						
AVDD6	H11	0	Internal supply rail	Connect 4.7µF capacitor to AGND1						
V2V2	G10	0	Internal 2.2V supply rail	1μF (minimum) decoupling capacitor to AGND1						



PIN FUNCTIONS (continued)

NAME	PIN	1/0	DESCRIPTION	EXTERNAL REQUIRED COMPONENTS (See Application Diagram)			
1V25	G11	0	Internal 1.25V reference filter capacitor	100nF (minimum) decoupling cap to AGND1			
CHARGER							
TS	E9	I/O	Temperature Sense Input, current source output	Connect to battery pack thermistor to sense battery pack temperature			
ISET	F9	I	Current set point when charging with AC selected.	External resistor from ISET pin to AGND1 pin sets charge current value			
VTSBIAS	H8	0	Thermistor network bias supply, internally connected to 2V2 via integrated switch	Connect to external thermistor pull-up resistor			
VIN_CHG	F10, F11	I/O	Charger supply.	Connect to SM2 converter output or SYS pin, see charger section			
CHG_STAT	K2	0	Charger Status	Push-pull output, 2V2 level			
FLTDPPM D10 I DPPM loop filter capacitor				Not used, pin should be left open			
SM3 BOOST CO	NVERTER						
L3	K11	0	Drain of the integrated boost power stage switch	4.7μH inductor to SYS pin, external Schottky diode to SM3 pin			
		_	White LED duty cycle switch output, LED current setting	External resistor from FB3 pin to PGND3 pin sets LED peak current. Connect 100pF (minimum) filter capacitor to PGND3 pin.			
SM3_SW	H9 I Integrated White LED duty cycle switch input		Integrated White LED duty cycle switch input				
SM3IG	H10 I/O General purpose input/output		General purpose input/output	HI-Z Output, controlled via I ² C. May be used to set SM3 current gain step, implementing a high/low brightness control			
SM3	J10	I	White LED driver output over-voltage detection	Connect 1µF capacitor to PGND3 pin. Connect SM3 pin to the positive side of white LED ladder.			
PGND3	J11	I	Power ground, SM3 converter	Connect to the power ground plane			
DRIVERS							
RED2	K8	0	Programmable LED driver, open drain output,	Connect to RED input of RGB LED			
GREEN2	L8	0	current sink output when active.	Connect to GREEN input of RGB LED			
BLUE2	G7	0		Connect to BLUE input of RGB LED			
RED1	K9	0		Connect to RED input of RGB LED			
GREEN1	L9	0		Connect to GREEN input of RGB LED			
BLUE1	J8	0		Connect to BLUE input of RGB LED			
LED_PWM	L10	0	LED_PWM driver output, open drain, programmable duty cycle.	Can be used to drive a keyboard backlight LED or other external functions			
PWM	J9	_	PWM DRIVER, open drain output	May be used to control external vibrator motor			
DIG_PWM	L11	0	PWM, digital push-pull output	2V2 output voltage level			
DIG_PWM2	G3	0	PWM, digital push-pull output	2V2 output voltage level			
DC/DC CONVER	RTERS						
VIN_SM0	B1, B2	Ι	SM0 synchronous buck converter positive supply input	2 x 10μF capacitor to PGND0 pin			
SM0	A2	Ι	SM0 synchronous buck converter output voltage sense	LC filter: 1.5µH Inductor and 10µF Capacitor. Connect capacitor to PGND0 pin			
LO	C1, C2	0	SM0 synchronous buck converter power stage output	1.5µH inductor to SM0 pin			
PGND0	D1, D2	- 1	Power ground, SM0 converter	Connect to the power ground plane			
VIN_SM1	G1, G2	_	SM1 synchronous buck converter positive supply input	2 x 10μF capacitor to PGND1 pin			
SM1	B4	Ι	SM1 synchronous buck converter output voltage sense	LC filter: 1.5µH Inductor and 10µF Capacitor. Connect capacitor to PGND1 pin			
L1	F1, F2	0	SM1 synchronous buck converter power stage output	1.5µH inductor to SM1 pin			
PGND1	E1, E2	I	Power ground, SM1 converter	Connect to the power ground plane			
VIN_SM2	A9, B9	I	SM2 synchronous buck converter positive supply input	2 x 10μF capacitor to PGND2 pin			
SM2	C9	I	SM2 synchronous buck converter output voltage sense	LC filter: 1.5µH Inductor, 10µF Capacitor. Connect capacitor to PGND2 pin			
L2	A8, B8	0	SM2 synchronous buck converter power stage output	1.5μH inductor to SM2 pin			
PGND2	A7, B7	I	Power ground pin, SM2 converter	Connect to power ground plane			



PIN FUNCTIONS (continued)

NAME	PIN	I/O	DESCRIPTION	EXTERNAL REQUIRED COMPONENTS
	FIN	1/0	DESCRIPTION	(See Application Diagram)
ACNDO	In		Analog ground ADC subsystem	Connect to cooled ground plans
AGND2 ANLG1	J3 H5	'	Analog ground, ADC subsystem	Connect to analog ground plane
		!	Analog input1 to ADC, programmable current source output	Can be used to monitor additional system or pack parameters
ANLG2	L2		·	
ANLG3	K3	1/0	ADOLL I CONTROL I	0 , 1 , 1 , 100 F (, 1, 1, 1, 1, 1, 1, 1, 1, 1, 1, 1, 1, 1
ADC_REF	L1	I/O	ADC internal reference filter or ADC external reference input	Connect a maximum capacitance of 6.8uF referenced to the AGND2 pin.
EXTERNAL SYS	STEM RES	ET AND	CLOCK OUTPUTS, ADJUSTABLE LEVEL	
V32K	B6	I	Power supply for host interface buffers	
		Interruption pin nINT pin is LO when interrupt is requested by TPS658XX.	Open drain output	
OUT32K	C6	0	32kHz clock from external XTAL	Push-pull output, V32K level
NOPOWER	G8	0	Host reset output, LO level, adjustable width	
NORTC	D3	0	RTC_OUT POR pulse, LO level, fixed width	
SEQUENCING (CONTROL	INPUTS		
HOT_RST	В3	I/O	Reboot cycle request	Hardware reboot cycle control
RESUME	A1	I	Sleep on/off request	Hardware sleep on/off control
LDO4EN	E4	I	LDO4 enable control	
SM0EN (CORECTRL)	CTRL)		Supply enable control	Active low signal.
SM1EN	C8	I	Supply enable control	
SYNCEN	C7	I	Supply enable control	
I ² C INTERFACE	Ē			
PSDAT	G5	I/O	Power I ² C clock line	Connect to external host power I ² C clock. Connect 2K external
PSCLK	J2	I		pull-up resistor. Connect to 2V2 pin if not used
SDAT	НЗ	I/O	I ² C interface data line	Connect 2K external pull-up resistor.
SCLK	G4	I	I ² C interface clock line	
RTC OSCILLAT	OR			
XTAL1	L5	ı	Xtal oscillator	Connect to external xtal
XTAL2	K6	ı		
INPUT / OUTPU	IT	ļ		
GPIO1	L3	I/O	General purpose input/output	Input: SM0, SM1, SM2 power saving mode and output voltage setting control
GPIO2	K4	I/O	General purpose input/output	Input: ADC external trigger or LDO0, LDO1 enable
GPIO3	J5	I/O		Input: LDO2, LDO3 enable
GPIO4	L4	I/O		Input: ADC external trigger or LDO6, LDO7, LDO8 enable
COMP	J4	I	General purpose comparator input, ADC input	
SM0PG	А3	0	SM0 power good status	
SM1PG	C4	0	SM1 power good status	
LDO4PG	H4	0	LDO4 power good status	
LINEAR REGUL	ATORS	1	1	
VIN_LDO01	J6	I	Positive supply input for LDO0, LDO1	1μF (minimum) decoupling capacitor to AGND1
LDO0	K5	0	LDO0 output	1μF(minimum) capacitor to AGND1
LDO1	L6	0	LDO1 output	1μF(minimum) capacitor to AGND1
VIN_LDO23	A5	I	Positive supply input for LDO2, LDO3	1μF (minimum) decoupling capacitor to AGND1
LDO2	A6	0	LDO2 output	1μF(minimum) capacitor to AGND1
LDO3	B5	0	LDO3 output	1μF(minimum) capacitor to AGND1
VIN_LDO4	H7	I	Positive supply input for LDO4	1μF (minimum) decoupling capacitor to AGND1
LDO4	K7	0	LDO4 output	1μF(minimum) capacitor to AGND1
LDO5	D7	0	LDO5output	1μF(minimum) capacitor to AGND1
VIN_LDO678	H1	ı	Positive supply input for LDO0, LDO1	1μF (minimum) decoupling capacitor to AGND1



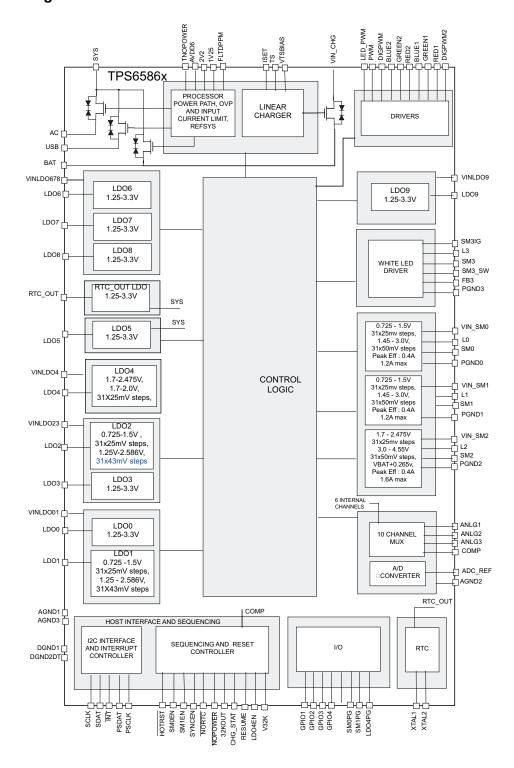
PIN FUNCTIONS (continued)

NAME	PIN	1/0	DESCRIPTION	EXTERNAL REQUIRED COMPONENTS (See Application Diagram)				
LDO6	H2	0	LDO6 output	1μF(minimum) capacitor to AGND1				
LDO7	K1	0	LDO7 output	1μF(minimum) capacitor to AGND1				
LDO8	J1	0	LDO8 output	1μF(minimum) capacitor to AGND1				
VIN_LDO9	J7	1	Positive supply input for LDO9	1μF (minimum) decoupling capacitor to AGND1				
LDO9	L7	0	LDO9 output	1μF(minimum) capacitor to AGND1				
RTC_OUT	E10	0	Low leakage LDO output. Can be connected to a super-capacitor or secondary cell, if used as a RTC backup output.	1μF (minimum) capacitor to AGND1 pin or supercap				
ANALOG AND I	DIGITAL GF	ROUND	PINS					
DGND1	H6	1	Digital ground pin	Connect to digital ground plane				
AGND1	F8	1	Analog ground pin	Connect to analog ground plane				
AGND3	A4	ı	Analog ground pin	Connect to analog ground plane				
DGND2DT	C5	I/O	Digital ground pin	Connect to analog ground plane				
HSK								



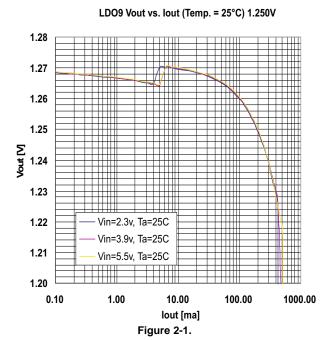
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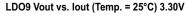
2.11.2 Block Diagram





2.12 TYPICAL CHARACTERISTICS





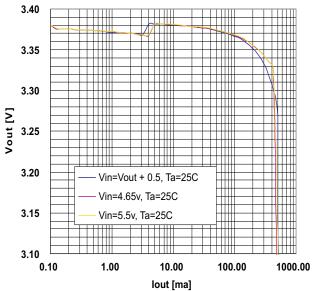
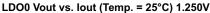
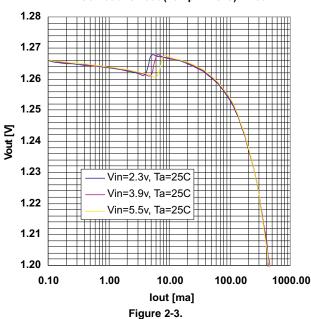


Figure 2-2.





LDO0 Vout vs. lout (Temp. = 25°C) 3.30V

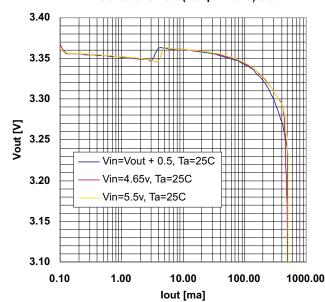
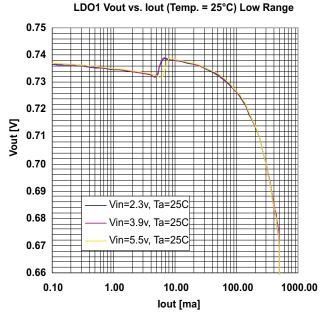


Figure 2-4.

(continued)





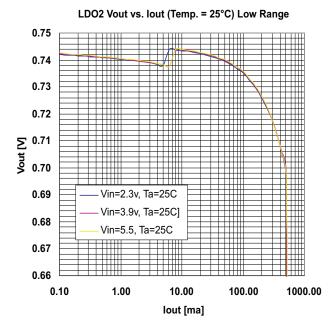
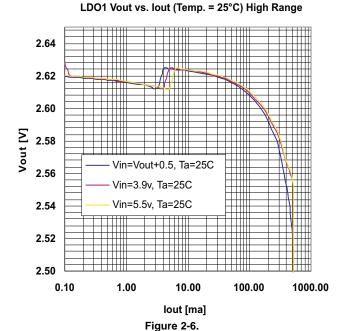


Figure 2-7.



LDO2 Vout vs. lout (Temp. = 25°C) High Range

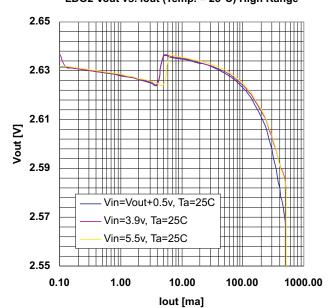
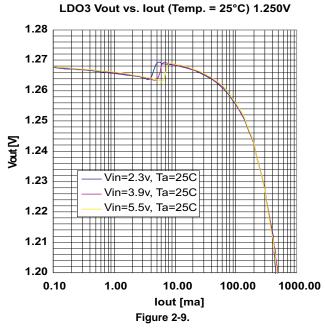
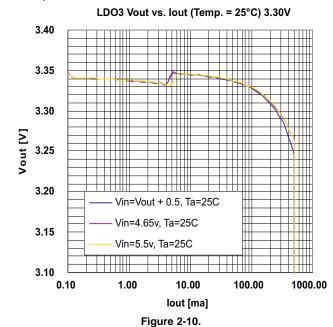


Figure 2-8.

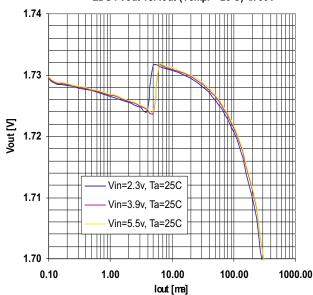


(continued)









LDO4 Vout vs. lout (Temp. = 25°C) 2.475V

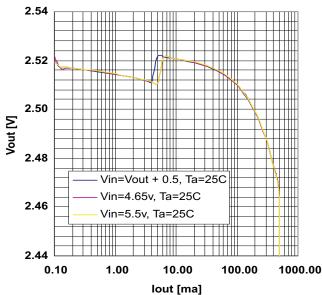
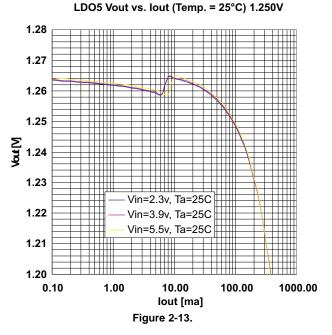


Figure 2-11.

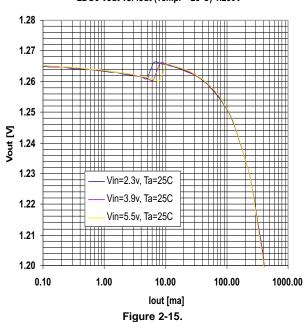


(continued)



LDO5 Vout vs. lout (Temp. = 25°C) 3.30V 3.40 3.35 3.30 Vout [V] 3.25 3.20 Vin=Vout + 0.5, Ta=25C Vin=4.65v, Ta=25C 3.15 Vin=5.5v, Ta=25C 3.10 0.10 10.00 100.00 1.00 1000.00 lout [ma]

LDO6 Vout vs. lout (Temp. = 25°C) 1.250V



LDO6 Vout vs. lout (Temp. = 25°C) 3.30V

Figure 2-14.

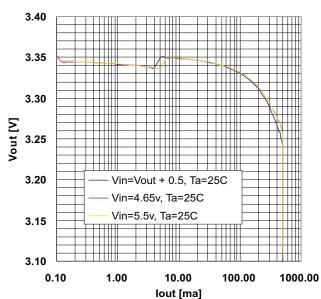


Figure 2-16.



(continued)

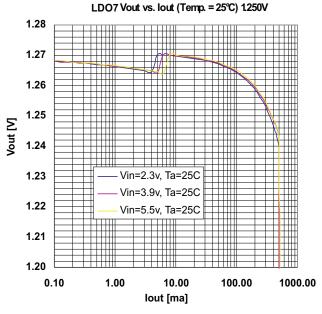
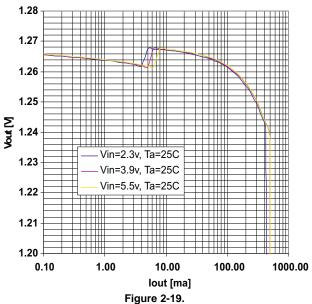
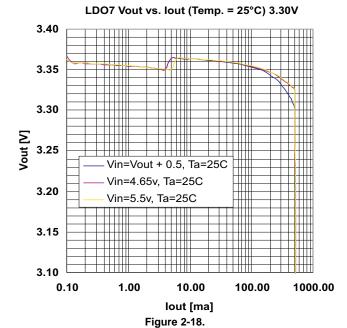


Figure 2-17.

LDO8 Vout vs. lout (Temp. = 25°C) 1.250V





LDO8 Vout vs. lout (Temp. = 25°C) 3.30V

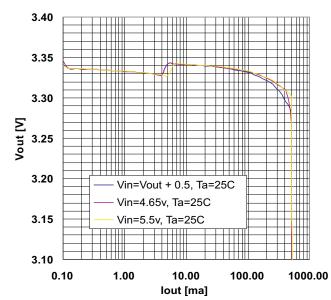


Figure 2-20.

(continued)

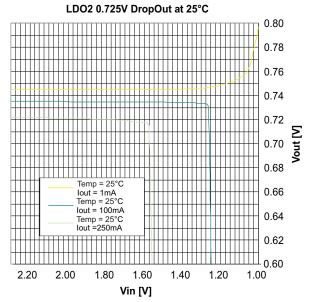
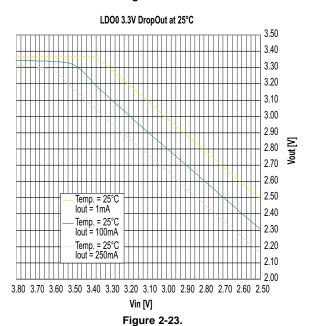


Figure 2-21.



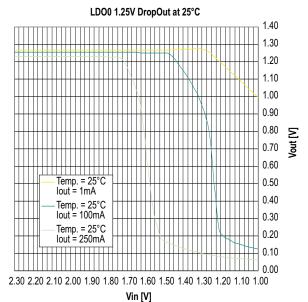


Figure 2-22.

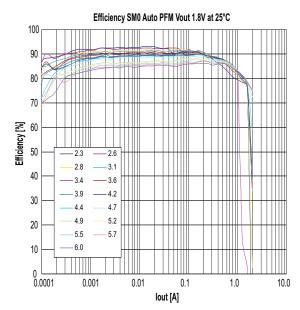


Figure 2-24.



(continued)

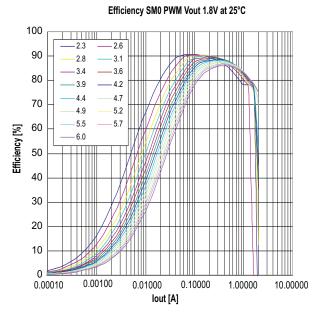
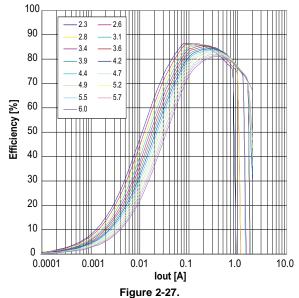


Figure 2-25.

Efficiency SM1 PWM Vout 1.250V at 25°C



Efficiency SM1 Auto PFM Vout 1.25V at 25°C

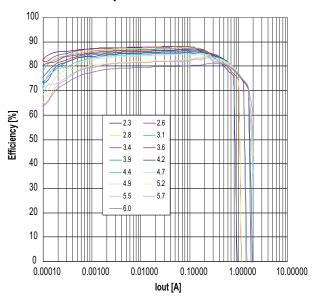
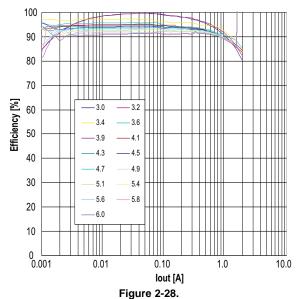


Figure 2-26.

Efficiency SM2 Auto PFM Vout 3.25V at 25°C



(continued)

Efficiency SM2 PWM Vout 3.25V at 25°C

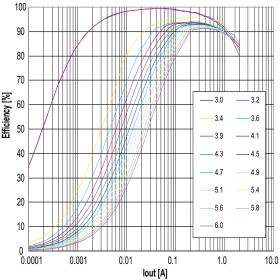


Figure 2-29.

3 DETAILED DESCRIPTION

3.1 I²C INTERFACE

Two I²C configurations are implemented in the TPS658600 device:

A -Standard I²C interface (SDAT/SCLK engine): A single I²C communication port provides a simple way for an I²C compatible host to access system status information, reset fault modes, and set supply output voltages. The I²C port functions as a SLAVE enabling I²C compatible hosts (MASTER) to perform WRITES and READS to/from internal registers. The I²C port is a 2-wire bidirectional interface using the SCLK (clock) and SDAT (data) pins. The I²C is designed to operate at SCLK frequencies up to 400 kHz. The standard 8 bit command is supported. The CMD part of the sequence is the 8 bit register address to read or write.

B – Power I²C interface (PSDAT/PSCLK engine): The TPS658600 supports processors that use a dedicated I²C bus to dynamically adjust critical supply voltages by adding a second I²C bus (Power I²C) connected to a second, dedicated I²C engine. The Power I²C port is a 2-wire bidirectional interface using the PSCLK (clock) and PSDAT (data) pins. The Power I²C is designed to operate at PSCLK frequencies up to 400 kHz. A multiple-byte data-register pair command protocol, not compatible with the standard I²C protocol, is supported by the Power I²C engine. The Power I²C engine does not support read operations.

NOTE

The Standard and Power I²C engines are always reset by the sequencer when the TPS658600 is in the POWER-UP state and when the SLEEP state is set.

3.2 I2C ADDRESS

The TPS658600 will acknowledge (ACK) addresses 0x68 (writes) and 0x69 (reads) and will NACK any other address.

3.3 DVM REGISTER ACCESS

The sequencer state machine disables write access to specific supply voltage setting registers when the TPS658600 is initially powered and when the integrated supplies are being sequenced. See the sequencer functional description for details.

3.4 SCLK/SDAT AND PSCLK/PSDAT TIMEOUT

The TPS658600 monitors the SCLK/PSCLK clock lines, and it identifies a timeout condition if the clock line is held at a logic low for longer than 30ms. The I²C engine is NOT reset when the clock line timeout is identified.

The TPS658600 monitors the SDAT/PSDAT data lines. The I²C engine will be reset when the data line is held at a logic low for more than 30ms.

3.5 I²C BUS RELEASE

The TPS658600 I²C engine does not create START or STOP states on the I²C bus during normal operation.

3.6 I²C BUS ERROR RECOVERY

The I²C bus specification does not define a method to be used when recovering from a host side bus error. During a read operation the SDAT pin can be left in a LO state if the host has not sent enough SCLK pulses to complete a transaction (i.e. host side bus error). The TPS658600 will clear any SDAT LO condition if 10 SCLK pulses are sent by the host, enabling recovery from host side bus error events.



3.7 I²C COMMUNICATION PROTOCOL

The following conventions will be used when describing the communication protocol:

CONDITION	CODE
START sent from host	S
STOP sent from host	Р
TPS658600 I ² C slave address sent from host (WRITE)	hA0
TPS658600 register address sent from TPS658600 (READ)	hA1
Non-valid I ² C slave address sent from host	hA_N
Valid TPS658600 register address sent from host	HCMD
Non-valid TPS658600 register address sent from host	HCMD_N
I/O data byte (8 bits) sent from host to TPS658600	hDATA
I/O data byte (8 bits) sent from TPS658600 to host	bqDATA
Acknowledge (ACK) from host	hA
Not acknowledge (NACK) from host	hN
Acknowledge (ACK) from TPS658600	bqA
Not acknowledge (NACK) from TPS658600	bqN

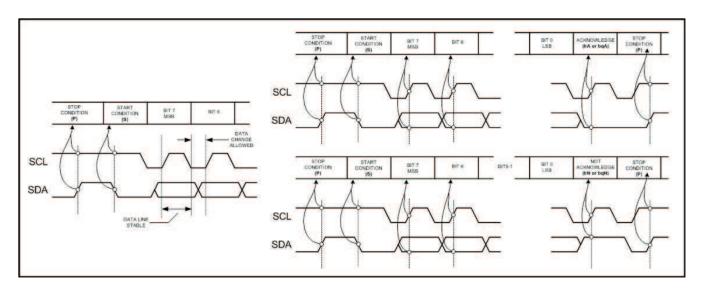


Figure 3-1. I²C Conditions

For normal data transfers, the data line (SDAT or PSDAT) is allowed to change only when the clock line (SCLK or PSCLK) is low, and one clock pulse is used per bit of data. The data line must remain stable whenever the clock line is high, as data changes when the clock is high are reserved for indicating the start and stop conditions. Each data transfer is initiated with a start condition and terminated with a stop condition.

When addressed, the TPS658600 device generates an acknowledge bit after the reception of each byte by pulling the data line Low. The master device (microprocessor) must generate an extra clock pulse that is associated with the acknowledge bit. After the acknowledge/not acknowledge bit, the TPS658600 leaves the data line high, enabling a STOP condition generation.

3.8 I²C READ AND WRITE OPERATIONS

The TPS658600 supports the standard I²C one byte Write. The basic I²C read protocol has the following steps:

1. Host sends a start and sends TPS658600 address

- 2. TPS658600 ACK's that this is a valid I²C address and that the bus is configured for write
- 3. Host sends TPS658600 register address
- 4. TPS658600 ACK's that this is a valid register and stores the register address to be read
- 5. Host sends a repeated start and TPS658600 I²C slave address, reconfiguring the bus for read
- 6. TPS658600 ACK's that this is a valid address and that bus is reconfigured
- 7. Bus is in read mode, TPS658600 starts sending data from selected register

The I^2C write protocol is similar to the read, without the need for a repeated start and bus being set in write mode. In a WRITE, it is not necessary to end each 1 byte WRITE command with a STOP as a START will have the same effect (repeated start).

The host can complete a READ or a WRITE sequence with either a STOP or a START.

$\begin{tabular}{ll} \textbf{NOTE}\\ \textbf{Read operations are not supported for the PSDAT/PSCLK I2C engine.} \end{tabular}$

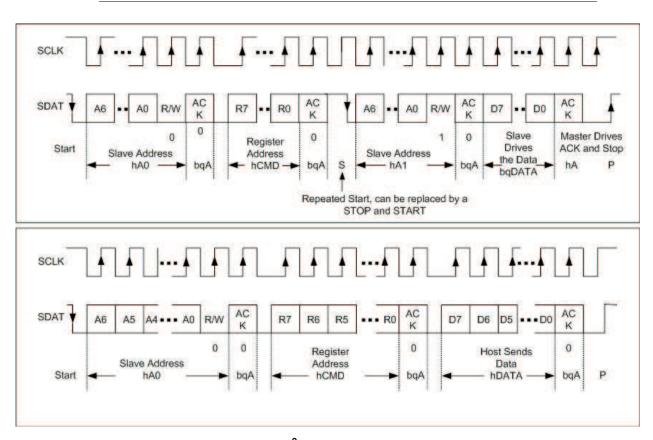


Figure 3-2. I²C Read/Write Example

3.9 VALID WRITE SEQUENCES (SDAT/SCLK, PSDAT/PSCLK)

The TPS658600 will always ACK its own address. If CMD points to an allowable READ or WRITE address, the device writes the address into its RAM address register and sends an ACK. If CMD points to a non-allowed address, the device does NOT write the address into its RAM address register and sends a NACK.

31



		S	hA0	bqA		S	hA0	bqA	hCMD	bqA		S	hA0	bqA	hCMD_N	bqN
--	--	---	-----	-----	--	---	-----	-----	------	-----	--	---	-----	-----	--------	-----

3.10 ONE BYTE WRITE (SDAT/SCLK, PSDAT/PSCLK)

The data is written to the addressed register at the end of the bq ACK, ending the one byte write sequence when the RAM address and the data byte are stored in the I²C registers. The host can cancel a WRITE by sending a STOP or START before the trailing edge of the ACK clock pulse.

e	hAO	bαΛ	hCMD	baA	bDΔTΔ	bαΛ
3	hAU	bqA	TICIVID	Apd	NDATA	bqA

3.11 VALID READ SEQUENCES (SDAT/SCLK ONLY)

The TPS658600 will always ACK its own address.

•	I. A 4	I A
	na1	naa
J	11/ 11	5971

Upon receiving hA1, TPS658600 starts at the current location of the RAM address register. The START and the STOP both act as priority interrupts. If the host has been interrupted and is not sure where it left off, it can send a STOP and reset the TPS658600 state machine to the WAIT state; once in the WAIT state, the TPS658600 will ignore all activity on the SCLK and SDAT lines until it receives a START. A repeated START and START in the I²C specification are both treated as a START.

5	3	hAC)	bqA		hCMD		bqA		Р
S	hA0	bqA	hCMD	bqA	S	hA1	bqA	bqDATA	hN	Р

3.12 VALID READ SEQUENCES (SDAT/SCLK ONLY)

Į	S		hA1		bqA		bqDATA	١	hN		Р
	Inc	remental	read seq	uences							
	S	hA1	bqA	bqData	hA	bqDATA	hA		bqDATA	hN	Р

3.13 NON-VALID SEQUENCES

START and non-hA0 or non-hA1 Address: A START followed by an address which is not hA0 or hA1 will be NACKED.

•	L A 4	la ach l
5	nA_1	Npa

Attempt to Specify Non-Allowed READ Address

If the CMD points to a non-allowed READ address (reserved registers), bq will send a NACK back to the host and it will not load the address in the RAM address register. Note that the TPS658600 NACKS whether a stop is sent or not.

S hA0 bqA hCMD_N bqA P S hA0 bqA hCMD_N bqN

Attempt to Specify Non-Allowed WRITE Address

If the host attempts to WRITE to a READ-ONLY or non-accessible address, the TPS658600 ACKS the CMD containing the allowed READ address, loads the address into the address register and ACKS after the host sends the next data byte. A subsequent hA1 READ could read this address, but the data sent by the host will not have been written.

_						
l S	hA0	bqA	hCMD	bqA	hDATA	bqA

3.14 INCREMENTAL READ (SDAT/SCLK ONLY)

The SDAT/SCLK I²C interface supports incremental read operations. Each register must be accessed in a single read operation. A valid WRITE address is required to write to the RAM, and a valid READ address is required to specify the initial RAM address where the READ starts. Once a read command is received, the RAM data for the specified address is output to the host. If the host chooses, it can loop through the remaining addresses; the address is automatically incremented by one at the end of each read. If the loop gets to the top address, it automatically rolls over to address 0x00 and the sequence stops.

3.15 I²C COMMUNICATION PROTOCOL – POWER I²C INTERFACE, PINS PSDAT/PSCLK

The Power I²C interface is designed to support fast write operations using multiple register-data pair sequences. The Power I²C engine is a write-only engine, and it does not support read operations.

During a write sequence, the host sends the start command, followed by the TPS658600 address. Then the host sends the register address byte, followed by eight bits of the data for the respective register (Register1 Address/Data in Figure 3-3). From this point on the TPS658600 will accept all the following 2 byte pairs as a random register address, followed by the data content to be written to that register. This process continues until the host sends a valid stop condition after the last register (Register N in Figure 3-3) is written. A typical multi-byte sequence is shown in Figure 3-3.

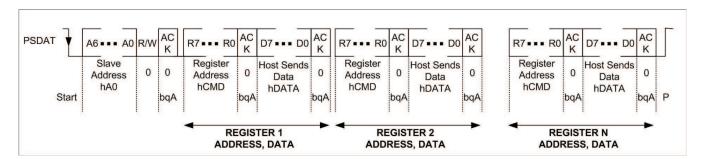


Figure 3-3. Power I²C Protocol

3.16 SIMULTANEOUS STANDARD AND POWER I²C OPERATION

The TPS658600 has individual address pointers for the Power I²C engine and Standard I²C engine. The value written to the register will be defined by the relative timing between read/write pulses when simultaneous I²C read/write operations happen. Simultaneous write/read operations to the same register will be handled as follows:

- 1. Both Standard I²C and Power I²C are executing operations accessing distinct registers at the same time (simultaneous read/read, read/write, write/read or write/write): No conflict exists in this case.
- 2. Power I²C writes and Standard I²C reads the same register at the same time
 - (a) Standard I²C will read the old register value if the Standard I²C read pulse is generated at least 110nsec (typ) before the Power I²C write pulse happens.
 - (b) Standard I²C will read the new register value if the Standard I²C read pulse is generated at least 110nsec (typ) after the Power I²C write pulse happens.
- 3. Power I²C and Standard I²C write to the same register at the same time



- (a) If both write operations are more than 110nsec (typ) apart, the register final value will be set by the engine that executes the last write operation.
- (b) a. If both write operations are less than 110nsec (typ) apart, the priority will be given to the Power I²C engine. The value from the Power I²C engine will be written into the register, and the data received by the Standard I²C operation is not written to the TPS658600 internal memory.

THERE IS NO CLOCK STRETCH FUNCTION IN EITHER SCLK OR PSCLK WHEN A CONFLICT SITUATION HAPPENS. THE CONFLICT IS HANDLED INTERNALLY BY GIVING PRIORITY TO PSDAT/PSCLK ENGINE.

3.17 POWER PATH

3.17.1 RAM Control Bits

The power path circuit connects one of the power sources plugged into the AC, USB or BAT pins to the SYS pin. The supply selection is made based on system parameters monitored by the power path circuit and internal RAM control bits in register 0x4C.

PPATH1 [Addr 0x4C] Defaults in BOLD Bit Number **B5** В4 В3 B2 В1 Bit Name USBSUSP USBDCH ACDCH RSVD4B4 BOOTOFF USBLIMIT USBMODE **PWRSYS** USB INPUT AUTO SYS USB SUSPEND CHARGE USB INPUT ILIMIT **USB INPUT** Function SPARE SPARE **CURRENT LIMIT POWER** CURRENT LIMIT VOLTAGE RANGE MODE at BOOT PHASE SETTING **SELECTION** SET BY USBLIMIT SUSPEND OFF SET BY USBLIMIT When 0 NOT USED NOT USED 3.95V-4.2V 100mA BAT TO SYS ONLY SET BY AUTO MODE When 1 SUSPEND ON NOT USED NOT USED 4.3V-4.45V **USBMODE AND** 500mA 2.25 A **ENABLED** USBLIMIT

Table 3-1. Power Path Control

The input power priority is hard-wired internally, with the AC input having the higher priority, followed by the USB input (2nd) and the battery pack (3rd). The SYS pin voltage is **not** regulated and it will be equal to the input voltage (AC, USB or BAT value) minus the voltage drop across the switch that is ON when the selected input current limit is not active.

Setting the control bit PWRSYS (bit 0) to **0**, the user can override the power path priority, connecting the battery to the SYS pin even if AC or USB are detected. When PWRSYS is **0** and the battery is removed, the SYS pin *will not* be connected back to the AC or USB inputs and thereby will discharge to ground.

The USB power will be ignored when USBSUSP (bit 7) is 1, connecting only the AC or BAT power sources to the SYS pin. If neither AC nor BAT is connected the SYS pin, it will discharge to ground.

The USB input current is limited to the maximum value programmed by the host via the I²C interface by setting bits USBLIMIT (bit 2) and USBMODE (bit 1) as shown in Table 3-2.

USBMODE	USBLIMIT	USB INPUT CURRENT LIMIT	AC INPUT CURRENT LIMIT
0	0	100 mA max	
0	1	500 mA max	2.2 A min
1	Х	2.1A min	

Table 3-2. Power Path Current Limit

If the system current requirements exceed the input current limit, the SYS pin voltage will be reduced until the power path is set in supplement mode (if pack is connected).

3.18 SYSTEM STATUS DETECTION

The TPS658600 has integrated comparators that monitor the BAT, AC, USB and SYS pin voltages. The data generated by the comparators is used by the power path control logic to define which of the integrated power path switches will be active. Table 3-3 lists the system power detection conditions:

Table 3-3. Power Path Detection Functions

SYSTEM STATUS	DETECTION CONDITIONS ⁽¹⁾
AC input voltage detected	$V_{IN(OVP)} > V(AC) > V(BAT) + V_{IN(DT)}$
USB input voltage detected	$V_{IN(OVP)} > V(USB) > V(BAT) + V_{IN(DT)}$
AC over-voltage detected	$V(AC) > V_{IN(OVP)}$
USB over-voltage detected	$V(USB) > V_{IN(OVP)}$
SYS pin short detected	V(SYS) < V _{SH(SYS)}
Battery switch over-current detection	I(BAT) > I _{BATSYS}
Supplement mode detection	V(SYS) <v(bat)-v<sub>SUP(SYS) AND I(BAT)<i<sub>BATSYS</i<sub></v(bat)-v<sub>

 V_{IN(DT)}, V_{SH(SYS)}, V_{BATSH}, V_{IN(OVP)}, V_{SUP(SYS)} are TPS658600 internal references, refer to the electrical characteristics for additional details

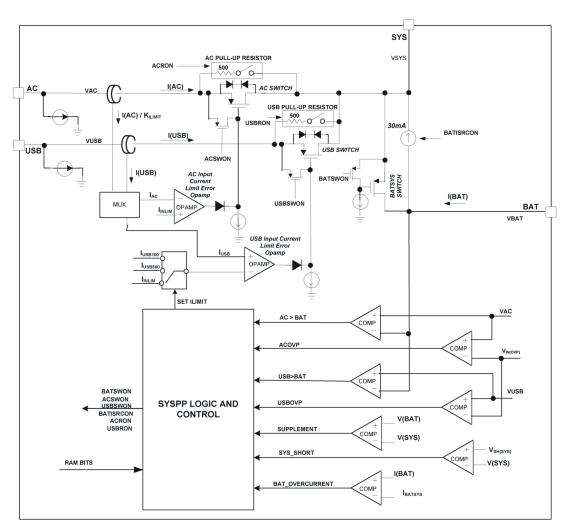


Figure 3-4. Simplified Power Path Block

The I²C control bits and system status are used by the power path control logic to define the state of the power path switches as shown below; a fault condition will be detected when the SYS pin is shorted or a battery switch over-current condition is detected.

Table 3-4. Power Path Control

6586x MODE	PWRSYS	USBSUSP	AC DETECTED	USB DETECTED	FAULT DETECTE D	AC SWITCH	USB SWITCH	BATTERY SWITCH	SYS PIN CONNECTED TO
UVLO	Х	Х	X	X	Х	OFF	OFF	OFF	NONE
NOT UVLO	Х	Х	Х	Х	YES	OFF	OFF	OFF	PULL-UP RES/ISRC
NOT UVLO		Х	YES	Х	NO	ON	OFF	ON if Supplement	AC
NOT UVLO	1	0	NO	YES	NO	OFF	ON	mode is required, OFF otherwise	USB
NOT UVLO		1	NO	YES	NO	OFF	OFF	ON	BATTERY
NOT UVLO		Х	NO	NO	NO	OFF	OFF	ON	BATTERY
NOT UVLO	0	Х	Х	Х	NO	OFF	OFF	ON	BATTERY

When a fault condition is detected, the fault recovery method (resistor or current source) is defined by the input power supply detection:

Table 3-5. Power Path Fault Recovery Control

AC DETECTED	USB DETECTED	RECOVERY METHOD		
YES	X	AC PULL-UP RESISTOR ON		
NO	YES	USB PULL-UP RESISTOR ON		
NO	NO	30mA CURRENT SOURCE ON		

3.19 POWER PATH STATUS

The power path status is available at register 0xB9, bits BATSYSON, ACSWON, USBSWON, and register 0xBB, bits LOWSYS, ACDET, USBDET, AC_OVP and USB_OVP. See the STATUS REGISTER section for bit function description.

3.20 BATTERY CHARGER

The TPS658600 has an integrated linear charger that is designed to enable the implementation of two distinct configurations. The TPS658600 has been configured such that the Charger input power is supplied by the SM2 output. In this mode, the SM2 acts as a pre-regulator to the charger input. The Charger is active when the device is in the SLEEP state.

Charger input power supplied by power path output: The SM2 voltage is set to the voltage programmed by the host via register SUPPLYV2 control bits VSM2[4:0] at all times. The charger input pin VIN_CHG must be connected to the power path output SYS pin. This topology has lower efficiency when compared to the pre-regulator configuration, but it enables the use of SM2 as a stand alone converter in systems where lower charge rates are required.

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System SYS VIN_SM2 AC L2 AC Charge Switch Control Current USB **DISCHG** SUPL USB FET V_{REF} FET SM₂ Detection Power Path Control VIN_CHG CHG FET **BAT** Discharge Current TS I_{chg} Detection & Charge Control SET

Figure 3-5. Linear Charger Configured as Stand-Alone

SM2 acting as a pre-regulator to the linear charger input: The charger and internal control logic are configured to work together such that during fast charge, the SYS pin voltage is down-converted by SM2 to VBAT+ 0.26V (typ), tracking the battery voltage as it increases during the charge process. This topology achieves overall efficiency close to a switched mode charger topology. When the system is on battery power operation, pre-charge or the thermistor is removed, the SM2 tracking mode is disabled and SM2 down converts the battery voltage to the voltage programmed by the host via register SUPPLYV2 control bits VSM2[4:0]. When the charger is configured to turn ON in sleep mode, the SM2 output voltage should be set using the SUPPLY2 control bits VSM2[4:0] to a voltage 250mV (typ) above the charge regulation voltage.



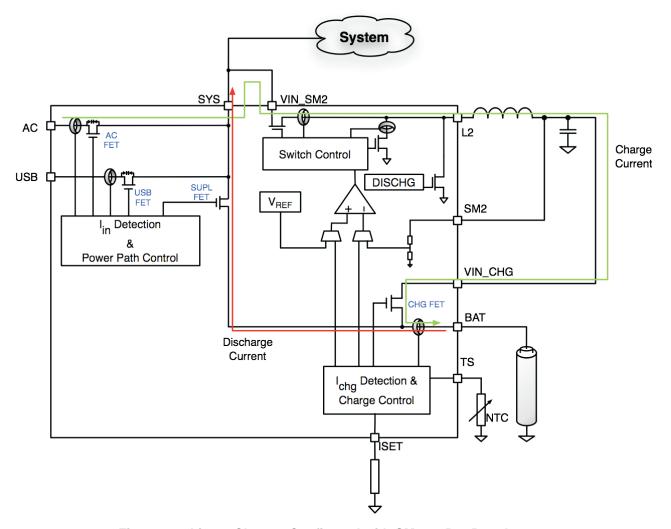


Figure 3-6. Linear Charger Configured with SM2 as Pre-Regulator

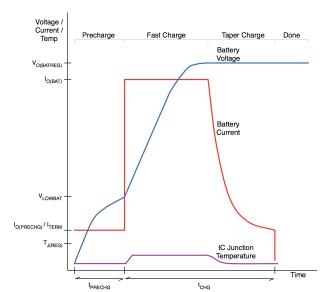
3.21 OPERATING MODES

The TPS658600 supports charging of single-cell Li-Ion or Li-Pol battery packs. The charge process is executed in three phases: pre-charge (or pre-conditioning), constant current and constant voltage. Protection circuits reduce the charge current when the IC junction temperature exceeds 125°C (typ, thermal loop), or when the SYS pin voltage drops below a user-selectable threshold (DPPM loop).

When the charger is enabled, the control loops limit the BAT pin current to the programmed charge current value (charge current loop) or regulates the BAT pin voltage to the programmed charge voltage value (charge voltage loop). If $V(BAT) < V_{LOWBAT}$, the BAT pin current is internally set to the programmed pre-charge current value. A typical charge profile is shown below, for an operation condition when the thermal and DPPM loops are not active.

If the operating conditions cause the IC junction temperature to exceed 125°C or the SYS pin voltage collapses, the charge cycle is modified, with the activation of additional control loops. The DPPM and thermal loops will override the other charger control loops and reduce the charge current. A modified charge cycle, with the thermal or DPPM loop active, is shown in Figure 3-7 and Figure 3-8.





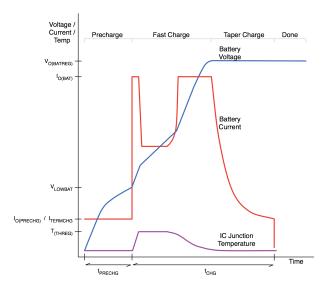


Figure 3-7. Charge Phases Without Thermal Foldback

Figure 3-8. Charge Phases With Thermal Foldback

3.22 DETECTING THE SYSTEM STATUS

The TPS658600 has integrated comparators that monitor the voltages at the BAT, TS, and VIN_CHG pins, as well as the charge current. The data generated by those comparators is used by the control logic to detect fault conditions and control SM2 operation. Table 3-6 lists the system power detection conditions. $V_{SH(VIN_CHG)}$, V_{LOWBAT} , and $V_{SH(BAT)}$ are TPS658600 internal references (refer to the electrical characteristics for additional details).

Table 3-6. System Status Detection Conditions

STATUS	DETECTION REQUIREMENTS
VIN_CHG pin short detected	V(VIN_CHG) < V _{SH(VIN_CHG)}
Battery voltage below pre-charge threshold	V(BAT) < V _{LOWBAT}
Battery short detected	$V(BAT) < V_{SH(BAT)}$



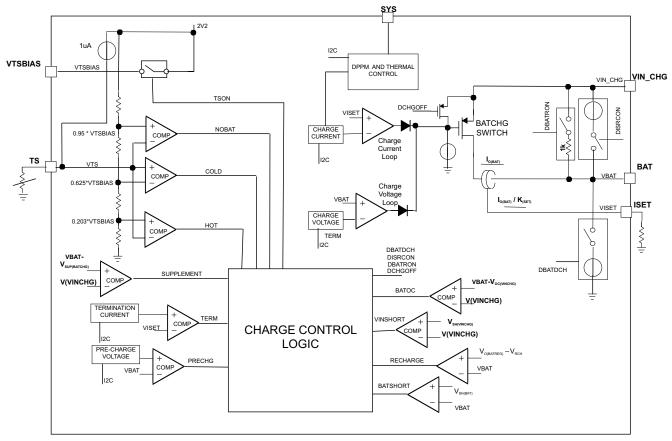


Figure 3-9. Simplified Charger Block Diagram



3.23 CHARGER RAM REGISTERS

The charger has control bits that enable user configuration of multiple charger parameters, as shown below:

Table 3-7. Charger Control

CHG1 [Addr 0)x49]							Defaults in BOLD
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0
Bit Name	CHGTMR[1]	CHTMR[0]	BATDCH	TSON	ISET[1]	ISET[0]	TERMOFF	CHSUSP
Function			BATTERY DISCHARGE SWITCH	THERMISTOR BIAS CONTROL	CHARGE CURR		CHARGE TERMINATION STATE	SUSPEND CHARGE
When 0	00 = 4 Hrs		OFF	OFF	00 = 0.25		TERM ON	NOT SUSPENDED
When 1	10 = 6 Hrs	11 = 8 Hrs	ENABLED	ON	01 = 0.50	11 = 1.00	TERM OFF	SUSPENDED
CHG2 [Addr 0)x4A]							Defaults in BOLD
Bit Number	B7	В6	B5	B4	В3	B2	B1	В0
Bit Name	DTCON	VPCHG	TSBYP	CHTMREN	VCHG[1]	VCHG[0]	CHGON[1]	CHBOOT
Function	DYNAMIC TIMER FUNCTION	PRE-CHARGE VOLTAGE	ENABLE CHARGER LDO MODE	CHARGE SAFETY TIMER	CHARGE VOLTAGE SELECTION		CHARGER ON/OFF	CHARGER OPERATION DURING BOOT
When 0	OFF	2.5V	OFF	OFF	SEE VCHG SE	TTING TABLE	SEE CHARGE	OFF
When 1	ON	2.9V	ON	ON	SEE VCHG SE	TTING TABLE	ENABLE TABLE	ON
CHG3 [Addr 0)x4B]							Defaults in BOLD
Bit Number	B7	В6	B5	B4	В3	B2	B1	В0
Bit Name	CHGON[0]	SYSDPPM[1]	SYSDPPM[0]	TPCHG	ITERM[1]	ITERM[0]	IPCHG[1]	IPCHG[0]
Function	CHARGER ON/OFF	SYSTEM POWE		PRE-CHARGE TIMER SCALING	TERMINATION CURRENT FACTOR		PRE-CHARGE CUI	RRENT FACTOR
When 0	SEE CHARGE	00=3.5V	01=3.75V	30 MIN	00=0.04	01=0.10	00=0.04	01=0.1
When 1	ENABLE TABLE	10=4.0V	11=4.25V	60 MIN	10=0.15 11=0.20		10=0.15 11=0.2	

Table 3-8. VCHG Settings

RSVD4B4 ⁽¹⁾	VCHG[1]	VCHG[0]	CHARGER REGULATION VOLTAGE ⁽¹⁾
0	0	0	4.10
0	0	1	4.15
0	1	0	4.20
0	1	1	3.95
1	0	0	4.30
1	0	1	4.35
1	1	0	4.40
1	1	1	4.45

⁽¹⁾ The charge voltage range is set by bit RSVD4B4, located on register PPATH1, 0x4C (bit B4)

Table 3-9. Charge Enable Control

SM2	CHGON[1]	CHGON[0]	CHARGER MODE IN SLEEP	CHARGER MODE IN NORMAL
OFF	X	X	OFF	OFF
ON	0	0	OFF	OFF
ON	0	1	OFF	OFF
ON	1	0	ON	OFF

Table 3-9. Charge Enable Control (continued)

SM2	CHGON[1]	CHGON[0]	CHARGER MODE IN SLEEP	CHARGER MODE IN NORMAL
ON	1	1	ON	ON

3.24 SUPPLEMENT MODE DETECTION

The TPS658600 charger does not have a supplement mode. The charger power mosfet will NOT turn on when the charger is disabled and V(VIN_CHG) < V(BAT).

3.25 SHORT CIRCUIT DETECTION

The BAT pin is monitored for a short circuit condition. If $V(BAT) < V_{SH(BAT)}$, the BATCHG switch is turned OFF and an internal resistor is connected from VIN_CHG pin to BAT pin.

3.26 DPPM FUNCTION

Internal circuits monitor the voltage at the SYS pin and reduce the charge current when $V(SYS) < V_{SYS(DPPM)}$. This function assures that the external power is used to run the system. The threshold $V_{SYS(DPPM)}$ can be programmed using the I^2C bits SYSDPPM<1:0> in register CHG3.

3.27 BATTERY DETECTION, TEMPERATURE QUALIFICATION

Battery pack insertion and battery pack temperature are detected by three comparators that monitor the thermistor voltage. The thermistor supply is enabled via I²C when control bit TSON=HI in register CHG1. This control bit enables the host software to turn on the thermistor bias when the charger is off and the pack temperature needs to be measured via the ADC, minimizing system quiescent current when operating under battery power. When the charger is activated, the thermistor power is enabled independent of the state of bit TSON.

The host software must disable the charger by setting bit CHGON(1)=0 when the battery pack removal is detected by the TPS658600. This procedure is required in order to avoid undesired transients when a battery pack is hot-plugged in the system.

3.28 BATTERY PRE-CONDITIONING

The TPS658600 applies a pre-charge current $I_{O(PRECHG)}$ to the battery if the battery voltage is below the V_{LOWBAT} threshold, pre-conditioning deeply discharged cells. The resistor, R_{ISET} , connected between the ISET and AGND pins, determines the pre-charge rate. The pre-charge rate programmed by R_{ISET} is always applied to a deeply discharged battery pack, independent of the input power selection (AC or USB). The pre-charge current can be calculated as shown in Equation 1:

$$I_{O(PRECHG)} = \frac{K_{PRECHG}}{R_{ISET}}$$
(1)

where K_{PRECHG} is the pre-charge current scaling factor in $A\Omega$.

The pre-charge current is set by the resistor on the ISET pin and can be scaled via I²C register CHG3 bits IPCH_1, IPCH_0 to a percentage (20%, 15%, 10%, or 4%) of the value set by R_{ISET}. The pre-charge voltage is selectable via bit VPCHG, register CHG2.

3.29 CONSTANT CURRENT CHARGING

The constant charge current mode (fast charge) is set when the battery voltage is higher than the pre-charge voltage threshold. The fast charge current regulation point is defined by the external resistor, R_{ISET} , connected to the ISET pin as shown in Equation 2.

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$$I_{O(BAT)} = \frac{K_{SET}}{R_{ISET}}$$
 (2)

where K_{SET} is the charge current scaling factor in $A\Omega$.

The charge current is set by the resistor on the ISET pin and can be scaled via I²C register CHG1 bits ISET1[1:0] to a percentage (100%, 75%, 50% or 25%) of the value set by R_{ISET}.

The ISET resistor will always set the maximum charge current if the AC input is selected. When the USB input is selected the maximum charge current will be defined by the USB input current limit and the programmed charge current. If the USB input current limit is lower than the I_{O(BAT)} value, the battery switch will be set in the dropout region and the charge current will be defined by the input current limit value and system load, as shown in Figure 3-10.

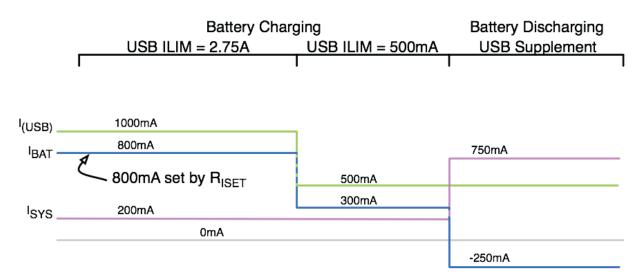


Figure 3-10. USB Supplement Mode

3.30 BATTERY VOLTAGE REGULATION, CHARGE VOLTAGE

The Voltage regulation feedback is implemented by sensing the BAT pin voltage, which is connected to the positive side of the battery pack. The TPS658600 monitors the battery-pack voltage between the BAT and AGND1 pins. When the battery voltage rises to the V_{O(BATREG)} threshold, the voltage regulation phase begins and the charging current tapers down.

The charging voltage can be selected via I2C, with bits VCHG<1:0> (register VCHG1) and RSVD4B4 (register PPATH1, 0x4C)

3.31 LDO MODE OPERATION

The LDO mode makes it possible to run critical subsystems connected directly to the battery node (BAT pin) when the battery is removed and the end equipment is powered by the AC or USB input.

The SM2 voltage must be programmed by the host via register SUPPLYV2 control bits VSM2<4:0> to a value 100mv above the programmed charge voltage before the LDO mode is enabled, and it should be left at that value while LDO mode is in use. The SM2 voltage can be set to any other value after the LDO mode is disabled.

The charger LDO Mode operation is enabled when termination is disabled (TERMOFF bit is 1 in CHG1) and thermistor removal detection is ignored (setting TSBYP bit to 1 in CHG2).



When the LDO mode is set, termination is disabled, all safety timers are held in reset, and the battery discharge switch is disabled. The BAT pin voltage will regulate to $V_{O(BATREG)}$ when **all** the following conditions are true: the charger is enabled (VIN_CHG > $V_{O(BATREG)}$) and input power is present (AC or USB input power detected). Under these conditions the BAT pin voltage will be regulated to the charge voltage $V_{O(BATREG)}$ if the charger current loops are not active.

The charger current limit loop will still be enabled, and the current that can be supplied by the BAT pin in LDO mode will be dependent on the BAT pin voltage, as shown in Table 3-10.

Table 3-10. Battery Charge Current

BAT PIN VOLTAGE	BATTERY CHARGE CURRENT
< V _{LOWBAT}	I _{O(PRECHG)}
> V _{LOWBAT}	I _{O(BAT)}

In LDO mode, both the thermal loop and DPPM loop are also enabled. These loops, when active, limit the current available at the BAT pin. The BAT pin voltage will collapse if the charge current available is lower than the current required to run subsystems connected to the BAT pin.

The battery tracking function is disabled when the thermistor is not detected; the BAT pin will, as a result, track the SM2 output voltage when V(SM2) is set below $V_{O(BATREG)}$.

3.32 CHARGER CONTROL LOGIC AND OPERATING MODES

The charger control logic monitors system parameters and control signals to define when the charger is enabled. The table below lists the charger operating modes. Note that when the charger is set to OFF all timers are reset. The charge is enabled by setting bit CHGON to 1 in register CHG2.

The timer fault and termination detection events are latched internally to the charger control logic, and after that the charger is set to OFF. The only way to reset a timer fault and termination detection is to start a new charge cycle.

Table 3-11. Charger Mode Control

TPS658600 MODE	INPUT POWER DETECTED	SM2 MODE ⁽¹⁾	CHARGER THSHUT DETECTED	CHARGE ENABLED	CHARGE SUSPEND CMD	TIMER FAULT DETECTED	PACK TEMP FAULT	TERM DETECTED	CHARGER MODE
UVLO	Х	Х	Х	Х	Х	X	Х	Х	OFF
	NO	Х	Х	Х	Х	Х	Х	Х	OFF
	YES	OFF	Х	Х	Х	X	Х	Х	OFF
	YES	ON	YES	Х	Х	Х	Х	Х	OFF
	YES	ON	NO	NO	Х	Х	Х	Х	OFF
NOT UVLO	YES	ON	NO	YES	NO	NO	NO	NO	ON
	YES	ON	NO	YES	NO	YES	Х	Х	OFF
	YES	ON	NO	YES	NO	X	Х	YES	OFF
	YES	ON	NO	YES	YES	NO	Х	NO	SUSPEND
	YES	ON	NO	YES	NO	NO	YES	NO	SUSPEND

⁽¹⁾ When SM2 is not configured as the charger pre-regulator the SM2 mode does not affect the charger mode.

3.33 CHARGE SUSPEND

The charge may be suspended anytime by setting CHSUSP to 1 in register CHG1 or when the pack temperature is out of range and I²C control bit TSBYP is 0. This will disable the charger stage and hold the safety timers at their current count. Normal operation resumes when a temperature fault is not detected.

3.34 CHARGE TERMINATION

The TPS658600 monitors the charging current during the voltage regulation phase. Charge is terminated when the charge current is lower than an internal threshold, set to 10% (typ) of the fast charge current rate. The termination point applies to both AC and USB charging, and it can be calculated as shown in Equation 3.

$$I_{TERM} = \frac{K_{TERM}}{R_{ISET}} \tag{3}$$

where K_{TERM} is the termination constant detection factor.

The termination current may be scaled using I²C register CHG3 bits ITERM[1:0].

The termination detection is internally deglitched by $T_{DGL(TERM)}$, 25ms typ. When the charge current drops below the internal termination threshold for $t > T_{DGL(TERM)}$, the bit ITERM is set to 1 in the status register \overline{STAT} , indicating that termination was detected. ITERM is not affected by the state of TERMOFF control bit, and it will always report the charge current status. If the termination is enabled (TERMOFF cleared to 0) and termination is detected, the charge cycle ends and the charger is turned off.

CHARGE CURRENT DPM OR DPPM OR TERMINATION TERMINATION BELOW TERMINATION THERMAL LOOP **CHARGER MODE DETECTION ENABLED** DETECTED, **THRESHOLD** ACTIVE VIA I²C $I(BAT) < I_{TERM}$ NO Χ Χ NO YES Χ Χ OFF NO YES Χ SUSPEND Χ NO Χ YES ON NO NO YES YES ON YES NO YES NO ON YES YES

Table 3-12. Termination Detection Conditions

The termination detection is latched and it will be reset only when a new charge cycle starts.

The I²C charge status bits in the STAT2 register only indicate DONE state when termination is detected.

3.35 STARTING A NEW CHARGE CYCLE

A new charge cycle will start only if the voltage on the BAT pin falls below the $V_{(RCH)}$ threshold for a time longer than $T_{DGL(RCH)}$, 25ms (typ). A new charge cycle also starts when bit CHGON (CHG1 register) changes from $\bf 0$ to $\bf 1$, or if both AC and USB input power are removed and then one or both are re-inserted.

After termination is detected a new battery pack insertion detection will not start a new charge cycle, even if $V(BAT) < V_{(RCH)}$.

3.36 PRE-CHARGE SAFETY TIMER

The TPS658600 activates an internal safety timer during the battery pre-conditioning phase. The pre-charge safety timer value is set internally to a fixed value, T_{PRECHG} , 30 min or 60 min typ, selectable via I^2C . The pre-charge safety timer is disabled when the termination is disabled via I^2C (bit TERMOFF=HI, register CHG1) or when CHTMREN=**0** at the I^2C register CHG2.

When the charger is in suspend mode the pre-charge safety timer is put on hold (i.e., charge safety timer is not reset). Normal operation resumes when the charger exits the suspend mode. If V(BAT) does not reach the internal voltage threshold $V_{(PRECHG)}$ within the pre-charge timer period a fault condition is detected and the charger is turned off.



3.37 CHARGE SAFETY TIMER

As a safety mechanism the TPS658600 has a user-selectable timer that measures the total fast charge time. This timer (charge safety timer) is started at the end of the pre-conditioning period. The following values are available: 4, 5, 6, 8 hours, selectable via I²C register CHG1 bits CHGTMR. The charge safety timer is kept in reset mode when CHTMREN=0 at the I²C register CHG2. The charge safety timer is disabled when TERMOFF=1, in register CHG1. When the charger is in suspend mode, set via I²C register CHG_CONFIG bit CHGON or set by a pack temperature fault, the charge safety timer is put on hold (i.e., charge safety timer is not reset). Normal operation resumes when the charger exits the suspend mode. If charge termination is not reached within the timer period a fault condition is detected, and the charger is turned off.

3.38 TIMER FAULT RECOVERY

The TPS658600 provides a recovery method to deal with timer fault conditions. The following summarizes this method:

Condition 1: Charge voltage above recharge threshold (V_(RCH)) and timeout fault occurs.

Recovery method:

The IC waits for the battery voltage to fall below the recharge threshold. This could happen as a result of a load on the battery, self-discharge or battery removal. Once the battery falls below the recharge threshold, the IC clears the fault and starts a new charge cycle.

Condition 2: Charge voltage below recharge threshold (V_(RCH)) and timeout fault occurs.

Recovery method:

Under this scenario, the IC connects an internal pull-up resistor from VIN_CHG pin to BAT pin. This pull-up resistor is used to detect a battery removal condition and remains on as long as the battery voltage stays below the recharge threshold. If the battery voltage goes above the recharge threshold, the IC disables the pull-up resistor connection and executes the recovery method described for condition 1.

All timers will be reset and all timer fault conditions are cleared when a new charge cycle is started either via $\hat{\Gamma}$ C (toggling bit CHGON in register CHG1) or by cycling the input power. All timers are reset and all timer fault conditions are cleared when the TPS658600 enters the UVLO mode or if the LDO mode is set.

3.39 DYNAMIC TIMER CONTROL

When the charger, thermal loop or DPPM loop are active the charge current is reduced. To avoid a false termination detection when those loops are active the charger logic doubles the period of the clock used by the charge safety timer.

The clock frequency is divided by 2 when any of those loops are active and DTCON=1. The dynamic timer control may be disabled by setting control bit DTCON=0. at the CHG2 I²C register.

3.40 BATTERY DISCHARGE SWITCH

An internal switch will discharge the BAT pin to ground when the battery is not detected. This switch is enabled via I²C control bit BATDCH on register CHG1.

3.41 CHARGER STATUS

Charger status information is available at registers 0xB9, bits PACK_HOT, PACK_COLD, BATDET and BATCHGSWON; register 0xBA, bits TMRFLT, DPPM_ON, TH_ON, ITERM, STAT1 and STAT2. See STATUS REGISTERS section for bit functional description. The charger status also is indicated at pin CHG_STAT, this pin can be used as a logic level output (2v2 level) or it can be connected to an external LED.

Table 3-13. Charger Status Pin States

0xBA[2] (STAT1)	0xBA[1] (STAT2)	CHARGER STATE	CHG_STAT LEVEL
0	0	Pre-Charge	Н
0	1	Charge Done	LO
1	0	Fast Charge	HI
1	1	Charge Suspend, Timer fault	LO

3.42 TPS658600 OPERATING MODES

The TPS658600 has an internal state machine that sets the operating modes based on the system status and host commands. The state machine directly controls the state of the integrated supplies during power-up sequences and normal operation. It also can change the on/off state of all integrated power supplies and peripherals to implement protection functions or execute external hardware control or host software commands.

TEXAS INSTRUMENTS

3.43 STATE MACHINE DIAGRAM

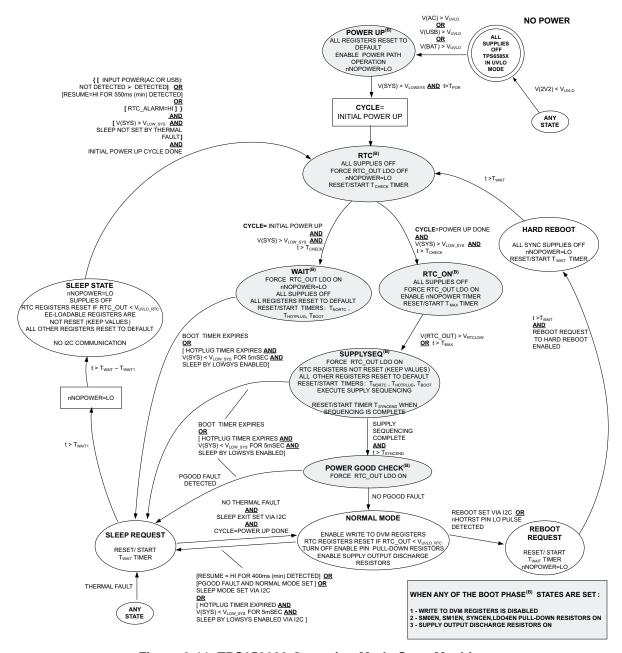


Figure 3-11. TPS658600 Operation Mode State Machine

The state machine transitions for the TPS658600 have been defined as shown below.

- 1. Supply sequencing started only when LDO4EN voltage level is a logic high
- 2. REBOOT REQUEST state transitions to the HARD REBOOT state
- 3. Supply sequencing is considered complete only if SM0 is turned ON
- 4. Sequencer goes into sleep during initial power-up cycle and ONLY RESUME pin can trigger exit from sleep state

3.44 STATE MACHINE DESCRIPTION

In a normal power-up sequence the state machine will step through the following states:

POWER-UP: If the internal digital supply (2V2) is below the internal UVLO threshold, V_{UVLO} (2V typ), all IC blocks are disabled and the TPS658600 is not operational. When the 2V2 supply voltage rises above V_{UVLO} , the POWER-UP state is entered, an internal delay (T_{POR} , 8ms typ) is started and the SYS power path is enabled. The SYS pin voltage is sensed by an internal comparator, and compared to the internal threshold V_{LOW_SYS} . When the power-on-reset delay expires and $V(SYS) > V_{LOW_SYS}$ the TPS658600 enters the RTC mode.

RTC: When the RTC state is set the nNOPOWER pin is pulled to ground, discharging the external capacitor connected to pin TNOPOWER and resetting the NOPOWER timer. The RTC_OUT LDO is turned off, and the voltage at pin RTC_OUT is flagged as low if $V(RTC_OUT) < V_{RTCLOW}$ The RTC state ends when the timer T_{CHECK} expires.

RTC_ON: When the state RTC_ON is set the integrated current source connected to the TNOPOWER pin and the RTC_OUT LDO are enabled. If the RTC_OUT voltage was flagged as low in the RTC state the T_{NORTC} timer is enabled, and the \overline{NORTC} pin is pulled low until $V(RTC_OUT) > V_{RTC_PGOOD}$. The T_{NORTC} timer starts counting when RTC_OUT $> V_{RTC_LOW}$, and \overline{NORTC} will be set to hi when $t > T_{NORTC}$.

The TNOPOWER current source will remain ON until a new reboot cycle or sleep cycle is set, charging the external capacitor connected to the TNOPOWER pin. The NOPOWER pin will be at a low logic level until the TNOPOWER pin voltage is above an internal threshold (1.23v typ). When NOPOWER pin transitions from LO→HI, a 250µsec (typ) positive going pulse is generated at CHG_STAT pin. The TNOPOWER external capacitor is discharged whenever the sequencer sets the NOPOWER pin to a low state.

The RTC_ON state ends when $V(RTC_OUT) > V_{RTC_PGOOD}$ or when the internal watchdog timer T_{MAX} expires.

WAIT: The TPS658600 will go into the WAIT state when exiting the RTC state during the initial power-up cycle. To avoid undesired lockup conditions this operational mode should be used only when the boot timer is enabled.

Three internal timers are started when the state machine enters the WAIT state. These timers run independent of the sequencing state and have the following functionality:

- BOOT Timer (T_{BOOT}): Sets the TPS658600 in the SLEEP REQUEST state if it expires during WAIT state.
- HOTPLUG Timer (T_{HOTPLUG}): SLEEP REQUEST state set by V(SYS) < V_{LOWSYS} is inhibited until this timer expires
- NORTC Timer (T_{NORTC}): NORTC pin will be set to a logic low level until this timer expires

The BOOT timer value is set to 500ms and the NORTC pulse width is set to 10ms.

SUPPLYSEQ: During the SUPPLYSEQ state all the internal supplies, with exception of RTC_OUT, are initially turned off and then turned on according to a pre-programmed internal sequencing. Three internal timers are started when the state machine enters the SUPPLYSEQ state. These timers run independent of the sequencing state and have the following functionality:

- BOOT Timer (T_{BOOT}): Sets the TPS658600 in the SLEEP REQUEST state if it expires during SUPPLYSEQ state.
- HOTPLUG Timer (T_{HOTPLUG}): SLEEP REQUEST state set by V(SYS) < V_{LOWSYS} is inhibited until this timer expires
- NORTC Timer (T_{NORTC}): NORTC pin will be set to a logic low level until this timer expires

The BOOT timer value is set to 500ms and the NORTC pulse width is set to 10ms.

The I²C engines are available while the device is in the SUPPLYSEQ state, however write operations to the DVM registers are disabled, refer to DVM register section for more details. The TPS658600 remains in this state until all the supplies are sequenced and the internal delay T_{SYNCEND} (5ms typ) has expired.

POWER GOOD CHECK: Supplies that were powered up during the SUPPLYSEQ state will have their power good flags checked during the POWER GOOD CHECK state (with exception of RTC_OUT Ido). The POWER GOOD CHECK state ends and the NORMAL state is set when a power good fault is not present. If a power good fault is detected, the POWER GOOD CHECK state will move to the SLEEP REQUEST state when the boot timer expires.

NORMAL STATE: In this state write operations to the DVM registers are enabled and the external host controls all the TPS658600 functions. The normal state operation ends if a fault condition (defined as either a thermal fault, V(SYS) < V_{LOW_SYS} or a supply power good fault) is detected or if hardware or software commands trigger a sleep or reboot request. While in NORMAL mode, the host can mask any of the power supply power good fault detection via I²C registers PGFLTMASK1 and PGFLTMASK2. Supplies that have their power good fault detection masked will not end the normal state operation. However, the status bit for the supply indicates that the output voltage is out of regulation. A RTC_OUT LDO power good fault does not trigger a transition to SLEEP REQUEST.

PGFLTMASK1 [Addr 0x4D] Defaults in BOLD Bit Number B6 **B**5 B3 B2 B1 B0 Bit Name MASK_PLDO8 MASK_PLDO7 MASK_PLDO6 MASK_PLDO4 MASK_PLDO3 MASK_PLDO2 MASK_PLDO1 MASK_PLDO0 MASK MASK MASK MASK MASK MASK MASK MASK Function PGOODLDO8 PGOODLDO7 PGOODLDO6 PGOODLDO4 PGOODLDO3 PGOODLDO2 PGOODLDO1 PGOODLDO0 UNMASKED **UNMASKED UNMASKED UNMASKED UNMASKED** UNMASKED **UNMASKED** UNMASKED When 0 When 1 MASKED MASKED MASKED MASKED MASKED MASKED MASKED MASKED PGFLTMASK2 [Addr 0x4E] Defaults in BOLD Bit Number B6 B5 MASK_PLDO9 Bit Name MASK_PSM3 MASK_PSM2 MASK_PSM1 MASK_PSM0 MASK_PLDO5 RSVD4E1 RSVD4E0 MASK MASK MASK MASK MASK MASK NOT USED Function NOT USED PGOODLD09 PGOODLDO5 PGOODSM3 PGOODSM2 PGOODSM1 PGOODSM0 UNMASKED UNMASKED MASKED UNMASKED **UNMASKED** When 0 UNMASKED NOT USED **NOT USED** MASKED UNMASKED MASKED MASKED NOT USED When 1 MASKED MASKED NOT USED

Table 3-14. Sequencer Power Good Fault Masking

SLEEP REQUEST: The SLEEP REQUEST state is set at anytime when a thermal fault condition is detected. It is also set when the TPS658600 is in the NORMAL state followed by one of the events shown below.

- 1. A hardware sleep request is detected at the RESUME pin.
- 2. A power good fault is detected at any of the integrated supplies
- 3. V(SYS_IN) < V_{LOW SYS} and the HOTPLUG timer has expired (t > T_{HOTPLUG})
- 4. SLEEP MODE is 1 (register 0x14, bit B3)

When the SLEEP REQUEST state is set an internal timer is started and bit SLEEPREQ=1 is set in register STAT3 (address 0xBB). Writing EXITSLREQ to 1 (0x14, bit B1) returns the TPS658600 to the NORMAL state. If no action is taken by the host, while SLEEP_REQUEST state is set, the $\overline{\text{NOPOWER}}$ pin is pulled low when T_{WAIT} expires and the SLEEP state is entered after the T_{WAIT} timer expires.

Table 3-15. Sequencer Control, LDO5/LDO9 Enable

SUPPLYENE [A	SUPPLYENE [Addr 0x14]							
Bit Number	B7	B6	B5	B4	В3	B2	B1	B0
Bit Name	LDO9_ON	LDO5_ON	SYSINEN	HOTDLY	SLEEP MODE	RSVD	EXITSLREQ	SOFT RST
Function	LDO9 ON/OFF CONTROL	LDO5 ON/OFF CONTROL	SYS_IN LOW VOLTAGE SETS SLEEP MODE	HOT RESET DEGLITCH	SET TPS658600 IN SLEEP MODE		SLEEP REQUEST EXIT CONTROL	SOFTWARE RESET CONTROL
When 0	OFF	OFF	DISABLED	5µsec min, 16µsec max	NOT ACTIVE		GO TO SLEEP at T>T _{wait}	NOT ACTIVE

Table 3-15. Sequencer Control, LDO5/LDO9 Enable (continued)

When 1	ON	ON	ENABLED	5ms	SET SLEEP		FORCE TRANSITION TO NORMAL STATE	REBOOT REQUEST	
--------	----	----	---------	-----	-----------	--	---	-------------------	--

SLEEP STATE: When the SLEEP state is set all supplies are set to OFF mode (with exception of RTC_LDO) and the NOPOWER output is pulled low. A few internal blocks are still active, enabling detection of system status changes that trigger the SLEEP state exit.

All I²C engines are reset and all RAM registers are reset to their default condition when the SLEEP state is set. The RAM bits that have a default set via the non-volatile memory will keep the value they had before the SLEEP state was set.

The SLEEP state ends when one of the following sequences is executed:

- A. If SLEEP was set by thermal fault: The SLEEP state will end only when all external input supplies and battery pack are removed and an UVLO condition is detected by the TPS658600, setting the POWER UP state.
- B. If SLEEP was not set by thermal fault: The SLEEP state will end when a hardware sleep exit request is detected at RESUME pin

EXITING THE SLEEP STATE: The figure below shows the timing relationship needed on the RESUME pin to exit the sleep mode. This applies for all cases where the sleep mode entry was triggered by any event other than a thermal fault.

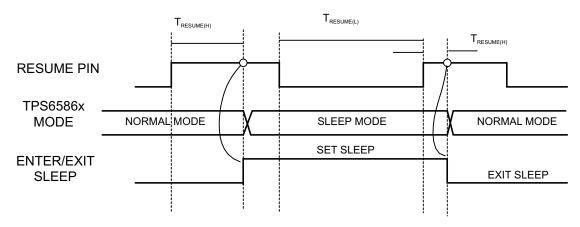


Figure 3-12. Entering and Exiting Sleep Mode Resume

REBOOT REQUEST: The REBOOT REQUEST state is entered from the NORMAL state. It can be set via software (SOFT_RST set to 1, register 0x14 Bit B0) or by a V_{IL} level detection at \overline{HOTRST} pin. When the reboot request state is set an internal timer T_{WAIT} (10ms typ) is started, and the $\overline{NOPOWER}$ pin is pulled to ground. The reboot request ends when t > T_{WAIT} . The REBOOT REQUEST will transition the device state machine to the HARD REBOOT state. The REBOOT REQUEST is set if the \overline{HOTRST} low pulse width is greater than 10µsec (typ).

The status bit COMPDET=1 (register STAT2, address 0xBA) when the NORMAL state is entered after a reboot cycle triggered by the HOTRST pin. The status bit COMPDET=0 when the NORMAL state is entered, after a power-up, sleep cycle or software triggered reboot cycle.

The bit COMPDET is reset to **0** when bit SPARECC0=**1**, in register SPARE2 (address 0xCC). After resetting the COMPDET bit the host needs to set SPARECC0=0 to enable detection of another reboot cycle set via the HOTRST pin.



An interrupt is generated when the TPS658600 transitions from the POWER GOOD CHECK state to the NORMAL state, COMPDET=1 and IMASK_COMP=0 in register INTMASK4 (address 0xB3). An interrupt request is generated after the NORMAL state is set if IMASK_COMP=0 and COMPDET value changes from 1 to 0.

Table 3-16. Reboot Flag Control

SPARE2 [Add	r 0xCC]						De	faults in BOLD
Bit Number	B7	В6	B5	B4	В3	B2	B1	В0
Bit Name	SPARECC7	SPARECC6	SPARECC5	SPARECC4	SPARECC3	SPARECC2	SPARECC1	SPARECC0
Function	SPARE	RESET REBOOT BY HOTRST STATUS BIT						
When 0	NOT USED	DO NOT RESET						
When 1	NOT USED	RESET						

HARD REBOOT: The HARD REBOOT state powers down all the TPS658600 supplies, with exception of the RTC OUT LDO.

SUPPLYLOAD: When the SUPPLYLOAD state is set all the registers are reset to their defaults, and the non-volatile memory is reloaded into the RAM. The supplies are not sequenced, and they will return to their on/off and output voltage defaults upon entering the SUPPLYLOAD state (on/off, default voltages). The timers T_{BOOT} , $T_{HOTPLUG}$ and $T_{SYNCEND}$ are reset and started. The SUPPLYSEQ state ends when $t > T_{SYNCEND}$, and the POWER GOOD CHECK state is set.

3.45 C_{NOPOWER} CAPACITOR DISCHARGE

The external capacitor connected to the TNOPOWER pin is always discharged when the sequencer sets NOPOWER=LO in the following states: POWER-UP, RTC, REBOOT REQUEST, HARD REBOOT and SLEEP. For large capacitance values (above 330nF) the external capacitor may not be fully discharged during reboot cycles, and as a result the NOPOWER pulse width may be slightly reduced when compared to the value indicated in the parametric tables.

3.46 SEQUENCER STATUS

Sequencer status information is available at registers 0xBA, bit COMPDET and register 0xBB bits SLEEPREQ and RESUME. See STATUS REGISTERS section for functional description of these bits.

3.47 SUPPLY SEQUENCING AND HOST INTERFACE

3.47.1 Integrated Supply Sequencing

The TPS658600 enables the implementation of complex supply sequencing. With the exception of RTC_OUT, the integrated power-up sequencing starts when the TPS658600 state machine enters the SUPPLYSEQ state. The RTC_OUT LDO is always enabled in the RTC state, which occurs before the SUPPLYSEQ state, and the output of this LDO can be used to power an external processor or circuitry in systems where the supply sequencing is controlled externally using pins SM0EN, SM1EN or SYNCEN.

Each supply rail is controlled by a combination of its default status (ON or OFF), its assigned sequencing trigger group (INTERNAL, SM0EN, SM1EN or SYNCEN), and a delay time.

The default status (ON or OFF) of each rail is shown in Table 3-17.

If the default for a supply rail is ON the trigger group associated to the supply determines the control signal that initiates the delay time to the start of the rail power up. There are four trigger groups, one internal and three external pins:

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INTERNAL This group is controlled by an internal signal that goes high when the TPS658600 goes

from the RTC_ON state to the SUPPLYSEQ state.

This group is controlled by the falling edge of the SM0EN pin and starts when the pin **SM0EN**

voltage is below its V_{II} level.

SM1EN This group is controlled by the rising edge of the SM1EN pin and starts when the pin

voltage is above its V_{IH} level.

SYNCEN This group is controlled by the rising edge of the SYNCEN pin and starts when the pin

voltage is above its V_{IH} level.

The trigger group of each rail and its associated delay is shown in Table 3-17. If a supply rail has a default state of ON and the appropriate trigger is high, the rail will be turned on after the delay time for that rail has expired. The delay time starts when the trigger signal for that supply has gone high, while SUPPLYSEQ state is set. No delays are available after NORMAL mode is set.

Table 3-17. TPS658600 Integrated Supply Power-Up Defaults

	TPS658600 SETTINGS									
SUPPLY	DEFAULT STATE	DEFAULT VOLTAGE	TRIGGER	DELAY						
LDO0	ON	2.85V	SM1EN	15ms						
LDO1	ON	1.2V	INTERNAL	Value applies to LDO0, LDO1						
LDO2	ON	1.2V	INTERNAL	0ms						
LDO3	OFF	1.8V	SM1EN	Value applies to LDO2, LDO3						
LDO4	OFF	1.8V	INTERNAL	2.5 ms						
LDO6	ON	2.85V	SYNCEN							
LDO7	OFF	2.85V	INTERNAL	2.5ms Value applies to LDO6, LDO7 and LDO8						
LDO8	ON	2.85V	SYNCEN	value applies to EDOO, EDO7 and EDOO						
LDO5	OFF	2.85V	SM1EN	3.75ms						
LDO9	OFF	2.85V	Trigger applies to both LDO5 and LDO9	Value applies to LDO5, LDO9						
SM0	ON	1.2V	SM0EN	2.5ms						
SM1	ON	1.8V	SM1EN	15ms						
SM2	OFF	4.4V	INTERNAL	15ms						

3.48 INTEGRATED SUPPLY SEQUENCING – SUPPLY ENABLE CONTROL

The ON or OFF mode for each supply is defined by the supply enable RAM control bits and enable pins SM0EN, SM1EN and LDO4EN. The supply enable bits are located in registers SUPPLYENA, SUPPLYENB, SUPPLYENC, SUPPLYEND, SUPPLYENE (see supply functional description for more details). The functionality of the RAM bits and enable pins is dependent on the state set in the state machine as follows:

When the NORMAL state is NOT set: The pins SM1EN, SM0EN and LDO4EN will always control the ON or OFF modes for all supplies that use them as triggers. The supply enable RAM bits will control the ON or OFF modes for the supplies.

When the NORMAL state is set: The supply enable RAM bits will always control the ON or OFF modes for the supplies. The pins SM1EN, SM0EN and LDO4EN may control the ON or OFF modes for supplies SM1, SM0 and LDO4. The enable pins do not control the ON or OFF modes of any other supplies.

During sequencing, the following RAM bits control the supply ON/OFF mode: LDO2 RAM bits, LDO4 RAM bits, SM0 RAM bits and SM1 RAM bits.

When the NORMAL mode is set, SM0EN controls the SM0 ON/OFF mode, SM1EN controls the SM1 ON/OFF mode and LDO4EN controls the LDO4 ON/OFF mode.

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3.49 INTEGRATED SUPPLY SEQUENCING - POWER-DOWN

To start a power down sequence the SLEEP REQUEST or REBOOT REQUEST states must be set. Once one of those two states is set the trigger pins are active again and they will control the ON/OFF state of the supplies associated with that trigger group. The device will enter the SLEEP or HARD REBOOT state 10ms after the SLEEP REQUEST or REBOOT REQUEST is initiated. Any supply still active when the SLEEP or HARD REBOOT state is entered will be immediately disabled. This is the default turn off condition for any supply associated with the INTERNAL sequencing trigger group.

For example, if a supply has a default state of OFF and it has SM1EN as the selected factory trigger: this supply will not power up during the SUPPLYSEQ state when SM1EN goes high. If it is enabled during the NORMAL state and is still enabled when the SLEEP REQUEST or REBOOT REQUEST states are entered, this supply will be turned off on the falling edge of SM1EN as this is its assigned trigger group programmed at the factory.

If LDO4EN is set LO by the host when the TPS658600 enters the SLEEP REQUEST or REBOOT REQUEST states, the LDO4 supply will turn off only when the HARD REBOOT or SLEEP states are set. The LDO4PG pin will be pulled low when LDO4EN is below $V_{\rm IL}$, with no delay.

All the supplies are turned off at the same time when the TPS658600 enters the SLEEP or HARD REBOOT state.

3.50 HOST INTERFACE

The TPS658600 devices have multiple signals that can be used by the external system to execute power sequencing operations or verify the system status. Those signals are generated as follows:

- 1. Power supply status (2V2 logic level): SM0PG, SM1PG, LDO4PG A HI level indicates that the supply is on and the regulation voltage is valid. A LO level indicates either that the supply voltage is out of regulation or that the supply has been disabled.
- 2. External system and host control (V32K pin logic level): The NOPOWER, NORTC, and OUT32K pins may be used to interface to external hosts, controlling the host reset and executing host-controlled power-up sequencing.

3.51 EXTERNAL 32 kHz

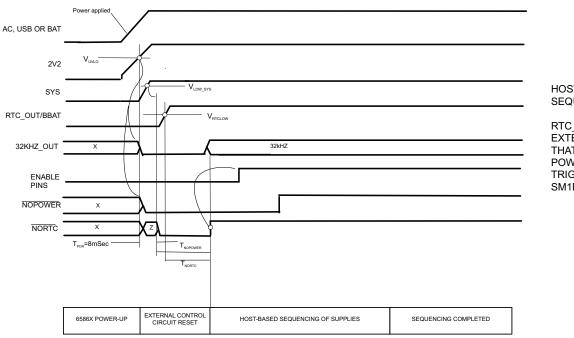
The TPS658600 outputs a 32 kHz clock (pin OUT32K) that can be used by the external system. The OUT32K output starts when the $\overline{\text{NORTC}}$ pin is above V_{IH} and V32K is valid. The 32 kHz can be derived either from an internal 32kHz oscillator or from a crystal-based clock, selectable via I²C using bit 6 of the RTC_CTRL (Addr 0xC0) register (see the Real Time Clock section). However, only the crystal-based clock is output to the OUT32K pin.

3.52 SUPPLY INPUT PIN CONNECTION

The input pins for all supplies (VIN_LDO01, VIN_LDO23, VIN_LDO4, VIN_LDO678, VIN_LDO9) enable optimization of the overall system power architecture by connecting lower output voltage supplies to intermediate rails or external rails. Care must be taken to ensure that the input pin for each integrated supply is powered when the supply is enabled during the power-up sequencing. Failure to do so will result in a power good fault detection with a potential lock-up situation. The input pins VIN_SM0, VIN_SM1, VIN SM2 must be connected to the SYS pin

3.53 HOST INTERFACE

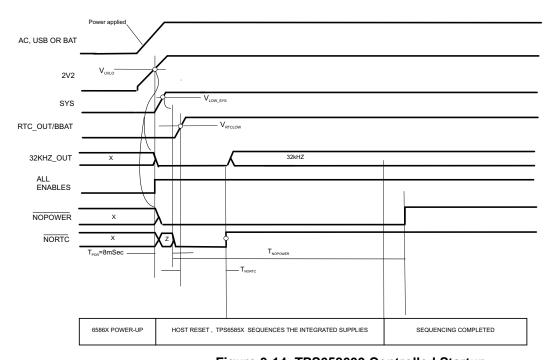
The TPS658600 may be used in systems where the sequencing is controlled by an external host or housekeeping circuit, as well as in systems where stand-alone sequencing is a requirement. For host controlled systems the RTC_OUT LDO can be used as the supply that powers the external sequencing control and the NOPOWER and NORTC pin signals are used as resets for the external circuit.



HOST CONTROLLED SEQUENCING:

RTC_OUT SUPPLIES EXTERNAL CIRCUIT THAT DRIVES SUPPLY POWER-UP USING TRIGGER PINS SM0EN, SM1EN, SYNCEN

Figure 3-13. Host Controlled Startup



6586X SEQUENCING:

HOST IS KEPT IN
RESET MODE UNTIL
6586X SEQUENCES ALL
SUPPLIES FOLLOWING
INTERNAL,
PRE-DEFINED TIMING.
ALL ENABLE PINS
CONNECTED TO 2V2

Figure 3-14. TPS658600 Controlled Startup

3.54 INTEGRATED SUPPLIES - ENABLE CONTROL, DVM CONTROL

3.54.1 DVM and Non-DVM Supplies

The TPS658600 has two types of voltage control for the integrated supplies:

1. DVM supplies: SM0, SM1, LDO2 and LDO4 are DVM supplies with dedicated register sets that enable a controlled transition from an initial voltage to a final voltage. The initial voltage, final voltage, and voltage transition start time are set via I²C. SM0 and SM1 have I²C programmable slew rate.



2. NON-DVM supplies: LDO0, LDO1, LDO3, LDO5, LDO6, LDO7, LDO8, LDO9, SM2 and RTC_OUT outputs can be changed, but without slew rate and transition start time control. The output of these supplies will be changed to the new value as soon as TPS658600 sends the ACK of the I²C command setting the new output voltage.

3.54.2 DVM and Non-DVM Supply Enable

All the integrated supplies can be turned on/off by RAM enable bits. All the supplies (with exception of LDO5, LDO9 and RTC_OUT LDO's) have two enable bits on distinct registers (registers 0x10, 0x11, 0x12, 0x13, 0x14). A supply will be enabled when ANY of its enable bits, in the registers below, are set to 1. Each supply will be disabled when ALL of the enable bits for that supply are set to 0. For example: SM0 enabled: SM0_ENA=1 *OR* SM0_ENB=1, SM0 disabled: SM0_ENA=0 *AND* SM0_ENB=0

Table 3-18. SM0-2, LDO0-9 Control

SUPPLYENA	[Addr 0x10]						De	faults in BOLD			
Bit Number	B7	B6	B5	B4	В3	B2	B1	B0			
Bit Name	RSVD107	RSVD106	RSVD105	RSVD104	LDO2_ENA1	LDO2_ENA0	SM0_ENA	SM1_ENA			
Function	NOT USED	NOT USED	NOT USED	NOT USED	LDO2 CONTROL	LDO2 CONTROL	SM0 CONTROL	SM1 CONTROL			
SUPPLYENB	[Addr 0x11]						De	faults in BOLD			
Bit Number	B7	B6	B5	B4	В3	B2	B1	B0			
Bit Name	RSVD117	RSVD116	RSVD115	RSVD114	LDO2_ENB1	LDO2_ENB0	SM0_ENB	SM1_ENB			
Function	NOT USED	NOT USED	NOT USED	NOT USED	LDO2 CONTROL	LDO2 CONTROL	SM0 CONTROL	SM1 CONTROL			
SUPPLYENC [Addr 0x12]											
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0			
Bit Name	SM2_ONC	LDO8_ONC	LDO7_ONC	LDO6_ONC	LDO4_ONC	LDO3_ONC	LDO1_ONC	LDO0_ONC			
Function	SM2 CONTROL	LDO8 CONTROL	LDO7 CONTROL	LDO6 CONTROL	LDO4 CONTROL	LDO3 CONTROL	LDO1 CONTROL	LDO0 CONTROL			
SUPPLYEND [Addr 0x13]											
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0			
Bit Name	SM2_OND	LDO8_OND	LDO7_OND	LDO6_OND	LDO4_OND	LDO3_OND	LDO1_OND	LDO0_OND			
Function	SM2 CONTROL	LDO8 CONTROL	LDO7 CONTROL	LDO6 CONTROL	LDO4 CONTROL	LDO3 CONTROL	LDO1 CONTROL	LDO0 CONTROL			
SUPPLYENE [[Addr 0x14]						De	faults in BOLD			
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0			
Bit Name	LDO9_ON	LDO5_ON	SYSINEN	HOTDLY	SLEEP MODE	SETNORMAL	EXITSLREQ	SOFT RST			
Function	LDO9 ON/OFF CONTROL	LDO5 ON/OFF CONTROL	SYS_IN LOW VOLTAGE SETS SLEEP MODE	HOT RESET DEGLITCH	SET TPS658600 IN SLEEP MODE	SET TPS658600 IN NORMAL MODE	SLEEP REQUEST EXIT CONTROL	SOFTWARE RESET CONTROL			
When 0	OFF	OFF	DISABLED	5μsec min, 16μsec max	NOT ACTIVE	NORMAL MODE NOT SET	GO TO SLEEP at T>Twait	NOT ACTIVE			
When 1	ON	ON	ENABLED	5ms	SET SLEEP	ENABLE NORMAL MODE	FORCE TRANSITION TO NORMAL STATE	REBOOT REQUEST			

LDO5 and LDO9 will be turned on when LDO5_ON is 1 or LDO9_ON is 1, respectively. The RTC_OUT LDO enable bits are located in the RTC control register, see real time clock section for details.

The supply enable defaults are unique for each device. See App Notes for device specific settings.

3.54.3 DVM Supplies - Voltage Transition Control

The output voltage for the DVM supplies can be set to one of the values programmed in the voltage setting registers SM0V1, SM0V2, SM1V1, SM2V2, LDO2AV1, LDO2AV2, LDO2BV1, LDO2BV2, LDO4V1 and LDO4V2 in registers VCC1 and VCC2.

The voltage change for the DVM supplies is usually done with 2 l²C write commands:

- 1. The host writes the new voltage to the voltage setting register for the supply(s) that will have an output voltage modification.
- 2. The voltage change starts by setting specific control bits in registers VCC1 and VCC2.

Bits $\overline{\text{VS}}$ in registers VCC1 and VCC2 select the next voltage for the DVM supplies. A voltage change is started when ANY of the $\overline{\text{GO}}$ bits for the supply is set to 1. At the end of the voltage transition the GO bits are cleared by the internal logic.

Table 3-19. DVM Supply Control

VCC1 [Addr	VCC1 [Addr 0x20] Defaults in BOLD												
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0					
Bit Name	LDO4VS	LDO4GO	LDO2AVS2	LDO2AGO2	SM0VS1	SM0GO1	SM1VS1	SM1GO1					
Function	DON LDO4 VOLTAGE SELECTION		LDO2 VOLTAGE	SELECTION	SM0 VOLTAG	E SELECTION	SM1 VOLTAG	E SELECTION					
When 0	SELECT VOLTAGE SET BY LDO4V1	HOLD CURRENT VOLTAGE	NOT USED	HOLD CURRENT VOLTAGE	SELECT VOLTAGE SET BY SM0V1	HOLD CURRENT VOLTAGE	SELECT VOLTAGE SET BY SM1V1	HOLD CURRENT VOLTAGE					
When 1	SELECT VOLTAGE SET BY LDO4V2	RAMP TO VOLTAGE SELECTED BY LDO4VS	NOT USED	RAMP TO VOLTAGE SELECTED BY LDO2BVS1	SELECT VOLTAGE SET BY SM0V2	RAMP TO VOLTAGE SELECTED BY SM0VS1	SELECT VOLTAGE SET BY SM1V2	RAMP TO VOLTAGE SELECTED BY SM1VS1					
VCC2 [Addr	0x21]			•			De	faults in BOLD					
VCC2 [Addr Bit Number	0x21] B7	B6	B5	B4	В3	B2	De B1	faults in BOLD					
-	· -	B6 LDO2BGO1	B5 LDO2AVS1	B4 LDO2AGO1	B3 SM0VS2	B2 SM0GO2	_						
Bit Number	B7 LDO2BVS1 LDO2 V	-		LDO2AGO1	SM0VS2		B1 SM1VS2	В0					
Bit Number Bit Name	B7 LDO2BVS1 LDO2 V	LDO2BGO1	LDO2AVS1	LDO2AGO1	SM0VS2	SM0GO2	B1 SM1VS2	B0 SM1GO2					

Table 3-20. SM0 and SM1 Voltage Selection Register Settings

	SM0 OUTPUT VOLTAGE SELECTION				SM1 OUTPUT VOLTAGE SELECTION			
SM0VS1	SM0VS2	SM0GO1=1 OR SM0GO2=1 STARTS VOLTAGE TRANSITION TO VALUE SET BY REGISTER :		SM0VS1	SM0VS2	SM1GO1=1 OR SM1GO2=1 STARTS VOLTAGE TRANSITION TO VALUE SET BY REGISTER		
0	0	SM0V1		0	0	SM1V1		
0	1	SM0V2		0	1	SM1V2		

Table 3-20. SM0 and SM1 Voltage Selection Register Settings (continued)

	SM0 OUTPUT VOLTAGE SELECTION			SM1 OUTPUT VOLTAGE SELECTION				
1	0	SM0V2		1 0 SM1V2				
1	1	SM0V2		1	1	SM1V2		

Table 3-21. SM0 Voltage Selection by SM0EN

SM0 ACTIVE LEVEL	SM0EN	SM0 OUTPUT VOLTAGE		
0	0	1.2V		
0	1	OFF		

The SM0 output voltage value and transition is controlled by the SM0EN pin and SM0VS1/SMVS2.

NOTE

During a HI to LO transition of SM0EN (enabling SM0), the SM0 output will power up to the pre-defined default state regardless of the setting set via I²C prior to SM0 being disabled.

Table 3-22. SM0 Output Voltage Settings Available for SM0EN Selection

RANGE	[4:0]	VOUT (V)						
0.725V-1.50V	00000	0.725	01000	0.925	10000	1.125	11000	1.325
	00001	0.750	01001	0.950	10001	1.150	11001	1.350
	00010	0.775	01010	0.975	10010	1.175	11010	1.375
	00011	0.800	01011	1.000	10011	1.200	11011	1.400
	00100	0.825	01100	1.025	10100	1.225	11100	1.425
	00101	0.850	01101	1.050	10101	1.250	11101	1.450
	00110	0.875	01110	1.075	10110	1.275	11110	1.475
	00111	0.900	01111	1.100	10111	1.300	11111	1.500

Table 3-23. LDO4 Voltage Selection Register Settings

LD	LDO4 OUTPUT VOLTAGE SELECTION							
LDO4VS	LDO4GO=1 STARTS VOLTAGE TRANSITION TO VALUE SET BY REGISTER							
0	LDO4V1							
1	LDO4V2							

The LDO2 output voltage selection and GO bit functionality is shown below.

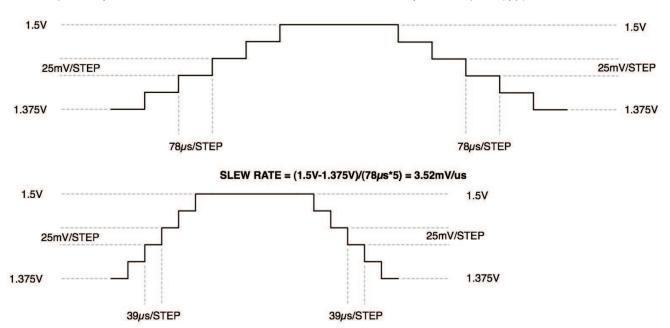
- 1. LDO2AGOn bits are not active
- LDO2BGO1=1 starts a voltage transition to the voltage selected by LDO2BV1, LDO2BV2 and LDO2BVS1
- 3. LDO2 voltage transition starts when SM0EN is set to LO

When the LDO2 output voltage is controlled by the SM0EN (CORECTRL) pin, registers LDO2AV2 and LDO2AV1 define the output voltage:

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3.54.4 DVM Supply Voltage Transition

During a voltage transition the output voltage will be stepped from the currently programmed voltage to the new target voltage as shown below. The slew rate from the initial voltage to the final voltage for SM0 and SM1 can be selected using the I²C registers SM0SL (ADDRESS = 0x25) and SM1SL (ADDRESS = 0x28) respectively. LDO2 and LDO4 have the slew rate fixed internally to 7mV/µSec(typ).



SLEW RATE = $(1.5V-1.375V)/(39\mu s*5) = 7.04mV/us$

Figure 3-15. SM0 and SM1 Dynamic Voltage Slew Rate Example

3.55 SM0, SM1, SM2 CONVERTERS

The TPS658600 has three highly efficient step down synchronous converters. The integration of the power stage switching FETs reduces the external component count, and only the external output inductor and filter capacitor are required. The integrated power stage supports 100% duty cycle operation. The converters have two possible modes of operation: a 2.25MHz fixed frequency pulse width modulation (PWM) mode at moderate to heavy loads, and a pulse frequency modulation (PFM) mode at light loads. The converters SM0, SM1 and SM2 output voltages are programmable via I²C registers SMnV1 and SMnV2 (SM0 and SM1) and SUPPLYV2 (SM2):

> NOTE VIN_SM0, VIN_SM1 AND VIN_SM2 PINS SHOULD ALWAYS BE EXTERNALLY CONNECTED TO SYS PIN

3.55.1 SM0, SM1 DVM Buck Converters - Output Voltage Registers

Table 3-24. DVM Supply Voltage and Slew Rate Selection - SM0 and SM1

SM1V1 [Addr 0x23]											
Bit Number	В7	В6	B5	B4	В3	B2	B1	В0			
Bit Name	RSVD237	RSVD236	RSVD235	SM1V1[4]	SM1V1[3]	SM1V1[2]	SM1V1[1]	SM1V1[0]			
Function	NOT USED	NOT USED	NOT USED		SM1 SUP	PLY OUTPUT \	/OLTAGE				
SM1V2 [Addr	0x24]										
Bit Number	B7	В6	B5	B4	В3	B2	B1	В0			



Table 3-24. DVM Supply Voltage and Slew Rate Selection – SM0 and SM1 (continued)

Bit Name	RSVD247	RSVD246	RSVD245	SM1V2[4]	SM1V2[3]	SM1V2[2]	SM1V2[1]	SM1V2[0]
Function	NOT USED	NOT USED	NOT USED		SM1 SUP	PLY OUTPUT \	/OLTAGE	
SM1SL [Addr	0x25]							
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0
Bit Name	RSVD257	RSVD256	RSVD255	RSVD254	RSVD253	SM1SL[2]	SM1SL[1]	SM1SL[0]
Function	NOT USED	SM1 S	SUPPLY RAMP	RATE				
SM0V1 [Addr	0x26]							
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0
Bit Name	RSVD267	RSVD266	RSVD265	SM0V1[4]	SM0V1[3]	SM0V1[2]	SM0V1[1]	SM0V1[0]
Function	NOT USED	NOT USED	NOT USED		SM0 SUP	PLY OUTPUT \	/OLTAGE	
SM0V2 [Addr	0x27]							
Bit Number	B7	В6	B5	B4	В3	B2	B1	В0
Bit Name	RSVD277	RSVD276	RSVD275	SM0V2[4]	SM0V2[3]	SM0V2[2]	SM0V2[1]	SM0V2[0]
Function	NOT USED	NOT USED	NOT USED		SM0 SUP	PLY OUTPUT \	/OLTAGE	
SM0SL [Addr	0x28]							
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0
Bit Name	RSVD287	RSVD286	RSVD285	RSVD284	RSVD283	SM0SL[2]	SM0SL[1]	SM0SL[0]
Function	NOT USED	SM0 S	SUPPLY RAMP	RATE				

The available output voltages and slew rates are shown below.

Table 3-25. SM0V1[4:0] / SM0V2[4:0] / Output Voltage Settings

RANGE	[4:0]	VOUT (V)						
0.725V-1.50V	00000	0.725	01000	0.925	10000	1.125	11000	1.325
	00001	0.750	01001	0.950	10001	1.150	11001	1.350
	00010	0.775	01010	0.975	10010	1.175	11010	1.375
	00011	0.800	01011	1.000	10011	1.200	11011	1.400
	00100	0.825	01100	1.025	10100	1.225	11100	1.425
	00101	0.850	01101	1.050	10101	1.250	11101	1.450
	00110	0.875	01110	1.075	10110	1.275	11110	1.475
	00111	0.900	01111	1.100	10111	1.300	11111	1.500

Table 3-26. SM1V1[4:0] / SM1V2[4:0] Output Voltage Settings

RANGE	[4:0]	VOUT (V)						
1.45V-3.0V	00000	1.45	01000	1.85	10000	2.25	11000	2.65
	00001	1.50	01001	1.90	10001	2.30	11001	2.70
	00010	1.55	01010	1.95	10010	2.35	11010	2.75
	00011	1.60	01011	2.00	10011	2.40	11011	2.80
	00100	1.65	01100	2.05	10100	2.45	11100	2.85
	00101	1.70	01101	2.10	10101	2.50	11101	2.90
	00110	1.75	01110	2.15	10110	2.55	11110	2.95
	00111	1.80	01111	2.20	10111	2.60	11111	3.00

Table 3-27. SM0SL[2:0] and SM1SL[2:0] Slew Rate Settings

SMxSL	SLEW RATE						
[2:0]	(mV/µs)	[2:0]	(mV/µs)	[2:0]	(mV/µs)	[2:0]	(mV/µs)
000	INSTANTLY	001	0.11	010	0.22	011	0.44



Table 3-27. SM0SL[2:0] and SM1SL[2:0] Slew Rate Settings (continued)

SMxSL	SLEW RATE						
[2:0]	(mV/µs)	[2:0]	(mV/µs)	[2:0]	(mV/µs)	[2:0]	(mV/µs)
100	0.88	101	1.76	110	3.52	111	

Table 3-28. Non-DVM supply Voltage selection - SM2, LDO8

SUPPLYV2 [A	SUPPLYV2 [Addr 0x42]										
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0			
Bit Name	VLDO8[2]	VLDO8[1]	VLDO8[0]	VSM2[4]	VSM2[3]	VSM2[2]	VSM2[1]	VSM2[0]			
Function	LDO8	OUTPUT VOL	TAGE		SM2	OUTPUT VOLT	TAGE				

Table 3-29. VSM2[4:0] Output Voltage Settings

RANGE	[4:0]	VOUT (V)						
3.0V-4.55V	00000	3.000	01000	3.400	10000	3.800	11000	4.200
	00001	3.050	01001	3.450	10001	3.850	11001	4.250
	00010	3.100	01010	3.500	10010	3.900	11010	4.300
	00011	3.150	01011	3.550	10011	3.950	11011	4.350
	00100	3.200	01100	3.600	10100	4.000	11100	4.400
	00101	3.250	01101	3.650	10101	4.050	11101	4.450
	00110	3.300	01110	3.700	10110	4.100	11110	4.500
	00111	3.350	01111	3.750	10111	4.150	11111	4.550

3.55.2 PWM Operation

During PWM operation the converters use a fast response voltage mode controller scheme with input voltage feed-forward, enabling the use of small ceramic input and output capacitors. At the beginning of each clock cycle the high side channel MOSFET switch is turned on, and the oscillator starts the voltage ramp. The inductor current will ramp-up until the ramp voltage reaches the error amplifier output voltage, when the comparator trips and the high-side channel MOSFET switch is turned off. Internal adaptive break-before-make circuits turn on the integrated low-side MOSFET switch after an internal, fixed dead-time delay, and the inductor current ramps down, until the next cycle is started. When the next cycle starts the ramp voltage is reset to its low value and the high-side channel MOSFET switch is turned on again.

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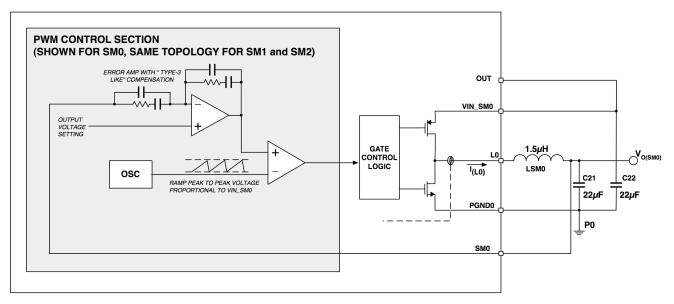


Figure 3-16. PWM Control

3.55.3 PFM Mode Operation

The TPS658600 SM0, SM1 and SM2 buck converters can be set to operate only in PWM mode or to switch automatically between PFM and PWM modes, via the I²C interface. While in the Pulsed Frequency Mode the converters operate with reduced switching frequency and with a minimum quiescent current to maintain high efficiency.

In PFM mode the converter will regulate the output voltage to 1% above the nominal output voltage. To determine when to transition between the modes, the inductor current is monitored, and the PFM mode is set when the inductor ripple current approaches zero. For duty cycles above 85% the PFM mode is entered for load currents below the threshold IPFM(ENTER).

$$I_{PFM(ENTER)} = \frac{V_{(VIN_SMx)}}{34\Omega}$$
(4)

In PFM mode the output voltage is monitored by a voltage comparator, which regulates the output voltage to the programmed value $V_{O(SM1)}$. If the output voltage is below $V_{O(SM1)}$ the PFM control circuit turns on the power stage, applying a burst of pulses to increase the output voltage. When the output voltage exceeds the target regulation voltage $V_{O(SM1)}$ the power stage is disabled, and the output voltage will drop until it is below the regulation voltage target, when the power stage is enabled again.

The PFM operation is disabled and PWM operation set if one of the following events happens during PFM operation:

- 1. The burst operation exceeds 7µs, typ.
- 2. The output voltage falls below 3% of the target regulation voltage in PFM mode (2% of the nominal output voltage in PWM mode)

3.55.4 Setting the PWM/PFM Mode

In TPS658600 the PWM mode can be forced for each converter by setting the bit SMn_PWM to 1 in the SMODE1 register. If bits SMn_GPIO is 1, the GPIO will control the PWM or PFM mode setting, and bits SMn_PWM are ignored.



Table 3-30. SM0,SM1, SM2 PWM/PFM Mode Selection

SMODE1 [Addr 0x47]											
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0			
Bit Name	RSVD477	SM2_GPIO	SM1_GPIO	SM0_GPIO	RSVD473	SM2_PWM	SM1_PWM	SM0_PWM			
Function	SPARE	SM2 AUTO PFM CONTROL SELECTION	SM1 AUTO PFM CONTROL SELECTION	SM0 AUTO PFM CONTROL SELECTION	SPARE	SM2 PWM MODE ON	SM1 PWM MODE ON	SM0 PWM MODE ON			

Table 3-31 details how the GPIO control is implemented. Note that the GPIO1 polarity indicated in Table 3-31 is controlled by bit GPIOINV, register 0x5E.

Table 3-31. GPIO1 PWM/PFM Mode Control

SMx_GPIO	SMx_PWM	GPIO1 POLARITY	GPIO1	CONVERTER MODE
0	0	х	x	Auto PWM/PFM
0	1	х	x	PWM Only
1	х	Inverted	0	PWM Only
1	х	Inverted	1	Auto PWM/PFM
1	х	Not Inverted	0	Auto PWM/PFM
1	х	Not Inverted	1	PWM Only

3.55.5 Output Discharge Switches

When the SM0, SM1 and SM2 converters are disabled, an integrated switch automatically discharges the converter output capacitor.

The converter output discharge switches are always enabled when NORMAL state is set and during the SUPPLYSEQ state.

3.55.6 Dynamic Voltage Positioning

This feature reduces the voltage under/overshoots at load steps from light to heavy load and vice versa. It provides more headroom for both the voltage drop at a load step and the voltage increase at a load throw-off. This improves load transient behavior.

At light loads, in which the converter operate in PFM Mode, the output voltage is regulated typically 1% higher than the nominal value. In case of a load transient from light load to heavy load, the output voltage will drop until it reaches the COMP LOW threshold set to 2% below the nominal value and enters PWM mode. During a load throw off from heavy load to light load, the voltage overshoot is also minimized due to active regulation turning on the low-side channel switch.

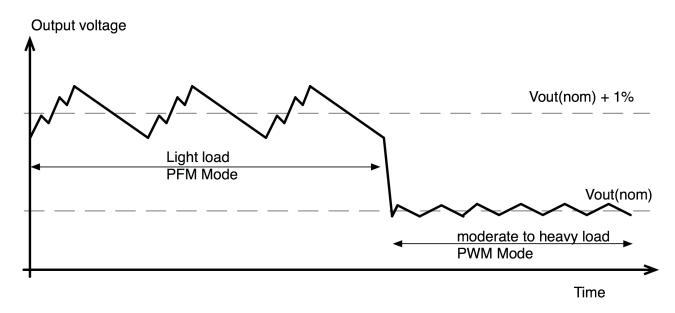


Figure 3-17. Voltage Positioning

3.55.7 Soft Start

SM0, SM1 and SM2 have an internal soft start circuit that limits the inrush current during start-up. An initial delay (170µs typ) from the converter enabled command to the converter effectively being operational is required to ensure that the internal circuits of the converter are properly biased. At the end of that initial delay the soft start is initiated and the internal compensation capacitor is charged with a low value current source. The soft start time is typically 250µs, with the output voltage ramping from 5% to 95% of the final target value.

3.55.8 Dropout Operation at 100% Duty Cycle

The TPS658600 buck converters offer a low input to output voltage difference while still maintaining operation when the duty cycle is set to 100%. In this mode of operation the high-side FET is constantly turned on to enable operation with a low input voltage. The dropout operation will start if:

$$V_{(VIN_SMx)} \le V_{(SMx)} + I_{Lx} \times \otimes_{DSON(PSMx)} + R_{L}$$

where I_{Lx} is the output current plus ½ inductor ripple current and R_L is the DC resistance of the inductor.

3.55.9 Output Voltage Monitoring

The output voltage of converters SM0, SM1 and SM2 is monitored by internal comparators, and an output low voltage condition is detected when the output voltage is below 90% of the programmed value. The power good comparator is disabled for all converters during output voltage transitions. The power comparator on SM2 power good is also disabled when battery tracking mode is set.

3.55.10 Phase Control in PWM Mode

By default the SM0, SM1 and SM2 converters operate with phased clocking when they are in PWM mode, with converter SM0 as the master. Converters SM0 and SM1, when enabled, will run 90 and 180 degrees out of phase with SM0.

3.55.11 Integrated Snubber and Current Limit

The SM2 converter has an integrated electronic snubber that is used to improve transient response when operating under conditions which cause the inductor current to flow in the negative direction (into the Ln node). This is especially true when SM2 is configured as the pre-regulator stage to the charger.



3.56 LINEAR REGULATORS

The TPS658600 offers ten integrated linear dropout regulators (LDOs), designed to be stable over the operating load range with use of external ceramic capacitors. The output voltage can be programmed via I²C. All of the LDOs, with the exception of LDO5 and RTC_OUT LDO, have uncommitted input power supply pins (VIN_LDO01, VIN_LDO23, VIN_LDO4, VIN_LDO678, VIN_LDO9) which should be externally connected to a number of system rails including SYS and the output of SM2.

The LDO5 and RTC_OUT regulators are internally connected to the SYS pin.

3.56.1 Output Voltage Monitoring

Internal power good comparators monitor the LDO outputs and detect when the output voltage is below 95% of the programmed value. This information is used by the TPS658600 to generate interrupts or to trigger distinct operating modes, depending on specific I²C register settings. See interrupt and sequencing controller section for additional details.

3.56.2 LDO2 DVM LDO - Output Voltage Registers

Registers 0x29, 0x2A, 0x2F and 0x30 set the output voltage for LDO2. The slew rate is internally fixed to 7mV/µSec (typ).

Table 3-32. DVM Supply Voltage Selection – LDO2

LDO2AV1 [Ad	dr 0x29]						De	faults in BOLD	
Bit Number	B7	В6	B5	B4	В3	B2	B1	В0	
Bit Name	RSVD297	RSVD296	RSVD295	LDO2AV1[4]	LDO2AV1[3]	LDO2AV1[2]	LDO2AV1[1]	LDO2AV1[0]	
Function	NOT USED	NOT USED	NOT USED	LDO	O2 SUPPLY OU	TPUT VOLTAG	E (See Table 3	-33)	
SM1V2 [Addr	SM1V2 [Addr 0x24] Defaults in BOLD								
Bit Number	B7	В6	B5	B4	В3	B2	B1	В0	
Bit Name	RSVD2A7	RSVD2A6	RSVD2A5	LDO2AV2[4]	LDO2AV2[3]	LDO2AV2[2]	LDO2AV2[1]	LDO2AV2[0]	
Function NOT USED NOT USED NOT USED LDO2 SUPPLY OUTPUT VOLTAGE (See Table 3-33)							-33)		
LDO2BV1 [Ad	dr 0x2F]						De	faults in BOLD	
Bit Number	B7	В6	B5	B4	В3	B2	B1	В0	
Bit Name	RSVD2F7	RSVD2F6	RSVD2F5	LDO2BV1[4]	LDO2BV1[3]	LDO2BV1[2]	LDO2BV1[1]	LDO2BV1[0]	
Function	NOT USED	NOT USED	NOT USED	LDO	O2 SUPPLY OU	TPUT VOLTAG	E (See Table 3	-33)	
LDO2BV2 [Ad	dr 0x30]						De	faults in BOLD	
Bit Number	B7	В6	B5	B4	В3	B2	B1	В0	
Bit Name	RSVD307	RSVD306	RSVD305	LDO2BV2[4]	LDO2BV2[3]	LDO2BV2[2]	LDO2BV2[1]	LDO2BV2[0]	
Function	Function NOT USED NOT USED NOT USED LDO2 SUPPLY OUTPUT VOLTAGE (See Table 3-33)								

The available output voltages for LDO2 are shown below:

Table 3-33. LDO2AV1/2[4:0] and LDO2BV1/2[4:0] Settings

RANGE	[4:0]	VOUT (V)						
0.725V-1.50V	00000	0.725	01000	0.925	10000	1.125	11000	1.325
	00001	0.750	01001	0.950	10001	1.150	11001	1.350
	00010	0.775	01010	0.975	10010	1.175	11010	1.375
	00011	0.800	01011	1.000	10011	1.200	11011	1.400
	00100	0.825	01100	1.025	10100	1.225	11100	1.425
	00101	0.850	01101	1.050	10101	1.250	11101	1.450
	00110	0.875	01110	1.075	10110	1.275	11110	1.475
	00111	0.900	01111	1.100	10111	1.300	11111	1.500



3.56.3 LDO4 DVM LDO – Output Voltage Registers

Registers 0x32 and 0x33 set the output voltage for LDO4. The slew rate is internally fixed to 7mV/µSec (typ).

Table 3-34. DVM Supply Voltage Selection - LDO4

LDO4V1 [Addr 0x32]										
Bit Number	В7	B6	B5	B4	В3	B2	B1	В0		
Bit Name	RSVD327	RSVD326	RSVD325	LDO4V1[4]	LDO4V1[3]	LDO4V1[2]	LDO4V1[1]	LDO4V1[0]		
Function NOT USED NOT USED NOT USED LDO4 SUPPLY OUTPUT VOLTAGE (See Table 3-35)										
LDO4V2 [Addr 0x33]										
LDO4V2 [Add	r 0x33]									
Bit Number	r 0x33] B7	В6	B5	B4	В3	B2	B1	В0		
	•	B6 RSVD336	B5 RSVD335	B4 LDO4V2[4]	B3 LDO4V2[3]	B2 LDO4V2[2]	B1 LDO4V2[1]	B0 LDO4V2[0]		

The available output voltages are shown below:

Table 3-35. LDO4V1[4:0] and LDO4V2[4:0] Output Voltage Settings

RANGE	[4:0]	VOUT (V)						
1.7V-2.475V	00000	1.700	01000	1.900	10000	2.100	11000	2.300
	00001	1.725	01001	1.925	10001	2.125	11001	2.325
	00010	1.750	01010	1.950	10010	2.150	11010	2.350
	00011	1.775	01011	1.975	10011	2.175	11011	2.375
	00100	1.800	01100	2.000	10100	2.200	11100	2.400
	00101	1.825	01101	2.025	10101	2.225	11101	2.425
	00110	1.850	01110	2.050	10110	2.250	11110	2.450
	00111	1.875	01111	2.075	10111	2.275	11111	2.475

3.56.4 LDO Output Discharge Switches

All LDO's, with exception of RTC_OUT LDO, have internal discharge resistors that are connected to ground via internal switches when the LDO is turned OFF, thus discharging the output capacitor.

The LDO output discharge switches are always enabled when NORMAL state is set and during the SUPPLYSEQ state.

3.56.5 Non-DVM Supply Voltage Settings

Registers SUPPLYV1, SUPPLYV2, SUPPLYV3, SUPPLYV4 and SUPPLYV6 define the voltage settings for the non-DVM supplies.

Register SUPPLYV4 has two bits that control the RTC_OUT LDO functionality. The RTC_OUT LDO will be enabled when LDORTC_ON is 1. The power good threshold for the RTC_OUT LDO can be set as follows: 2.4V (RTC_PGOOD is 1), 2.0V (RTC_PGOOD is 0).

Table 3-36. Non-DVM Supply Voltage Selection

SUPPLYV1 [SUPPLYV1 [Addr 0x41]											
Bit Name	VLDO0[2]	VLDO0[1]	VLDO0[0]	VLDO1[4]	VLDO1[3]	VLDO1[2]	VLDO1[1]	VLDO1[0]				
Function	LDO0 OUTPL	JT VOLTAGE (Se	ee Table 3-38)		LDO1 OUTPU	T VOLTAGE (Se	ee Table 3-37)					
SUPPLYV3 [Addr 0x43]											
Bit Name	LDO7_SW	LDO6_SW	VLDO7[2]	VLDO7[1]	VLDO7[0]	VLDO6[2]	VLDO6[1]	VLDO6[0]				
Function SPARE SPARE LDO7 OUTPUT VOLTAGE (See Table 3-38) LDO6 OUTPUT VOLTAGE (See Table 3-38)								ee Table 3-38)				

Table 3-36. Non-DVM Supply Voltage Selection (continued)

SUPPLYV4 [Addr 0x44]							
Bit Name	LDORTC_ON	RTC_PGOOD	VRTC[2]	VRTC[1]	VRTC[0]	VLDO3[2]	VLDO3[1]	VLDO3[0]
Function	RTC_LDO ON/OFF CONTROL	RTC_OUT LOW VOLTAGE THRESHOLD	RTC OUTPUT	T VOLTAGE (Se	ee Table 3-38)	LDO3 OUTPU	T VOLTAGE (S	ee Table 3-38)
SUPPLYV6 [Addr 0x46]							
Bit Name	RSVD467	RSVD466	VLDO9[2]	VLDO9[1]	VLDO9[0]	VLDO5[2]	VLDO5[1]	VLDO5[0]
Function	NOT USED	NOT USED	LDO9 OUTPU	T VOLTAGE (S	ee Table 3-38)	LDO5 OUTPU	T VOLTAGE (S	ee Table 3-38)

The available output voltages for the non-DVM supplies are shown below:

Table 3-37. VLDO1[4:0] Settings

RANGE	[4:0]	VOUT (V)						
0.725V-1.50V	00000	0.725	01000	0.925	10000	1.125	11000	1.325
	00001	0.750	01001	0.950	10001	1.150	11001	1.350
	00010	0.775	01010	0.975	10010	1.175	11010	1.375
	00011	0.800	01011	1.000	10011	1.200	11011	1.400
	00100	0.825	01100	1.025	10100	1.225	11100	1.425
	00101	0.850	01101	1.050	10101	1.250	11101	1.450
	00110	0.875	01110	1.075	10110	1.275	11110	1.475
	00111	0.900	01111	1.100	10111	1.300	11111	1.500

Table 3-38. VLDO3/5/6/7/8/9[2:0] and VRTC[2:0] Settings

VLDOx[2:0]	OX[2:0] VOUT (V) VLDOX[2:0]		VOUT (V)
000	1.25	100	2.70
001	1.50	101	2.85
010	1.80	110	3.10
011	2.50	111	3.30

Table 3-39. VLDO0[2:0] and VRTC[2:0] Settings

VLDOx[2:0]	VOUT (V)	VLDOx[2:0]	VOUT (V)
000	1.20	100	2.70
001	1.50	101	2.85
010	1.80	110	3.10
011	2.50	111	3.30

Setting the RTC_OUT output voltage below the RTC_OUT power good threshold will result in a $\overline{\text{NORTC}}$ pulse always being generated during the reboot cycle or when exiting sleep. Setting the RTC_OUT output voltage below V_{UVLO_RTC} disables the use of the internal real time clock counter and xtal oscillator.

3.57 BOOST CONVERTER

The TPS658600 has an integrated boost converter (SM3) that is optimized to drive white LED's connected in a series configuration. Up to six series white LED's can be driven, with programmable current and duty cycle adjustable via a dedicated I²C register.



The SM3 boost Converter (SM3) has a 29v, 500mA low side integrated power stage switch, which drives the external inductor. Another integrated 29V, 25mA switch (LED switch) is used to modulate the external white LED's brightness.

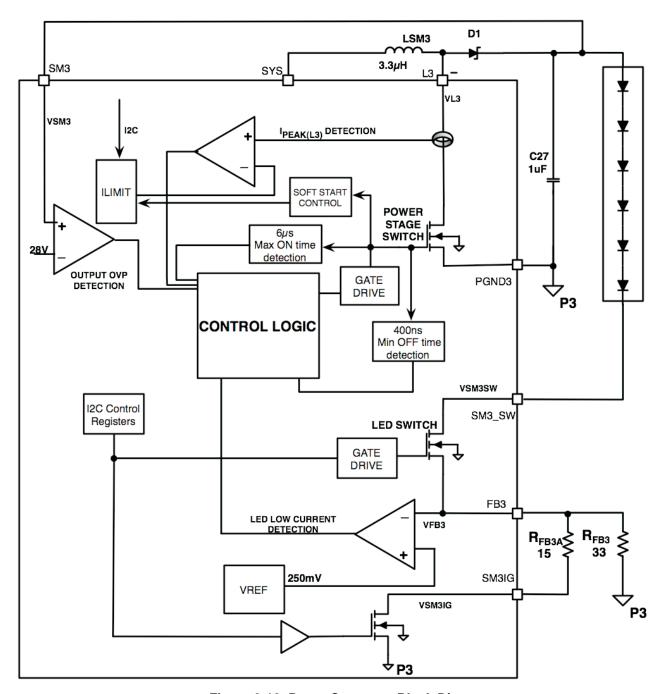


Figure 3-18. Boost Converter Block Diagram

The SM3 boost converter operates in a pulse frequency modulation (PFM) scheme with constant peak current control. This control scheme maintains high efficiency over the entire load current range and enables the use of small external components, as the switching frequency can reach up to 1 MHz depending on the load conditions. The LED current ripple is defined by the external inductor size.

The converter monitors the sense voltage at pin FB3, and turns on the integrated power stage switch when V(FB3) is below the 250mV (typ) internal reference voltage. The integrated power switch turns off when the inductor current reaches the internal peak current limit or if the switch is on for a period longer than the maximum on-time of 6 µs (typ).

As the integrated power switch is turned off the external Schottky diode is forward biased, delivering the stored inductor energy to the output. The main switch remains off until the FB3 pin voltage is below the internal 250mV reference voltage, when it is turned on again.

This PFM peak current control sets the converter in discontinuous conduction mode (DCM), and the switching frequency depends on the inductor, input/output voltage and LED current. Lower LED currents reduce the switching frequency, with high efficiency over the entire LED current range. This regulation scheme is inherently stable, allowing a wide range for the selection of the inductor and output capacitor.

3.57.1 SM3 RAM Registers

Table 3-40. SM3 Control

SM3_SET0 [Ad	ddr 0x57]							Defaults in BOLD		
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0		
Bit Name	SM3_SET7	SM3_SET6	SM3_SET5	SM3_SET4	SM3_SET3	SM3_SET2	SM3_SET1	SM3_SET0		
Function	Function SM3 PWM SWITCH DUTY CYCLE									
When 0	ADD 0 TO DUTY CYCLE									
When 1	ADD 6.25%	ADD 3.125%	ADD 1.5625%	ADD 0.78125%	ADD 0.390%	ADD 0.195%	ADD 0.0976%	ADD 0.048%		
SM3_SET1 [Addr 0x58] Defaults in							Defaults in BOLD			
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0		
Bit Name	SM3SOFTOFF	SM3_ILIM	SM3_PRESC1	SM3_PRESC0	SM3_IGAIN	SM3_SET10	SM3_SET9	SM3_SET8		
Function	SOFTSTART ENABLE	SM3 CURRENT LIMIT	SM3PWM REPETITION RATE[1]	SM3PWM REPETITION RATE[0]	ISM3G OUTPUTBUFF ER MODE	SM3 PWM DUTY CYCLE				
When 0	ENABLED	300 mA		SEE SM3 PWM REPETITION Hi-Z			DD 0 TO DUTY C	YCLE		
When 1	DISABLED	500 mA	SEE SM3 PWM REPETITION TABLE		LO	ADD 50%	ADD 25%	ADD 12.5%		

Table 3-41. SM3 PWM Repetition Settings

SM3PRESC[1]	SM3PRESC[0]	REPETITION RATE (Hz)
0	0	550
0	1	366
1	0	275
1	1	220

The internal LED switch, in series with the external LED's, disconnects the LEDs from ground during shutdown. In addition, the LED switch is driven by a PWM signal generated internally, enabling adjusting the average LED current by setting the LED switch duty cycle. The duty cycle is adjusted with control bits SM3_SET, on register SM3_SET0. With this control method the LED brightness depends on the LED switch duty cycle only and is independent of the boost converter operating frequency. The duty cycle control used in the SM3 converter LED switch is implemented by a single PWM pulse with a fixed repetition rate. An example of distinct duty cycles is shown IN Figure 3-19



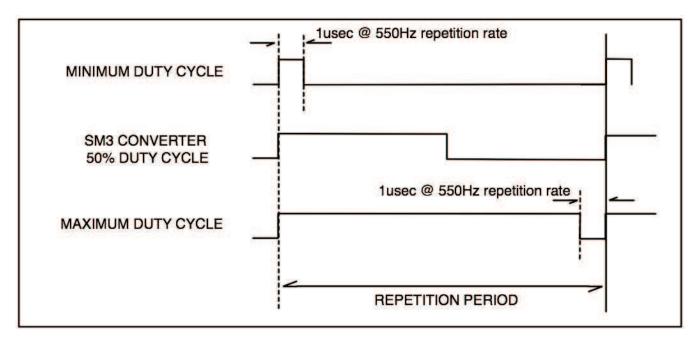


Figure 3-19. SM3 Duty Cycle Example

The repetition period can be set using control bits SM3_PRESCn in the register SM3_SET1 to either 220/275/366/550 Hz (HI). Each repetition period has a total of 2048 steps, enabling a resolution of 0.05% when programming the duty cycle.

3.57.2 Peak Current Control (Boost Converter)

The SM3 integrated power stage switch is turned on until the inductor current reaches the DC current limit $I_{MAX(L3)}$ (500 mA or 300mA, typ), selectable via bit SM3_ILIM, register SM3_SET1. Due to internal delays, typically around 100ns, the actual current exceeds the DC current limit threshold by a small amount. The typical peak current limit can be calculated as follows:

$$I_{P(typ)} = I_{MAX(L3)} + \frac{V_{SM3}}{L} \times 100 \text{ ns}$$
 (6)

The peak current will be directly proportional to the input voltage and inversely proportional to the inductor value. The internal current limit may be set to either 300mA or 500mA via I²C.

Note that under PWM operation the slew rate of the converter output (SM3) is dependent of the $I_{MAX(L3)}$ value selected.

3.57.3 Soft Start

All inductive step-up converters exhibit high in-rush current during start-up. If no special precautions are taken voltage drops can be observed at the input supply rail during start-up, with unpredictable results in the overall system operation.

The SM3 boost converter limits the inrush current during start-up by increasing the current limit in two steps, starting from $I_{MAX(L3)}$ /4 for 256 power stage switch cycles (1cycle=power stage switch OFF \rightarrow ON \rightarrow OFF) to $I_{MAX(L3)}$ /2 for the next 256 power stage switch cycles and then full current limit $I_{MAX(L3)}$. The softstart function can be disabled via control bit SM3SOFTOFF, in register SM3_SET1.

3.57.4 Enabling the SM3 Converter

The converter is enabled when an I²C command sets the duty cycle to a value different than zero.



INSTRUMENTS

The output voltage of the boost converter is sensed at pin SM3, and the integrated power stage switch is turned OFF when V(SM3) exceeds the internal over-voltage threshold V_(OVP3). The converter returns to normal operation when $V(SM3) < V_{(OVP3)} - V_{HYS(OVP3)}$.

3.57.6 Under Voltage Lockout Operation

The power stage mosfet switch and the LED switch are open (off) when the TPS658600 enters the sleep mode or if the SM3 converter is set to OFF mode.

3.57.7 SM3 Output Current - High and Low Current Settings

A dedicated, open-drain pin (ISM3G) enables I²C selection of a low and high brightness setting for the SM3 output current, by modifying the external FB3 resistor value. See application diagram for details. This pin is configured as an open drain and it can be turned on/off with bit SM3_IGAIN on register SM3_SET1.

3.58 RGB AND PWM DRIVERS

The TPS658600 has integrated open drain and push-pull drivers with programmable duty cycle and frequency, targeted at driving external RGB drivers, keyboard LED's, vibrator motor and other system peripherals.

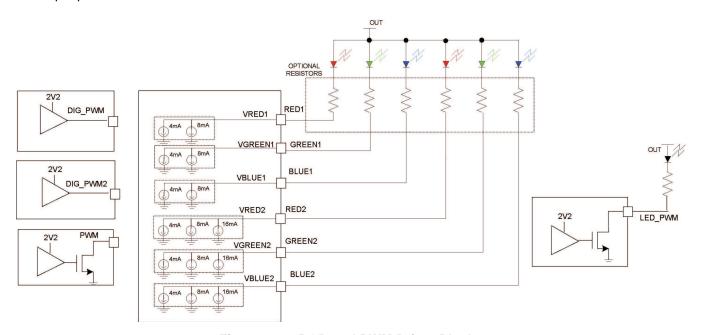


Figure 3-20. RGB and PWM Driver Blocks

3.58.1 PWM Pin Driver

The TPS658600 offers one high current (150mA max) open-drain PWM driver. The PWM driver is enabled when PWM_EN is 1 in register PWM.

Table 3-42. PWM Control

PWM [Addr 0x5B] De								Default to 0
Bit Number	В7	В6	B5	B4	В3	B2	B1	В0
Bit Name	PWM_EN	PWM_F[2]	PWM_F[1]	PWM_F[0]	PWM_D[3]	PWM_D[2]	PWM_D[1]	PWM_D[0]
Function	PWM DRIVER ON/OFF	PWM DRIVER FREQUENCY			PWM DRIVER DUTY CYCLE			E



The PWM frequency and duty cycle are defined by the PWM register settings as shown below.

Table 3-43. PWM Settings

PWM_F[2:0)	FREQUENCY(kHz)	PWM_D[3:0]	DUTY CYCLE (%)	PWM_D[3:0]	DUTY CYCLE (%)
000	23.4	0000	6.25	1000	56.25
001	11.7	0001	12.5	1001	62.5
010	6.7	0010	18.75	1010	68.75
011	4.5	0011	25	1011	75
100	3.0	0100	31.25	1100	81.25
101	2.3	0101	37.5	1101	87.5
110	1.5	0110	43.75	1110	93.75
111	0.75	0111	50	1111	100

3.58.2 DIG PWM, DIG PWM2 Drivers

The TPS658600 provides two push-pull outputs with programmable duty cycle at pins DIGPWM and DIGPWM2. The DIG_PWM register controls the DIGPWM pin duty cycle, register DIG_PWM2 controls the DIGPWM2 pin duty cycle. The DIG_PWM functions and register bit controls detailed below apply to the DIGPWM2 pin and DIG_PWM2 register as well. Both registers default to 0x00 upon power-up.

Table 3-44. DIGPWM, DIGPWM2 Control

DIG_PWM [Addr 0x5A] Default to									
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0	
Bit Name	DPWM_MODE	DPWM_SET[6]	DPWM_SET[5]	DPWM_SET[4]	DPWM_SET[3]	DPWM_SET[2]	DPWM_SET[1]	DPWM_SET[0]	
DIG_PWM2 [Add	DIG_PWM2 [Addr 0x5C] Default to (
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0	
Bit Name	DPWM2_MODE	DPWM2_SET[6]	DPWM2_SET[5]	DPWM2_SET[4]	DPWM2_SET[3]	DPWM2_SET[2]	DPWM2_SET[1]	DPWM2_SET[0]	

Mode 0 (DPWM_MODE is **0**): The pulse width modulated output is a single PWM pulse of the selected duty cycle, with a nominal 250Hz repetition rate. The DIG_PWM register bits [6:0] sets the pulse width value as shown below:

$$T_{ON}(ms) = \frac{DPWM_SET[6:0]}{32}, \text{ if } DPWM_SET[6:0] \le 126$$

$$T_{ON}(ms) = \text{Always On, if } DPWM_SET[6:0] = 127)$$
(7)

Mode 1 (DPWM_MODE is 1): The bit DPWMx_SET[6] of the DIG_PWMx register selects the pulse time range, bits DIG_PWMx[5:3] set the ON times and bits DIG_PWMx[2:0] set the off times.

Table 3-45. Digital PWM Settings, DPWM MODE=1

DPWMx_SET[6] = 0				DPWMx_SET[6] = 1				
DIG_PWMx[5:3]	ON TIME (µs)	DIG_PWMx[2:0]	OFF TIME (ms)	DIG_PWMx[5:3]	ON TIME (ms)	DIG_PWMx[2:0]	OFF TIME (ms)	
000	31	000	0.49	000	5	000	40	
001	61	001	1.01	001	10	001	60	
010	92	010	1.50	010	15	010	80	
011	122	011	2.01	011	20	011	100	
100	153	100	2.50	100	30	100	120	
101	183	101	2.99	101	40	101	140	
110	214	110	4.00	110	50	110	160	
111	244	111	5.00	111	60	111	180	

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3.58.3 LED PWM Driver

The LED PWM open drain pin has the duty cycle set by a pulse width modulation circuit. The LED_SET register bits (7:0) set the pulse width value in 256 steps. The pulse width modulated output is not a single pulse of the selected duty cycle but a collection of semi-equally spaced pulses that sum to the required duty cycle, with repetition rate of 125Hz (typ)

Table 3-46. LEDPWM Control

LED_PWM [Addr 0x59] Def										
Bit Number	B7	В6	B5	B4	В3	B2	B1	В0		
Bit Name	LED_SET[7]	LED_SET[6]	LED_SET[5]	LED_SET[4]	LED_SET[3]	LED_SET[2]	LED_SET[1]	LED_SET[0]		

$$T_{ON}(ms) = \frac{LED_SET[7:0]}{32}$$
, if LED_SET[7:0] ≤ 254
 $T_{ON}(ms) = Always On$, if LED_SET[7:0] = 255

3.58.4 RGB Drivers

The TPS658600 has two dedicated drivers for RGB external LED's. Three outputs are available for each driver (pins REDn, GREENn, BLUEn), with I²C selection of operation mode and LED current.

3.58.5 RGB1 Driver

The RGB1 driver is enabled when RGB1 EN=HI, in RGB1 GREEN register. Each RGB1 pin (RED1, GREEN1 or BLUE1) will sink the current selected by RGB1 ISET[1:0], RGB1 RED register.

The RGB1 driver can be set in a flashing mode, the flash operation parameters are configured in register RGB1FLASH. During the flashing ON time the duty cycle for each driver can be set individually using control bits PWMIR[4:0], PWMIG[4:0] and PWMIB[4:0] on registers RGB1 RED, RGB1 GREEN and RGB1 BLUE. The modulated output is not a single pulse of the selected duty cycle but a collection of semi-equally spaced pulses that sum to the required duty cycle, with repetition rate of 160Hz (typ). The start of 1 of the modulated pulses on RGB1 can be phased by 200 µs from the others so that for duty cycles below 50% the ON times of 2 of the LEDs will not overlap. When RGB1 PHASE is 0 (RGB1 GREEN[6]), the Red and Blue are drivers are in phase and Green is out of phase. For RGB1 PHASE is 1 the Red and Green are in phase and Blue is out of phase.

Table 3-47, RGB1 Control

RGB1FLASH [Ad	ldr 0x50]							Default is 0
Bit Number	В7	B6	B5	B4	В3	B2	B1	В0
Bit Name	RSVD507	FLASH1_ON[2]	FLASH1_ON[1]	FLASH1_ON[0]	FLASH1_PER[3]	FLASH1_PER[2]	FLASH1_PER[1]	FLASH1_PER[0]
Function	SPARE	RGB1 RED/BL	UE/GREEN FLASHI	NG ON-TIME	RC	BB1 RED/BLUE/GRE	EN FLASHING PERI	OD
RGB1RED [Addr	0x51]							Default is 0
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0
Bit Name	RSVD517	RGB1_ISET[1]	RGB1_ISET[0]	PWM1R[4]	PWM1R[3]	PWM1R[2]	PWM1R[1]	PWM1R[0]
Function	NOT USED	RGB1 RED/BLUE/ CURREN			RGB1 RED DRIVER INTENSITY CONTROL			
RGB1GREEN [Ad	ddr 0x52]							Default is 0
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0
Bit Name	RGB1_EN	RGB1_PHASE	RSVD535	PWM1G[4]	PWM1G[3]	PWM1G[2]	PWM1G[1]	PWM1G[0]
Function	RGB1 DRIVERS ON/OFF CONTROL	DRIVER ON TIME PHASE CONTROL	NOT USED		RGB1 GREE	N DRIVER INTENSIT	TY CONTROL	
RGB1BLUE [Add	Ir 0x53]							Default is 0
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0
Bit Name	RSVD537	RSVD536	RSVD535	PWM1B[4]	PWM1B[3]	PWM1B[2]	PWM1B[1]	PWM1B[0]
Function	NOT USED	NOT USED	NOT USED	RGB1 BLUE DRIVER INTENSITY CONTROL				

Table 3-48. RGB1 Sink Current Settings

RGB1_ISET[1:0]	RGB1 SINK CURRENT (mA)
00	0
01	3.7
10	7.4
11	11.1

Table 3-49. FLASH1_ON Settings

FLASH1_ON[2:0]	FLASH ON TIME (s)
000	0.10
001	0.15
010	0.20
011	0.25
100	0.30
101	0.40
110	0.50
111	0.60

Table 3-50. FLASH1_PER Settings

FLASH1_PER[3:0]	FLASH PERIOD (s)	FLASH1_PER[3:0]	FLASH PERIOD (s)
0000	1.0	1000	5.0
0001	1.5	1001	5.5
0010	2.0	1010	6.0
0011	2.5	1011	6.5
0100	3.0	1100	7.0
0101	3.5	1101	7.5
0110	4.0	1110	8.0
0111	4.5	1111	Always On

Equation 11 and Equation 12 indicates the duty cycle values for each driver, set with bit PWM1R[4:0], PWM1G[4:0] and PWM1B[4:0]:

$$T_{ON}(ms) = \frac{PWM1R/G/B[4:0]}{5.4}, \text{ if } PWM1R/G/B[4:0] \le 30$$

$$T_{ON}(ms) = Always \text{ On, if } pwm1r/g/b[4:0] = 31$$
 (11)

3.58.6 RGB2 Driver

The RGB2 driver is enabled when RGB2_EN is 1, in RGB2_GREEN register. Each RGB2 pin (RED2, GREEN2 or BLUE2) will sink the current selected by RGB2_ISET[2:0], set in RGB2_RED register.

The RGB2 does not support a flashing mode, and will be turned on when RGB2_EN is 1. When turned ON the duty cycle for each driver can be set individually using control bits PWMIR[4:0], PWMIG[4:0] and PWMIB[4:0] on registers RGB2_RED, RGB2_GREEN and RGB2_BLUE. The modulated output is not a single pulse of the selected duty cycle but a collection of semi-equally spaced pulses that sum to the

required duty cycle, with repetition rate of 160Hz (typ). The start of one of the modulated pulses on RGB2 can be phased by 200 µs from the others, so that for duty cycles below 50% the ON times of 2 of the LEDs will not overlap. When RGB2_PHASE is **0** (RGB2_GREEN[6]), the Red and Blue drivers are in phase and Green is out of phase. When RGB2_PHASE is **1** the Red and Green are in phase and Blue is out of phase.

Table 3-51, RGB2 Control

RGB2RED [A	Addr 0x54]							Default to 0
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0
Bit Name	RGB2_ISET[2]	RGB2_ISET[1]	RGB2_ISET[0]	PWM2R[4]	PWM2R[3]	PWM2R[2]	PWM2R[1]	PWM2R[0]
Function	RGB2 RED/BLI	JE/GREEN DRIVER C	URRENT SINK		RGB2 RED [RIVER INTEN	SITY CONTROL	
RGB2GREEN	N [Addr 0x55]							Default to 0
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0
Bit Name	RGB2_EN	RGB2_PHASE	RSVD565	PWM2G[4]	PWM2G[3]	PWM2G[2]	PWM2G[1]	PWM2G[1]
Function	RGB2 DRIVERS ON/OFF CONTROL	RGB2 DRIVERS ON TIME PHASE CONTROL	SPARE		RGB2 GREEN	DRIVER INTE	NSITY CONTROL	-
RGB2BLUE	[Addr 0x56]							Default to 0
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0
Bit Name	RSVD577	RSVD576	RSVD575	PWM2B[4]	PWM2B[3]	PWM2B[2]	PWM2B[1]	PWM2B[1]
Function	NOT USED	NOT USED	NOT USED	RGB2 GREEN DRIVER INTENSITY CONTROL				

Table 3-52. RGB2 Sink Current Settings

RGB2_ISET[2:0]	RGB2 SINK CURRENT (mA)
000	0
001	3.7
010	7.4
011	11.1
100	14.9
101	18.6
110	23.2
111	27.3

The on time for each driver, set with bits PWM2R[4:0], PWM2G[4:0] and PWM2B[4:0], is set by the equations:

$$T_{ON}(ms) = \frac{PWM2R/G/B[4:0]}{5.4}, \text{ if } PWM2R/G/B[4:0] \le 30$$

$$T_{ON}(ms) = \text{Always On, if } PWM2R/G/B[4:0] = 31$$
(13)

3.59 REAL TIME CLOCK

The TPS658600 has an integrated real time clock circuit that maintains an accurate timer/counter register under all potential operating conditions (AC power input, USB power input, main battery power, backup coincell / SuperCap power source, or any combination of the above). The internal oscillator for the RTC can be driven by an external 32.768 kHz crystal. The TPS658600 has also been design with integrated, I²C selectable, capacitors which can be used with the external 32.768 kHz crystal such that a wide range of commercial crystals can be used without the need for external load capacitors.



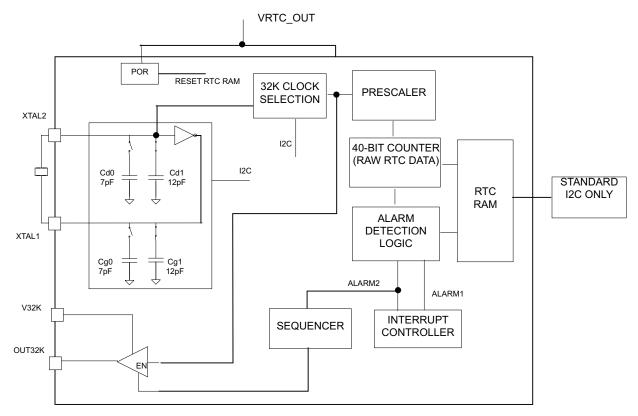


Figure 3-21. Simplified RTC Block

The following functions are provided:

- A 40-bit counter, driven by a low-power 32 kHz oscillator
- The 32 kHz oscillator can be switched using I²C, RTC_CTRL Register bit 6 (OSC_SRC_SEL), between the TPS658600 internal (RC) oscillator source and the crystal driven oscillator source.
- Externally biased buffer to supply the crystal driven oscillator to an external device via the OUT32K pin.
- Selectable pre-scaler divides the raw (32KHz) oscillator output, enabling clocking the RTC counter at 1.024 kHz or 32 kHz
- A 24-bit alarm register (ALARM1)
- A 16-bit alarm register (ALARM2)

The RTC registers are accessible only via the I^2C bus. When an I^2C read access is in progress, the RTC counter update is postponed. At the end of the I^2C read access, the accumulated missing counts are added to the RTC counter.

NOTE

The RTC registers (0xC0-0xCA) **ARE NOT** reset when the TPS658600 is in the POWER DOWN or SLEEP STATE as long as V(RTC_OUT) is greater than V_{UVLO_RTC} . All the RTC registers will be reset to their default settings, independent of the TPS658600 state, when V(RTC_OUT) is less than V_{UVLO_RTC} .

The host software must read all five RTC counter bytes when accessing the RTC counter data, as the counter update is postponed starting at the first I²C byte read of a sequential I²C read of the five RTC COUNT bytes and negated on the fifth I²C byte read.

To assure proper operation of the RTC counter the following steps should always be followed:

1. The I²C address pointer must not be left pointing in the range 0xC6 to 0xCA

- 2. The maximum time for the address pointer to be in this range is 1 ms
- Always read RTC_ALARM2 in the following order to prevent the address pointer from stopping at 0xC6: RTC_ALARM2_LO, then RTC_ALARM2_HI

When the RTC_OUT voltage falls below the internal RTC circuit Power On Reset threshold, V_{UVLO_RTC} , the RTC_CTRL register is reset. The host can identify this situation by reading the bit, POR_RESET_N, which will be $\bf{0}$.

The clock selection is controlled by OSC_SRC_SEL (RTC_CTRL [6]). The internal 32kHz oscillator is connected to the RTC when the OSC_SRC_SEL bit is reset. Once the processor is running, the software can set this bit to 1, thereby connecting the 32.768 kHz crystal oscillator clock to the RTC. After being set, the OSC_SRC_SEL bit will remain 1 selecting the crystal oscillator clock, as long as the VRTC_OUT voltage remains above the RTC_OUT Power On Reset threshold. POR_RESET_N=HI when OSC_SRC_SEL is set HI, indicating to the host that the crystal clock is being delivered to the RTC.

The RTC_ENABLE (RTC_CTRL [5]) bit is cleared to **0** by the RTC_OUT Power On Reset, disabling the RTC counter. To enable incrementing of the RTC_COUNT [39:0] from an initial value set by the host, the RTC_ENABLE bit should be written to **1** only after the RTC_OUT voltage reaches the operating range. The RTC_ENABLE bit must be cleared to **0** before any new value is written to the RTC_COUNT register.

RTC_CTRL [Addr 0xC0] Defaults in BOLD Bit Number B7 B6 B5 RΛ ВЗ R2 B1 ΒO POR_RESET_N OSC_SRC_SEL RTC_ENABLE BUF_ENABLE PRE_BYPASS CL_SEL[1] CL_SEL[0] RSVDC00 Bit Name INTERNAL XTAL1 RESET RTC 32K CLOCK RTC COUNTER 32KHZ BUFFER RTC COUNTER PIN RTC_ALARM2 Function COUNTER SELECTION CLOCK AND SCALING XTAL2 CAPACITANCE DETECTION **ENABLE** ALARM1/2 **EXITS SLEEP** When 0 RESET RTC **INTERNAL 32K** DISABLED DISABLED USE 32K/32 SEE CL_SEL SETTINGS TABLE DISABLED COUNTER When 1 CRYSTAL 32K ENABLED FNARI FD USE 32K SEE CL_SEL SETTINGS TABLE ENABLED OSC SRC SEL BIT =

Table 3-53. RTC Control⁽¹⁾

The selected 32KHz clock is applied to a prescaler that can divide it by 32, resulting in a timer tick resolution of either 32,768 ticks per second (pre-scaler disabled, PRE_BYPASS is 1) or 1,024 ticks per second (pre-scaler enabled, PRE_BYPASS is 0). The 32,768 Hz or 1024 Hz clock increments a 40 bit counter that tracks the real time and which can be read at anytime via I²C. With the prescaler enabled, the RTC count has a range of approximately 34 years. The RTC counter and alarm registers are shown below, the 40 bit RTC Counter is cleared only on when RTC_OUT is below the UVLO threshold.

RTC_COUNT4	4 [Addr 0xC6]							Default to 0
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0
Bit Name	RTC[39]	RTC[38]	RTC[37]	RTC[36]	RTC[35]	RTC[34]	RTC[33]	RTC[32]
RTC_COUNT	B [Addr 0xC7]							Default to 0
Bit Name	RTC[31]	RTC[30]	RTC[29]	RTC[28]	RTC[27]	RTC[26]	RTC[25]	RTC[24]
RTC_COUNT2	2 [Addr 0xC8]							Default to 0
Bit Name	RTC[23]	RTC[22]	RTC[21]	RTC[20]	RTC[19]	RTC[18]	RTC[17]	RTC[16]
RTC_COUNT1	[Addr 0xC9]							Default to 0
Bit Name	RTC[15]	RTC[14]	RTC[13]	RTC[12]	RTC[11]	RTC[10]	RTC[9]	RTC[8]
RTC_COUNT0 [Addr 0xCA]								Default to 0
Bit Name	RTC[7]	RTC[6]	RTC[5]	RTC[4]	RTC[3]	RTC[2]	RTC[1]	RTC[0]

Table 3-54, RTC Counter

⁽¹⁾ B7 is READ ONLY, all other bits have Read/Write access



The alarm logic compares the RTC_ALARM1 register bits to the RTC_COUNT registers as follows:

With prescaler enabled: ALM1[23:0] is compared to RTC[23:0]

With prescaler disabled: ALM1[23:0] is compared to RTC[28:5]

An interrupt is sent to the host (if enabled via I²C, see interrupt controller section) when the alarm logic detects that the RTC_COUNT value is equal to the pre-programmed ALARM1 register value.

The alarm logic compares the RTC_ALARM2 register bits to the RTC_COUNT registers as follows:

With prescaler enabled: ALM2[23:0] is compared to RTC[22:7]

With prescaler disabled: ALM2[15:0] is compared to RTC[27:12]

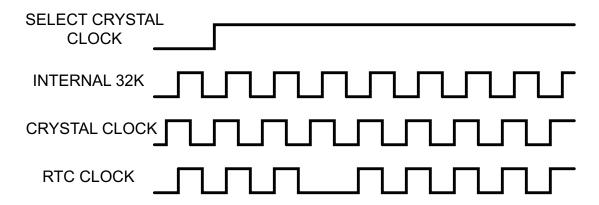
An interrupt is sent to the host (if enabled via I²C, see interrupt controller section) and the sleep mode ends when the alarm logic detects that the RTC_COUNT value is equal to the pre-programmed ALARM2 register value.

RTC_ALARM1	RTC_ALARM1_HI [ADDRESS=0xC1]								
Bit Number	B7	B6	B5	B4	В3	B2	B1	B0	
Bit Name	ALM1[23]	ALM1[22]	ALM1[21]	ALM1[20]	ALM1[19]	ALM1[18]	ALM1[17]	ALM1[16]	
RTC_ALARM1	_MID [Addr 0x	C2]						Default to 0	
Bit Name	ALM1[15]	ALM1[14]	ALM1[13]	ALM1[12]	ALM1[11]	ALM1[10]	ALM1[9]	ALM1[8]	
RTC_ALARM1	_LO [Addr 0x0	3]						Default to 0	
Bit Name	ALM1[7]	ALM1[6]	ALM1[5]	ALM1[4]	ALM1[3]	ALM1[2]	ALM1[1]	ALM1[0]	
RTC_ALARM2	2_HI [Addr 0xC	4]						Default to 0	
Bit Name	ALM2[15]	ALM2[14]	ALM2[13]	ALM2[12]	ALM2[11]	ALM2[10]	ALM2[9]	ALM2[8]	
RTC_ALARM2_LO [Addr 0xC5								Default to 0	
Bit Name	ALM2[7]	ALM2[6]	ALM2[5]	ALM2[4]	ALM2[3]	ALM2[2]	ALM2[1]	ALM2[0]	

Table 3-55. RTC Alarm

3.60 SWITCHING BETWEEN INTERNAL AND CRYSTAL CLOCK

When switching between the internal clock to the crystal clock, an internal logic extends the LO time of the clock sent to the counter to avoid undesired glitches. A typical clock switching timing diagram is shown below:



3.61 CRYSTAL OSCILLATOR

The crystal oscillator has internal load capacitances, in order to allow a typical 32K crystal to operate as described in the electrical characteristics tables. The TPS658600 has four integrated capacitors that can be connected to the XTAL1, XTAL2 pins as defined by control bits CL_SEL[1:0] in register RTC_CTRL, effectively applying a load capacitance to the external crystal.

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Table 3-56. CL_SEL[1:0] Setting (Default in bold)

CL_SEL[1]	CL_SEL[0]	Total C_LOAD [pF] (typ)
0	0	1.5
0	1	6.5
1	0	7.5
1	1	12.5

3.62 ADC FUNCTIONAL OVERVIEW

The TPS658600 ADC is capable of running in a variety of modes programmable via I²C. The ADC control and data registers are accessible only by the standard I²C interface (SDA/SCLK). An internal 11:1 analog multiplexer is used to allow a single SAR converter to sequentially monitor up to 11 analog inputs, as shown in Table 3-57.

Table 3-57. ADC Channel Settings

CHANNEL	CONNECTION	PARAMETER SAMPLED	VOLTAGE RANGE	SPECIAL FEATURES	FULL SCALE READING
CH1	ANLG1 pin		0-2.6V	Internal pull-up current	2.6 V
CH2	ANLG2 pin	User defined	AVDD6-V(ANLGn)>	source programmable via	2.6 V
CH3	ANLG3 pin		400mV	I ² C: 0/ 3/10/50 μA	2.6 V
CH4	ISET pin	Voltage proportional to charge current	0V (charger off) to		2.6 V
CH5	TS pin	Voltage proportional to pack temperature	See Charger Section		2.6 V
CH6	RSVD	N/A	N/A	_	2.6 V
CH7	LDO_RTC pin	Internal LDO output voltage	0V to 3.3V	_	4.622 V
CH8	SYS pin	System Power bus voltage	0V to 5.5V	_	5.547 V
CH9	VIN_CHG pin	System Power bus voltage	0V to 5.5V	_	5.547 V
CH10	BAT pin	Battery pack positive terminal voltage	0V to 4.6V	_	4.622 V
CH11	COMP pin	COMP pin voltage	0V - 2.6V	_	2.6 V



A simplified block diagram for the ADC analog section is show in Figure 3-22.

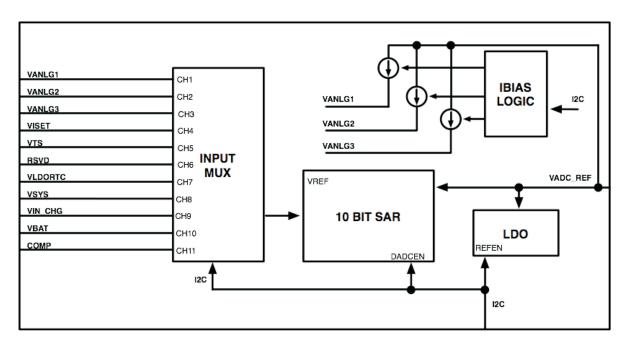


Figure 3-22. Simplified ADC Block

3.62.1 ADC External Input Pins – Bias Current Settings

The external pins ANLG1, ANLG2 and ANLG3 may be biased using internal pull-up current sources, with current source value set by register ADCANLG. The current sources are turned OFF when the ADC reference is disabled.

Table 3-58. ADC Input Bias Selection

ADCANLG [Addr 0x60] Default to 0											
Bit Name	ANLG2FLT	ANLG3FLT	IANLG3[1]	IANLG3[0]	IANLG2[1]	IANLG2[0]	IANLG1[1]	IANLG1[0]			
Function	SPARE	SPARE	ANLG3 BIAS CUR	RENT SOURCE	ANLG2 BIAS CU	IRRENT SOURCE	ANLG1 BIAS CI	JRRENT SOURCE			

Table 3-59. ANLG3/2/1 Current Source Settings

IANLG[1]	IANLG[0]	Current (µA)
0	0	0
0	1	3
1	0	10
1	1	50

The COMP pin has no internal pull-up current source.

3.62.2 ADC Timing Engine Overview

The ADC timing engine can be configured to perform either one reading, a single-trigger multiple set of readings, or to operate continuously until high or low limits are violated on any channel.

A conversion cycle includes the following steps:

- 1. Program the timing engine mode (single sample, multiple sample, etc.) and triggers
- 2. Enable the internal ADC reference and conversion start delay



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3. Select the channel to be used as the SAR input and start the conversion cycle

The timing engine has an internal ALU that stores the converted data in an internal accumulator, executing mathematical operations with the stored data. A conversion cycle ends when the accumulator data is transferred to the TPS658600 ADC RAM data registers.

When the conversion cycle is completed, an interrupt request corresponding to indicate end of conversion operation is generated. The interrupt controller subsystem will set the ACK_ADC (bit B1, register 0xB6) to indicate the source of the interrupt was the ADC subsystem. Additional information is available in the ADC0_INT register (0x9A).

3.62.3 Configuring the ADC Conversion Cycle

3.62.3.1 Number of Samples and ADC Input Setup

Register ADC0_SET controls the following parameters for a conversion cycle: conversion start, continuous or fixed-interval sampling mode, number of samples to be taken and channel selection.

Setting the ADC0 EN bit to 1 will start the conversion process. While a conversion cycle is being executed (and conversions are being taken) the ADC0 INT register cannot be externally accessed.

The ADC engine has a BUSY signal generated by the ADC Digital Control Logic to indicate this condition. If the ADC0_EN bit is cleared to 0 during a conversion, the conversion cycle will continue until the number of samples specified with the RD_MODE bits has been taken so that the SUM (average) value from the accumulator will be valid. The ADC0 EN bit must be set to 0 before a new conversion configuration is set up.

Table 3-60. ADC0 Conversion Selection

ADC0_SET	ADC0_SET [Addr 0x61] Default in BOLD										
Bit Number	В7	B6	B5	B4	В3	B2	B1	В0			
Bit Name	ADC0_EN	REPEAT0	RD0_MODE[1]	RD0_MODE[0]	CHSEL0[3]	CHSEL0[2]	CHSEL0[1]	CHSEL0[0]			
Function	ADC0 CONVERSION START	ADC0 REPEAT MODE ENABLE	READINGS IN A	READINGS IN A CONVERSION		ADC0 INPUT CHANNEL SELECTION					
When 0	DISABLED	DISABLED	CEE ADO DE ADINO CETTINOS		OFF ADO CHANNEL OF FOT CETTINGS			TINCS			
When 1	ENABLED	ENABLED	SEE ADC READING SETTINGS		SEE ADC CHANNEL SELECT SETTINGS						

Table 3-61. ADC Readings Setting (Default in bold)

RD0_MODE[1]	RD0_MODE[0]	NUMBER OF READINGS
0	0	1
0	1	16
1	0	32
1	1	64

Table 3-62. ADC Channel Select Settings (Default in bold)

CHSELn[3:0]	CHANNEL	CHSELn[3:0]	CHANNEL
0000	CH1	1000	CH9
0001	CH2	1001	CH10
0010	CH3	1010	CH11
0011	CH4	1011	AGND
0100	CH5	1100	AGND

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Table 3-62. ADC	Channel Select	: Settings (Default in b	oold) ((continued)

CHSELn[3:0]	CHANNEL	CHSELn[3:0]	CHANNEL
0101	CH6	1101	AGND
0110	CH7	1110	AGND
0111	CH8	1111	AGND

Continuous sampling mode can be set by writing $\overline{\text{REPEAT}}$ to **1** and RD0_MODE[1:0]=00. With those settings the conversions will be performed as single samples, without wait times, until the ADC_EN bit is cleared by the host or a limit violation occurs. If fixed-interval sampling mode (REPEAT0 = **0**) is chosen, the conversion cycle will consist of a specific number of samples (1, 16, 32, or 64) as specified by the RD0_MODE[1:0] bits. When a multiple sample conversion cycle is selected the time interval between individual samples is defined by the WAIT bits (register ADC0_WAIT). To exit the continuous conversion mode before a limit violation occurs, the host must first set the $\overline{\text{REPEAT}}$ bit to LO, and then set the ADC0_EN bit to **0**.

3.62.4 Timing and ADC Reference Setup

The ADC0_WAIT register controls the ADC0 timing engine reset, wait time value and the converter internal reference voltage enable. The ADC reference and SAR are disabled when AUTO_REF=0 AND REF_EN=0. The use of external references for the ADC is not supported.

Table 3-63. ADC0 Conversion Timing

ADC0_WAIT [Defaults in BOLD								
Bit Number	B7	В6	B5	B4	В3	B2	B1	В0	
Bit Name	ADC_RESET	RSVD626	AUTO_REF	REF_EN	WAIT0[3]	WAIT0[2]	WAIT0[1]	WAIT0[0]	
Function	RESET CONVERSION CYCLE	NOT USED	ADC Conversion Control		WAIT TIME BETWEEN INDIVIDUAL CONVERSIONS, REPEAT MODE ENABLED (ms)				
When 0	ALL ADC ENGINES ACTIVE	NOT USED		Function is based on ADC		SEE WAITO SETTINGS TABLE			
When 1	RESET ALL ADC ENGINES	NOT USED	Conversio	on Control	AUTHOL				

Table 3-64. ADC Conversion Control (Default in bold)

AUTO_REF	REF_EN	DESCRIPTION
0	0	Reference and ADC disabled
0	1	Manual control of the Reference. WAIT=0 is not valid. 8ms must occur between REF_EN=1 and ADC0_EN=1
1	0	Automatic control of the Reference. Automatically enabled 8 ms before an ADC conversion is started.
1	1	Not a valid state

The relative timing between enabling the internal ADC reference / ANLGn pin bias currents and the start of a conversion cycle is controlled by bits AUTO_REF and REF_EN. Those bits allow implementation of a software only reference enable control or automatic reference enable control, as shown below:

Software enables ADC reference: Clear AUTO_REF bit to **0**. Software must set REF_EN to **1** at least 8 ms before enabling an ADC engine and not clear REF_EN until all ADC engines are stopped.

Automatic ADC reference enable, internal or external trigger, wait time < 8ms : Set AUTO_REF bit to 1. The ADC logic will keep the ADC reference always on.

Automatic ADC reference enable, internal trigger, wait time > 8ms : Set AUTO_REF bit to 1. The ADC logic enables the ADC reference 8 ms before the programmed wait time is reached

Setting ADC_RESET to **1** will return ALL the ADC timing engine to the idle state, ready to be re-enabled for a new conversion cycle. During the conversion cycle the ADC_RESET bit is internally set to LO prior to the first ADC conversion being started. WAIT[3:0] sets the time interval between samples in the case where a multiple-sample conversion cycle is being executed. WAIT[3:0] should be set LO in single sample conversion cycles.

Table 3-65. ADC0 Conversion Wait Settings (Default in bold); Valid for All Timing Engines

WAIT0[3:0]	WAIT TIME (ms)	WAIT0[3:0]	WAIT TIME (ms)
0000	0.000	1000	8.000
0001	0.062	1001	16.00
0010	0.125	1010	32.00
0011	0.250	1011	64.00
0100	0.500	1100	128.0
0101	1.000	1101	256.0
0110	2.000	1110	512.0
0111	4.000	1111	1024

3.62.5 External Trigger Setup

The ADC conversion cycle can be started via an internal or external trigger when using the ADC0 timing engine. The trigger is selectable by setting bits ADC0_TRIG4, ADC0_TRIG2 in registers ADC0_DELAY.

Table 3-66. Trigger Settings

ADC0_DELAY [Addr 0x67] Default to 0										
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0		
Bit Name	ADC0_TRIG4	ADC0_TRIG2	ADC0HOLD	ADC0_EDGE	RSVD673	DELAY0[2]	DELAY0[1]	DELAY0[0]		
Function	GPIO4 IS ADC0 EXT TRIGGER	GPIO2 IS ADC0 EXT TRIGGER	ADC HOLDOFF ON/OFF CONTROL	NOT USED	NOT USED	ADC EXTERNAL TRIGGER DELAY (µs)				
When 0	DISABLED	DISABLED	OFF	NOT USED	NOT USED	000=00 001=50 010= 100 011=150 100=200 101=250 110=350 111=450				
When 1	ENABLED	ENABLED	ON	NOT USED	NOT USED			350 111=450		

When more than one GPIO trigger source is selected the GPIO signals are OR'ed prior to trigger detection. When both of those bits are cleared to **0** the internal trigger is selected.

ADC0_HOLDOFF (ADC0_DELAY[5]) enables the GPIOx trigger source to be used as a level-sensed gating signal which will suspend conversion cycles when the trigger source is low. The default for this bit is **0**. When ADC0HOLD is **0**, the conversion cycle will continue for the preset number of conversions selected with the RD_MODE bits once the initial trigger occurs. If the ADC0HOLD bit is **1**, any pending conversion cycle can be suspended if the GPIO trigger goes low (and resumes once the trigger signal goes high again and the trigger delay time has been met). ADC0_DELAY[2:0] are used to set the initial wait interval from the trigger event until the first conversion in a cycle is started. This delay may be from 0 to 450us.

When the GPIO's are selected as external triggers the ADC conversion start will be dependent on the GPIO configuration. Table 3-67 shows the possible options:

Table 3-67. ADC0 GPIO Trigger Settings

ADC0_TRIG2 = 1, ADC0_TRIG4 = 0			ADC0_TRIG2 = 0, ADC0_TRIG4 = 1			
GPIO2 PIN	ADC TRIGGER SOURCE	WHEN HOLDOFF=HI	GPIO4 PIN	ADC TRIGGER SOURCE	WHEN HOLDOFF=HI	
NON-INVERTED	GPIO2 POSITIVE EDGE	SUSPEND TRIGGER at GPIO2=LO	NON-INVERTED	GPIO4 POSITIVE EDGE	SUSPEND TRIGGER at GPIO4=LO	



Table 3-67. ADC0 GPIO Trigger Settings (continued)

ADC0_TRIG2 = 1, ADC0_TRIG4 = 0			ADC0_TRIG2 = 0, ADC0_TRIG4 = 1			
INVERTED	GPIO2 NEGATIVE EDGE	SUSPEND TRIGGER at GPIO2=HI	INVERTED	GPIO4 NEGATIVE EDGE	SUSPEND TRIGGER at GPIO4=HI	

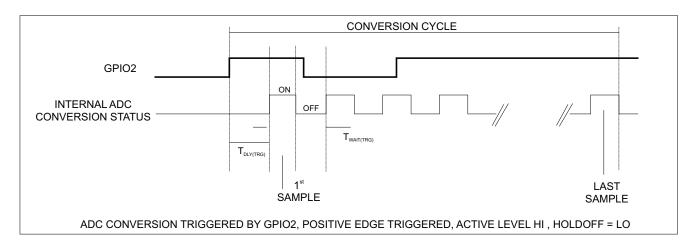
	ADC0_TRIG2=HI,ADC0_TRIG4=HI										
GPIO2 PIN	GPIO4 PIN	ADC TRIGGER SOURCE	WHEN HOLDOFF=HI								
NON-INVERTED	NON-INVERTED	GPIO2 OR GPIO4 POSITIVE EDGE	SUSPEND TRIGGER at GPIO2 = LO AND GPIO4 = LO								
NON-INVERTED	INVERTED	GPIO2 POSITIVE EDGE <i>OR</i> GPIO4 NEGATIVE EDGE	SUSPEND TRIGGER at GPIO2 = LO AND GPIO4 = HI								
INVERTED	NON-INVERTED	GPIO2 NEGATIVE EDGE <i>OR</i> GPIO4 POSITIVE EDGE	SUSPEND TRIGGER at GPIO2 = HI AND GPIO4 = LO								
INVERTED	INVERTED	GPIO2 <i>OR</i> GPIO4 NEGATIVE EDGE	SUSPEND TRIGGER at GPIO2 = HI AND GPIO4 = HI								

The procedure to start an externally-triggered conversion cycle has the following steps:

- 1. Verify that the current conversion cycle has ended (ADC0_BUSY is **0**, I²C register STAT4)
- 2. Clear ADC0_EN to 0 (ADC0_SET[7]).
- 3. Set the appropriate bit in the corresponding ADC0_DELAY register (example write 1 to ADC0_DELAY bit B7 to use GPIO4 as trigger source for ADC0). Ensure that the selected GPIOs have the appropriate input and polarity selection see GPIOSET1 and GPIOSET2 registers.
- 4. Set ADC0 EN to 1

After step 4 the ADC will be armed, waiting for an external trigger detection to start a conversion cycle. In triggered mode the current cycle will not expire if the converter is armed and an external trigger is not detected.





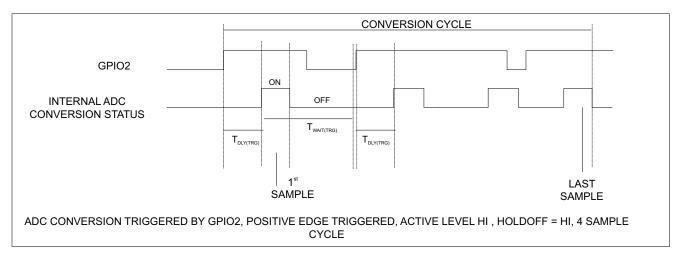


Figure 3-23. ADC Operation Example

3.62.6 ADC ALU Unit and Result Registers

The ALU performs mathematical operations on the ADC output data. It can execute average (SUM) calculations and minimum / maximum detection for a conversion cycle. The result of the SUM calculations is stored in a 16 bit accumulator register (ADC0SUM2, ADC0_SUM1) and the MIN/MAX data is stored in 10-bit registers (ADC0 MAX2, ADC0 MAX1, ADC0 MIN2, ADC0 MIN1).

Equation 15 indicates how to translate the register data into a voltage reading for each channel: ADC_OUTPUT_COUNTS = [ADC_INPUT_VOLTAGE / FULL_SCALE_READING] × 1023

Table 3-68. ADC0 Output Data

ADC0_SUM2(ADC0_SUM2 ⁽¹⁾ [Addr 0x94]											
Bit Number	В7	В6	B5	B4	В3	B2	B1	В0				
Bit Name	AVG[15]	AVG[14]	AVG[13]	AVG[12]	AVG[11]	AVG[10]	AVG[9]	AVG[8]				
ADC0_SUM1 [Addr 0x95]											
Bit Name	AVG[7]	AVG[6]	AVG[5]	AVG[4]	AVG[3]	AVG[2]	AVG[1]	AVG[0]				
ADC0_MAX2 [Addr 0x96]											
Bit Name	RSVD967	RSVD966	RSVD965	RSVD964	RSVD963	RSVD962	MAX[9]	MAX[8]				
ADC0_MAX1 [Addr 0x97]												

(1) All bits in ADC0_SUM2 are read only.



Table 3-68. ADC0 Output Data (continued)

Bit Name	MAX[7]	MAX[6]	MAX[5]	MAX[4]	MAX[3]	MAX[2]	MAX[1]	MAX[0]
ADC0_MIN2 [Addr 0x98]							
Bit Name	RSVD987	RSVD986	RSVD985	RSVD984	RSVD983	RSVD982	MIN[9]	MIN[8]
ADC0_MIN1 [Addr 0x99]							
Bit Name	MIN[7]	MIN[6]	MIN[5]	MIN[4]	MIN[3]	MIN[2]	MIN[1]	MIN[0]

3.62.7 Limit Check Setup

The ADC0 timing engine has configurable low and high thresholds to interrupt the host when conversion values, stored in registers ADC0_MAX and ADC0_MIN exceed a pre-selected range . A limit violation will be detected and an interrupt sent to the host when the sampled value stored in registers ADC0_MAX2, ADC0_MAX1 exceeds the maximum value set in registers ADC0_HILIM2, ADC0_HILIM1 or when the minimum sampled value stored in registers ADC0_MIN2, ADC0_MIN1 is lower than the minimum value programmed in registers and ADC0_HILIM2, ADC0_HILIM1.

Limit violations can not occur if Low Limit = 0x000 and High Limit = 0xFFF.

ADC0_HILIM2	[Addr 0x63]							
Bit Number	В7	В6	B5	B4	В3	B2	B1	В0
Bit Name	RSVD637	RSVD636	RSVD635	RSVD634	HILIMA[11]	HILIMA[10]	HILIMA[9]	HILIMA[8]
ADC0_HILIM1	[Addr 0x64]							
Bit Name	HILIMA[7]	HILIMA[6]	HILIMA[5]	HILIMA[4]	HILIMA[3]	HILIMA[2]	HILIMA[1]	HILIMA[0]
ADC0_LOLIM	2 [Addr 0x65]							
Bit Name	RSVD657	RSVD656	RSVD655	RSVD654	LOLIMA[11]	LOLIMA[10]	LOLIMA[9]	LOLIMA[8]
ADC0_LOLIM	1 [Addr 0x66]							
Bit Name	LOLIMA[7]	LOLIMA[6]	LOLIMA[5]	LOLIMA[4]	LOLIMA[3]	LOLIMA[2]	LOLIMA[1]	LOLIMA[0]

Table 3-69. ADC0 Limit Selection

The limit detection ADC conversion cycle should be configured with internal trigger and sampling sequences as follows:

- 1. To detect when an individual sample violates the max/min limits: Set RD_MODE[1:0] to **00** and REPEAT to **1**. With these settings the ALU will compare the 10-bit ADC data returned from the SAR engine to the 10 bit values loaded in the ADC0_LIMIT values. The conversion sequence will repeat until either a violation interrupt occurs or the ADC0_EN bit is written to 0.
- 2. To detect when the average value violates the max/min limits: Set RD_MODE[1:0]) to **01**, **10** or **11** and REPEAT to **1**. At the end of the multiple sample conversion cycle the ALU will calculate the 12 bit average of the sample values by shifting the AVG[15:0] register (shift right 2 if 16 samples, shift right 3 if 32 samples and shift right 4 if 64 samples). The shifted 12-bit average value is then compared to the value programmed in registers ADC0_LIMIT.

3.62.8 ADC Status Registers

The ADC conversion status for the timing engine is available in the ADC0_INT register. The ADC0_INT register is read-only. Reading the ADC0_INT register clears the ADC0INT bit in the STAT4 register (ADC0INT=0).

Table 3-70. ADC Conversion Status

ADC0_ INT [ADC0_ INT [Addr 0x9A]											
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0				
Bit Name	ADC0_ DONE	ADC0_ ERROR	HILIM0_FLT	LOLIM0_FLT	RSVD9A3	RSVD9A2	ADC0_GPIO4ST	ADC0_GPIO2ST				
Function	CONVERSION CYCLE STATUS	ADC_STATUS	HI LIMIT FAULT	LO LIMIT FAULT	NOT USED	NOT USED	GPIO4 LEVEL AT ADC0 EOC	GPIO2 LEVEL AT ADC0 EOC				

Table 3-70. ADC Conversion Status (continued)

ADC0_ INT [ADC0_INT [Addr 0x9A]											
When 0	BUSY	NO ERROR	NOT DETECTED	NO DETECTED	NOT USED	NOT USED	LOW	LOW				
When 1	DONE	ERROR	DETECTED	DETECTED	NOT USED	NOT USED	HIGH	HIGH				

3.63 **GPIO**

The TPS658600 integrates 4 general purpose push-pull ports (GPIOs) which can be configured as selectable inputs or outputs via register GPIOSET1 bits. When the GPIO is not configured the pull-down current source (2.5uA typ) is connected to the GPIOn pin. When configured as an input the GPIO can be set as inverting or non-inverting via bits GPIOnINV in the GPIOSET2 register.

When configured as an output, the GPIO output level is defined by bits GPIOnOUT in the GPIOSET2 register.

Table 3-71. GPIO Control⁽¹⁾

GPIOSET1 [Add	r 0x5D]							Default to 0
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0
Bit Name	GPIO4_MODE 1	GPIO4_MODE 0	GPIO3_MODE 1	GPIO3_MODE 0	GPIO2_MODE 1	GPIO2_MODE 0	GPIO1_MODE 1	GPIO1_MODE 0
Function	GPIO4 CONI	FIGURATION	GPIO3 CONI	FIGURATION	GPIO2 CON	FIGURATION	GPIO1 CONI	FIGURATION
GPIOSET2 [Add	r 0x5E]							
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0
Bit Name	GPIO4INV	GPIO3INV	GPIO2INV	GPIO1INV	GPIO2_MODE 1	GPIO2_MODE 0	GPIO1_MODE 1	GPIO1_MODE 0
Function	GPIO4 INPUT BUFFER MODE	GPIO3 INPUT BUFFER MODE	GPIO2 INPUT BUFFER MODE	GPIO1 INPUT BUFFER MODE	GPIO4 VOLTAGE, CONFIGURED AS OUTPUT	GPIO3 VOLTAGE, CONFIGURED AS OUTPUT	GPIO2 VOLTAGE, CONFIGURED AS OUTPUT	GPIO1 VOLTAGE, CONFIGURED AS OUTPUT
When 0	NON- INVERTING	NON- INVERTING	NON- INVERTING	NON- INVERTING	LO	LO	LO	LO
When 1	INVERTING	INVERTING	INVERTING	INVERTING	HI	HI	HI	HI

⁽¹⁾ All GPIO's default to the same configuration.

Table 3-72. GPIO4/3/2/1_MODE Settings

GPIOx_MODE[1]	GPIOx_MODE[0]	GPIO4 Config	GPIO3 Config	GPIO2 Config	GPIO1 Config	
0	0	Not Configured	Not Configured	Not Configured	Not Configured	
0	1	Output	Output	Output	Output	
1	0	Input ADC Trigger	Input Not Used	Input ADC Trigger	Input PWM/PFM Control	
1	1	Input LDO6/7/8 Enable	Input LDO2/3 Enable	Input LDO0/1 ENABLE	Input Not Used	

3.64 STATUS REGISTERS

The system status is accessible via I²C registers listed below. The STATn registers are read only.

Table 3-73. Status Registers

B6 ADC0_ERROR ADC_STATUS S	B5 HILIMO_FLT HI LIMIT FAULT	B4 LOLIM0_FLT LO LIMIT FAULT	B3 RSVD9A3	B2 RSVD9A2	B1 ADC0_GPIO4ST	B0 ADC0_GPIO2ST
ADC_STATUS	_	_			ADC0_GPIO4ST	ADC0_GPIO2ST
	HI LIMIT FAULT	LO LIMIT FAULT	NOTHOED			
3		20 2 177021	NOT USED	NOT USED	GPIO4 LEVEL AT ADC0 EOC	GPIO2 LEVEL AT ADC0 EOC
NO ERROR	NOT DETECTED	NOT DETECTED	NOT USED	NOT USED	LOW	LOW
ERROR	DETECTED	DETECTED	NOT USED	NOT USED	HIGH	HIGH
B6	B5	B4	B3	B2	B1	В0
	ERROR B6					



Table 3-73. Status Registers (continued)

Bit Name	BATSYSON	ACSWON	USBSWON	BATCHGSWON	RSVDB83	PACK_HOT	PACK_COLD	BATDET
Function	BAT TO SYS SWITCH ON/OFF STATUS	AC SWITCH ON/OFF STATUS	USB SWITCH ON/OFF STATUS	BAT TO VIN_CHG SWITCH ON/OFF STATUS	SPARE	PACK TEMP EXCEEDS HOT THRESHOLD	PACK TEMP BELOW COLD THRESHOLD	BATTTERY PACK TS THERMISTOR DETECTION
When 0	OFF	OFF	OFF	OFF	NOT USED	NO	NO	NOT DETECTED
When 1	ON	ON	ON	ON	NOT USED	YES	YES	DETECTED
STAT2 [Addr 0xE	BA]							
Bit Number	В7	B6	B5	B4	В3	B2	B1	В0
Bit Name	TMRFLT	DPPM_ON(4)	TH_ON	ITERM	SLEEPTSHUT	STAT1	STAT2	COMPDET
Function	PRE-CHARGE OR CHARGE TIMER TIMEOUT	CHARGER DPPM LOOP STATUS	CHARGER THERMAL LOOP STATUS	CHARGE CURRENT BELOW TERMINATION THRESHOLD	NOT USED	CHARGE	STATUS	nHOTRST PULSE GENERATED REBOOT CYCLE
When 0	NO	OFF	OFF	NO	NOT USED		HARGE ON	NO
When 1	YES	ON	ON	YES	NOT USED	01=CHARGE DONE 10=FAST CHARGE ON 11= CHARGE SUSPEND, TIMER FAULT, CHARGER OFF		YES
STAT3 [Addr 0xE	BB]							
STAT3 [Addr 0xE	BB]	B6	B5	B4	B3			B0
		B6 LOWSYS	B5 RESUME	B4 RTC_ALARM	B3 ACDET	TIMER FAULT,	CHARGER OFF	B0 USB_OVP
Bit Number	B7				_	TIMER FAULT,	CHARGER OFF B1	
Bit Number Bit Name	B7 SLEEPREQ SLEEP REQUEST	LOWSYS LOWSYS DETECTION	RESUME RESUME DETECTION	RTC_ALARM	ACDET AC INPUT POWER	B2 USBDET USB INPUT	B1 AC_OVP AC INPUT OVP	USB_OVP USB INPUT OVP
Bit Number Bit Name Function	B7 SLEEPREQ SLEEP REQUEST STATE SET	LOWSYS LOWSYS DETECTION STATUS	RESUME RESUME DETECTION STATUS	RTC_ALARM SPARE	ACDET AC INPUT POWER STATUS	B2 USBDET USB INPUT POWER STATUS	B1 AC_OVP AC INPUT OVP DETECTION	USB_OVP USB INPUT OVP DETECTION
Bit Number Bit Name Function When 0	B7 SLEEPREQ SLEEP REQUEST STATE SET NO YES	LOWSYS LOWSYS DETECTION STATUS NOT DETECTED	RESUME RESUME DETECTION STATUS NOT DETECTED	RTC_ALARM SPARE SPARE	ACDET AC INPUT POWER STATUS NOT DETECTED	B2 USBDET USB INPUT POWER STATUS NOT DETECTED	B1 AC_OVP AC INPUT OVP DETECTION NO OVP	USB_OVP USB INPUT OVP DETECTION NO OVP
Bit Number Bit Name Function When 0 When 1	B7 SLEEPREQ SLEEP REQUEST STATE SET NO YES	LOWSYS LOWSYS DETECTION STATUS NOT DETECTED	RESUME RESUME DETECTION STATUS NOT DETECTED	RTC_ALARM SPARE SPARE	ACDET AC INPUT POWER STATUS NOT DETECTED	B2 USBDET USB INPUT POWER STATUS NOT DETECTED	B1 AC_OVP AC INPUT OVP DETECTION NO OVP	USB_OVP USB INPUT OVP DETECTION NO OVP
Bit Number Bit Name Function When 0 When 1 STAT4 [Addr 0xE	B7 SLEEPREQ SLEEP REQUEST STATE SET NO YES BC]	LOWSYS LOWSYS DETECTION STATUS NOT DETECTED DETECTED	RESUME RESUME DETECTION STATUS NOT DETECTED DETECTED	RTC_ALARM SPARE SPARE SPARE	ACDET AC INPUT POWER STATUS NOT DETECTED DETECTED	B2 USBDET USB INPUT POWER STATUS NOT DETECTED DETECTED	B1 AC_OVP AC INPUT OVP DETECTION NO OVP OVP DETECTED	USB_OVP USB INPUT OVP DETECTION NO OVP OVP DETECTED
Bit Number Bit Name Function When 0 When 1 STAT4 [Addr 0xE Bit Number	B7 SLEEPREQ SLEEP REQUEST STATE SET NO YES BC] B7	LOWSYS LOWSYS DETECTION STATUS NOT DETECTED DETECTED B6	RESUME RESUME DETECTION STATUS NOT DETECTED DETECTED B5	RTC_ALARM SPARE SPARE SPARE SPARE	ACDET AC INPUT POWER STATUS NOT DETECTED DETECTED B3	B2 USBDET USB INPUT POWER STATUS NOT DETECTED DETECTED	B1 AC_OVP AC INPUT OVP DETECTION NO OVP OVP DETECTED	USB_OVP USB INPUT OVP DETECTION NO OVP OVP DETECTED B0
Bit Number Bit Name Function When 0 When 1 STAT4 [Addr 0xB Bit Number Bit Name	B7 SLEEPREQ SLEEP REQUEST STATE SET NO YES BC] B7 RSVDBC7	LOWSYS LOWSYS DETECTION STATUS NOT DETECTED DETECTED B6 RSVDBC6	RESUME RESUME DETECTION STATUS NOT DETECTED DETECTED B5 RSVDBC5	RTC_ALARM SPARE SPARE SPARE SPARE ADCOBUSY ADC ENGINE 0	ACDET AC INPUT POWER STATUS NOT DETECTED DETECTED B3 RSVDBC3	B2 USBDET USB INPUT POWER STATUS NOT DETECTED DETECTED B2 RSVDBC2	B1 AC_OVP AC INPUT OVP DETECTION NO OVP OVP DETECTED B1 RSVDBC1	USB_OVP USB INPUT OVP DETECTION NO OVP OVP DETECTED B0 ADCOINT ADC ENGINE 0

3.65 INTERRUPT CONTROLLER

The interrupt controller monitors the system status bus and internal signals continuously, generating an interrupt (INT = '0') when a system status change is detected. Individual bits that generated the interrupt will be set to 1 in the INT_ACK registers (read only registers), indicating which parameters generated the interrupt.

All the parameters monitored by the interrupt controller can be masked by registers INT_MASK (**0**=unmasked, **1**=masked). Masked parameters do not generate an interrupt when their state changes. When the host reads the INT_ACK registers, the interrupt is reset causing the INT pin to go to a logic 1 and the INT_ACK register bits are cleared.

The power good signals from the integrated supplies are level sensitive, and they will continue to cause an interrupt until the power good condition returns or the signal is masked. For non-masked power good parameters the INT_ACK bit will indicate the present state of the power good signals. The INTMASK register bits are cleared to **0** upon power-up.

Table 3-74. INT_ACK registers

INT_ACK1 [A	INT_ACK1 [Addr 0xB5]											
Bit Number	B7	B6	B5	B4	В3	B2	B1	В0				
Bit Name	ACK_PLDO7	ACK_PLDO6	ACK_PLDO5	ACK_PLDO4	ACK_PLDO3	ACK_PLDO2	ACK_PLDO1	ACK_PLDO0				
INT_ACK2 [A	ddr 0xB6]											
Bit Name	ACK_PSM3	ACK_PSM2	ACK_PSM1	ACK_PSM0	ACK_PLDO9	ACK_PLDO8	ACK_ADC	ACK_ COMPDET ⁽¹⁾				
INT_ACK3 [A	NT_ACK3 [Addr 0xB7]											

(1) ACK_COMPDET= ACK INT BY HOTRST FLAG SET

Table 3-74. INT_ACK registers (continued)

Bit Name	ACK_PP	ACK_CHGTEMP	ACK_CHGSTAT	ACK_BATDET	ACK_ACDET	ACK_USBDET	ACKACUSBOVP	ACK_RTCALM1
INT_ACK4 [Ad	ddr 0xB8]							
Bit Name	RSVDB87	RSVDB86 ⁽²⁾	IMASKLOWSYS	IMASKRESUME	IMASKRTCALM1	IMASKACDET	ACK_LOWSYS	ACK_RESUME

⁽²⁾ RSVDB86= ACK INT BY SLEEP REQUEST

Table 3-75. INTMASK Registers

NTMASK1 [Addr 0xB0] Default to 1 (Masked)										
Bit Name	IMASK_PLDO7	IMASK_PLDO6	IMASK_PLDO5	IMASK_PLDO4	IMASK_PLDO3	IMASK_PLDO2	IMASK_PLDO1	IMASK_PLDO0		
INTMASK2 [Addr 0	INTMASK2 [Addr 0xB1] Default to 1 (Masket									
Bit Name	IMASK_PSM3	IMASK_PSM2	IMASK_PSM1	IMASK_PSM0	IMASK_PLDO9	IMASK_PLDO8	IMASKADC	RSVDB10		
INTMASK3 [Addr 0	xB2]						D	Default to 1 (Masked)		
Bit Name	IMASKSYSSW	IMASKACSW	IMASKUSBSW	IMASKBCHGSW	RSVDB83	IMASK_HOT	IMASK_COLD	IMASKBATDET		
INTMASK4 [Addr 0	xB3]						D	Default to 1 (Masked)		
Bit Name	IMASK_TMRFLT	IMASK_DPPM	IMASK_THON	IMASK_TERM	IMASK_TSHUT	IMASKCHSTAT	IMASKRTCALM2	IMASK_COMP		
INTMASK5 [Addr 0xB4] Default to 1 (Masked)										
Bit Name	RSVDB47	IMASKLOWSYS	IMASKRESUME	IMASKRTCALM1	IMASKACDET	IMASKUSBDET	IMASKAC_OVP	IMASKUSB_OVP		

The interrupt controller can monitor either level or edge transitions to generate the interrupt request:

PARAMETER	STATUS BIT	SET INT_ACK BIT ON	MASK reg/bit	INT_ACK reg/bit	ACK clear at
LDO0 power good fault	LDO0 power good fault None		INTMASK1 / IMASK_PLDO0	INT_ACK1 / ACK_LDO0	Read INT_ACK1
LDO1 power good fault	None	PGOOD FAULT DETECTED	INTMASK1 / IMASK_PLDO1	INT_ACK1 / ACK_PLDO1	Read INT_ACK1
LDO2 power good fault	None	PGOOD FAULT DETECTED	INTMASK1 / IMASK_PLDO2	INT_ACK1 / ACK_PLDO2	Read INT_ACK1
LDO3 power good fault	None	PGOOD FAULT DETECTED	INTMASK1 / IMASK_PLDO3	INT_ACK1 / ACK_PLDO3	Read INT_ACK1
LDO4 power good fault	None	PGOOD FAULT DETECTED	INTMASK1 / IMASK_PLDO4	INT_ACK1 / ACK_PLDO4	Read INT_ACK1
LDO5 power good fault	None	PGOOD FAULT DETECTED	INTMASK1 / IMASK_PLDO5	INT_ACK1 / ACK_PLDO5	Read INT_ACK1
LDO6 power good fault	None	PGOOD FAULT DETECTED	INTMASK1 / IMASK_PLDO6	INT_ACK1 / ACK_PLDO6	Read INT_ACK1
LDO7 power good fault	None	PGOOD FAULT DETECTED	INTMASK1 / IMASK_PLDO7	INT_ACK1 / ACK_PLDO7	Read INT_ACK1
LDO8 power good fault	None	PGOOD FAULT DETECTED	INTMASK2 / IMASK_PLDO8	INT_ACK2 / ACK_PLDO8	Read INT_ACK2
LDO9 power good fault	None	PGOOD FAULT DETECTED	INTMASK2 / IMASK_PLDO9	INT_ACK2 / ACK_PLDO9	Read INT_ACK2
SM0 power good fault	None	PGOOD FAULT DETECTED	INTMASK2 / IMASK_PSM0	INT_ACK2 / ACK_PSM0	Read INT_ACK2
SM1 power good fault	None	PGOOD FAULT DETECTED	INTMASK2 / IMASK_PSM1	INT_ACK2 / ACK_PSM1	Read INT_ACK2
SM2 power good fault	None	PGOOD FAULT DETECTED	INTMASK2 / IMASK_PSM2	INT_ACK2 / ACK_PSM2	Read INT_ACK2
SM3 over-voltage detection	None	SM3 OVER-VOLTAGE DETECTED	INTMASK2 / IMASK_PSM3	INT_ACK2 / ACK_PSM3	Read INT_ACK2
HOT RESET FLAG STATUS	STAT2 bit 0	HI→LO OR LO→HI	INTMASK4 / IMASK_COMP	INT_ACK2 / ACK_COMPDET	Read INT_ACK2
BATSYS switch STATUS	STAT1 bit 7	HI→LO OR LO→HI	INTMASK3 / IMASKSYSSW	INT_ACK3 / ACK_PP	Read INT_ACK3
ACSYS SWITCH STATUS	STAT1 bit 6	HI→LO OR LO→HI	INTMASK3 / IMASKACSW	INT_ACK3 /ACK_PP	Read INT_ACK3
USBSYS SWITCH STATUS	STAT1 bit 5	HI→LO OR LO→HI	INTMASK3 / IMASKUSBSW	INT_ACK3 /ACK_PP	Read INT_ACK3
BATCHG SW STATUS	STAT1 bit 4	HI→LO OR LO→HI	INTMASK3 / IMASK_TERM	INT_ACK3 /ACK_PP	Read INT_ACK3
PACK HOT DETECTION	STAT1 bit 2	HI→LO OR LO→HI	INTMASK3 / IMASK_TSHUT	INT_ACK3 /ACK_CHGTEMP	Read INT_ACK3
PACK COLD DETECTION	STAT1 bit 1	HI→LO OR LO→HI	INTMASK3 / IMASKCHSTAT	INT_ACK3 /ACK_CHGTEMP	Read INT_ACK3
BATTERY INSERTION	STAT1 bit 0	HI→LO OR LO→HI	INTMASK3 / IMASKBATDET	INT_ACK3 /ACK_BATDET	Read INT_ACK3
charger timer fault	STAT2 bit 7	HI→LO OR LO→HI	INTMASK4 / IMASK_TMRFLT	INT_ACK3 /ACK_CHGSTAT	Read INT_ACK3



PARAMETER	STATUS BIT	SET INT_ACK BIT ON	MASK reg/bit	INT_ACK reg/bit	ACK clear at
DPPM loop STATUS	STAT2 bit 6	HI→LO OR LO→HI	INTMASK4 / IMASK_DPPM	INT_ACK3 /ACK_CHGSTAT	Read INT_ACK3
thermal loop STATUS	STAT2 bit 5	HI→LO OR LO→HI	INTMASK4 / IMASK_THON	INT_ACK3 /ACK_CHGSTAT	Read INT_ACK3
termination STATUS	STAT2 bit 4	HI→LO OR LO→HI	INTMASK4 / IMASK_TERM	INT_ACK3 /ACK_CHGSTAT	Read INT_ACK3
charger STAT2	STAT2 bit 1	HI→LO OR LO→HI	INTMASK4 / IMASKCHSTAT	INT_ACK3 /ACK_CHGSTAT	Read INT_ACK3
charger STAT1	STAT2 bit 2	HI→LO OR LO→HI	INTMASK4 / IMASKCHSTAT	INT_ACK3 /ACK_CHGSTAT	Read INT_ACK3
SLEEP and tshut detected	STAT2 bit 3	HI→LO OR LO→HI	INTMASK4 / IMASK_TSHUT	INT_ACK3 /ACK_CHGSTAT	Read INT_ACK3
SLEEP REQUEST DETECTED	STAT3 bit7	HI→LO OR LO→HI	INTMASK2/RSVDB10	INT_ACK4 / RSVDB86	Read INT_ACK4
AC DETection	STAT3 bit 3	HI→LO OR LO→HI	INTMASK5 / IMASKACDET	INT_ACK3 / ACK_ACDET	Read INT_ACK3
USB DETection	STAT3 bit 2	HI→LO OR LO→HI	INTMASK5 / IMAKSUSBDET	INT_ACK3 / ACKACUSBOVP	Read INT_ACK3
AC OVP	STAT3 bit 1	HI→LO OR LO→HI	INTMASK5 / IMAKSAC_OVP	INT_ACK3 / ACKACUSBOVP	Read INT_ACK3
USB OVP	STAT3 bit 0	HI→LO OR LO→HI	INTMASK5 / IMASKUSB_OVP	INT_ACK3 / ACKACUSBOVP	Read INT_ACK3
RTC ALARM1	NONE	ALARM1 DETECTED	INTMASK5 / IMAKSRTCALM1	INT_ACK3 / ACK_RTCALM1	Read INT_ACK3
RTC ALARM2	NONE	ALARM2 DETECTED	INTMASK4 / IMASKRTCALM2	INT_ACK4 / ACK_RTCALM2	Read INT_ACK4
RESUME command	STAT3 bit 5	HI→LO OR LO→HI	INTMASK5 / IMASKRESUME	INT_ACK4 / ACK_RESUME	Read INT_ACK4
LOWSYS detection	STAT3 bit 6	HI→LO OR LO→HI	INTMASK5 / IMASKLOWSYS		
DADC0INT	STAT4 bit 0	LO→HI ONLY	INTMASK2 / IMASKADC	INT_ACK4 / ACK_ADC	Read ADC0_INT

3.66 DEVICE ID RAM REGISTER

Each device has a unique 8-bit identifier stored in the read only register VERSIONID.

Table 3-76. Device ID Register

VERSIONID [Addr 0xCD]										
Bit Number	B7 B6 B5 B4 B3 B2 B1									
Bit Name	VCRC7	VCRC6	VCRC5	VCRC4	VCRC3	VCRC2	VCRC1	VCRC0		
Device Number	VERSION IDENTIFICATION, FACTORY SET									
TPS658600	0	0	0	0	0	0	1	0		



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3.67 RAM MEMORY MAP

MEMORY AREA	ADDR	REGISTER NAME	R/W	DESCRIPTION
SUPPLY CONTROL AND	0x10	SUPPLYENA	R/W	LDO2, SM0, SM1 ENABLE CONTROL
VOLTAGE SETTING	0x11	SUPPLYENB	R/W	LDO2, SM0, SM1 ENABLE CONTROL
	0x12	SUPPLYENC	R/W	LDO0, LDO1. LDO3, LDO4, LDO6, LDO7, LDO8, SM2 ENABLE CONTROL
	0x13	SUPPLYEND	R/W	LDO0, LDO1. LDO3, LDO4, LDO6, LDO7, LDO8, SM2 ENABLE CONTROL
	0x14	SUPPLYENE	R/W	TPS658600 OPERATION MODE, LDO5, LDO9 ENABLE CONTROL
	0x20	VCC1	R/W	SM0, SM1, LDO2, LDO4 VOLTAGE SELECTION / CHANGE CONTROL
	0x21	VCC2	R/W	SM0, SM1, LDO2, LDO4 VOLTAGE SELECTION / CHANGE CONTROL
	0x23	SM1V1	R/W	SM1 VOLTAGE SETTING #1
	0x24	SM1V2	R/W	SM1 VOLTAGE SETTING #2
	0x25	SM1SL	R/W	SM1 SLEW RATE
	0x26	SM0V1	R/W	SM0 VOLTAGE SETTING #1
	0x27	SM0V2	R/W	SM0 VOLTAGE SETTING #2
	0x28	SM0SL	R/W	SM0 SLEW RATE
	0x29	LDO2AV1	R/W	LDO2 VOLTAGE SETTING #1
	0x2A	LDO2AV2	R/W	LDO2 VOLTAGE SETTING #2
	0x2F	LDO2BV1	R/W	LDO2 VOLTAGE SETTING #1
	0x30	LDO2BV2	R/W	LDO2 VOLTAGE SETTING #2
	0x32	LDO4V1	R/W	LDO4 VOLTAGE SETTING # 1
	0x33	LDO4V2	R/W	LDO4 VOLTAGE SETTING # 2
CONVERTER SETTINGS	0x41	SUPPLYV1	R/W	LDO1, LDO0 OUPUT VOLTAGE
	0x42	SUPPLYV2	R/W	SM2, LDO8 OUTPUT VOLTAGE
	0x43	SUPPLYV3	R/W	LDO6, LDO7 OUTPUT VOLTAGE
	0x44	SUPPLYV4	R/W	RTC_LDO, LDO3 OUTPUT VOLTAGE, RTC_LDO ON/OFF
	0x45	SUPPLYV5	R/W	SPARE
	0x46	SUPPLYV6	R/W	LDO5, LDO9 OUTPUT VOLTAGE
	0x47	SMODE1	R/W	SM0, SM1, SM2, PWM/PFM MODE SETTING
	0x48	SMODE2	R/W	SPARE
CHARGER SETUP RAM	0x49	CHG1	R/W	CHARGER SETTINGS
	0x4A	CHG2	R/W	CHARGER SETTINGS
	0x4B	CHG3	R/W	CHARGER SETTING
POWER PATH SETUP RAM	0x4C	PPATH2	R/W	OUT POWER PATH SETTINGS
TPS658600	0x4D	PGFLTMSK1	R/W	POWER GOOD FAULT MASK
SEQUENCING	0x4E	PGFLTMSK2	R/W	POWER GOOD FAULT MASK
	0xCC	SPARE2	R/W	REBOOT CYCLE FLAG RESET



MEMORY AREA	ADDR hex	REGISTER NAME	ACC	DESCRIPTION			
PERIPHERAL	0X50	RGB1FLASH	R/W	RGB1R/G/B DRIVERS FLASH MODE SETTINGS			
CONTROL RAM	0X51	RGB1RED	R/W	RGB1 RED DRIVER INTENSITY CONTROL			
	0X52	RGB1GREEN	R/W	RGB1 GREEN DRIVER INTENSITY CONTROL			
	0X53	RGB1BLUE	R/W	RGB1 BLUE DRIVER INTENSITY CONTROL			
	0X54	RGB2RED	R/W	RGB2 RED DRIVER INTENSITY CONTROL			
	0X55	RGB2GREEN	R/W	RGB2 GREEN DRIVER INTENSITY CONTROL			
	0X56	RGB2BLUE	R/W	RGB2 BLUE DRIVER INTENSITY CONTROL			
	0X57	SM3_SET0	R/W	WHITE LED DUTY CYCLE SETTINGS			
	0X58	SM3_SET1	R/W	WHITE LED DUTY CYCLE SETTINGS			
	0X59	LED_PWM	R/W	LED_PWM DRIVER DUTY CYCLE SETTINGS			
	0X5A	DIG_PWM	R/W	DIG_PWM DRIVER DUTY CYCLE SETTINGS			
	0X5B	PWM	R/W	PWM DRIVER DUTY CYCLE SETTINGS			
	0X5C	DIG_PWM1	R/W	DIG_PWM1 DRIVER DUTY CYCLE SETTINGS			
	0X5D	GPIOSET1	R/W	GPIO CONFIGURATION			
	0X5E	GPIOSET2	R/W	GPIO CONFIGURATION			
ADC0 ENGINE	0x60	ADCANLG	R/W	adc input bias and filter control			
SETUP RAM	0X61	ADC0_SET	R/W	ADC0 CONVERSION CYCLE SETUP			
	0X62	ADC0_WAIT	R/W	ADC0 CONVERSION CYCLE SETUP			
	0X63	ADC0_HILIMIT2	R/W	ADC0 HI LIMIT THRESHOLD			
	0X64	ADC0_HILIMIT1	R/W	ADC0 HI LIMIT THRESHOLD			
	0X65	ADC0_LOLIMIT2	R/W	ADC0 LO LIMIT THRESHOLD			
	0X66	ADC0_LOLIMIT1	R/W	ADC0 LO LIMIT THRESHOLD			
	0X67	ADC0_DELAY	R/W	ADC0 TRIGGER MODE			
ADC0 ENGINE	0x94	ADC0_SUM2	R	SUM OF ALL SAMPLES			
DATA RAM	0x95	ADC0_SUM1	R	SUM OF ALL SAMPLES			
	0x96	ADC0_MAX2	R	MAX SAMPLE VALUE			
	0x97	ADC0_MAX1	R	MAX SAMPLE VALUE			
	0x98	ADC0_MIN2	R	MIN SAMPLE VALUE			
	0x99	ADC0_MIN1	R	MIN SAMPLE VALUE			
	0x9A	ADC0_INT	R	ADC0 STATUS			
INTERRUPT	0xB0	INT_MASK1	R/W	INT_MASK			
CONTROL RAM	0xB1	INT_MASK2	R/W	INT MASK			
	0xB2	INT_MASK3	R/W	INT MASK			
	0xB3	INT_MASK4	R/W	INT MANAGEMENT			
	0xB4	INT_MASK5	R/W	INT MANAGEMENT			
	0xB5	INT_ACK1	R/W	INT MANAGEMENT REGISTER			
	0xB6	INT_ACK2	R/W	INT MANAGEMENT REGISTER			
	0xB7	INT_ACK3	R/W	INT MANAGEMENT REGISTER			
	0xB8	INT_ACK4	R/W	INT MANAGEMENT REGISTER			
SYSTEM	0xB9	STAT1	R	power path switches, pack status			
STATUS RAM	0xBA	STAT2	R	charger status			
	0xBB	STAT3	R	rtc, input power status			
	0xBC	STAT4	R	ADC STATUS			



MEMORY AREA	ADDR hex	REGISTER NAME	ACC	DESCRIPTION
RTC	0xC0	RTC_CTRL	R/W	RTC CONTROL REGISTER
	0XC1	RTC ALARM		RTC ALARM
	0xC2			
	0xC3			
	0xC4			
	0xC5			
	0xC6	RTC COUNTER	R/W	RTC DATA
	0xC7			
	0xC8			
	0xC9			
	0xCA			
DEVICE ID	0XCD	VERSIONCRC	R	Device identification

TEXAS INSTRUMENTS

4 APPLICATION INFORMATION

4.1 DC/DC CONVERTER OUTPUT FILTER

4.1.1 Inductor Selection

The typical value for the converter inductor is 2.2µH output inductor. Larger or smaller inductor values can be used to optimize the performance of the device for specific operation conditions. The selected inductor has to be rated for its DC resistance and saturation current. The DC resistance of the inductance will influence directly the efficiency of the converter. Therefore an inductor with lowest DC resistance should be selected for highest efficiency. See document SLVA157 for more information on inductor selection.

Equation 16 calculates the maximum inductor current under static load conditions. The saturation current of the inductor should be rated higher than the maximum inductor current as calculated with Equation 16. This is recommended because during heavy load transient the inductor current will rise above the calculated value.

$$\Delta I_{L} = \text{Vout} \times \frac{1 - \frac{\text{Vout}}{\text{Vin}}}{L \times f}$$

$$I_{Lmax} = I_{outmax} + \frac{\Delta I_{L}}{2}$$
(16)

with:

f = Switching Frequency (2.25MHz typical)

L = Inductor Value

ΔI_L= Peak to Peak inductor ripple current

I_{Lmax} = Maximum Inductor current

The highest inductor current will occur at maximum Vin.

Open core inductors have a soft saturation characteristic and they can usually handle higher inductor currents versus a comparable shielded inductor. A more conservative approach is to select the inductor current rating just for the maximum switch current of the corresponding converter. It must be considered, that the core material from inductor to inductor differs and will have an impact on the efficiency especially at high switching frequencies.

Refer to Table 4-1 and the typical applications for possible inductors.

INDUCTANCE TYP DIMENSIONS **SUPPLY INDUCTOR TYPE SUPPLIER** [µH] [mm] SM₀ LPS4012-152 1.5 Coilcraft 4x4x1 1.5 TDK VLS4012-1R5N1R5 4x4x1 LPS4012-152 1.5 Coilcraft 4x4x1 SM1 TDK VLS4012-1R5N1R5 1.5 4x4x1 SM₂ LPS4414-152MLx 1.5 Coilcraft 4x4x1.5 1008PS-152Kx 1.5 4x4x2.5 Coilcraft 4.7 SM3 DO2010-472 Coilcraft 2x2x1 4.7 TDK VLS3012-47M1R0 3x3x1

Table 4-1. Inductors

4.1.2 Output Capacitor Selection

The advanced Fast Response voltage mode control scheme of the two converters allow the use of small ceramic capacitors with a typical value of 22µF, without having large output voltage under and overshoots during heavy load transients. Ceramic capacitors having low ESR values result in lowest output voltage ripple and are therefore recommended. Refer to for recommended components.

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If ceramic output capacitors are used the capacitor RMS ripple current rating will always meet the application requirements. Just for completeness the RMS ripple current is calculated as:

$$I_{RMSCout} = Vout \times \frac{1 - \frac{Vout}{Vin}}{L \times f} \times \frac{1}{2 \times \sqrt{3}}$$
(17)

At nominal load current the inductive converters operate in PWM mode and the overall output voltage ripple is the sum of the voltage spike caused by the output capacitor ESR plus the voltage ripple caused by charging and discharging the output capacitor:

$$\Delta Vout = Vout \times \frac{1 - \frac{Vout}{Vin}}{L \times f} \times \left(\frac{1}{8 \times Cout \times f} + ESR\right)$$
(18)

Where the highest output voltage ripple occurs at the highest input voltage Vin.

At light load currents the converters operate in Power Save Mode and the output voltage ripple is dependent on the output capacitor value. The output voltage ripple is set by the internal comparator delay and the external capacitor. The typical output voltage ripple is less than 1% of the nominal output voltage.

4.1.3 Input Capacitor Selection

Because of the nature of the buck converter having a pulsating input current, a low ESR input capacitor is required for best input voltage filtering and minimizing the interference with other circuits caused by high input voltage spikes. The converters need a ceramic input capacitor of 10µF. The input capacitor can be increased without any limit for better input voltage filtering.

Table 4-2. Capacitors

22 μF	0805	TDK C2012X5R0J226MT	Ceramic
22 μF	0805	Taiyo Yuden JMK212BJ226MG	Ceramic
10 μF	0805	Taiyo Yuden JMK212BJ106M	Ceramic
10 μF	0805	TDK C2012X5R0J106M	Ceramic

4.2 **XTAL OSCILLATOR PCB – GENERAL GUIDELINES**

Table 4-3. External Crystal Specifications

EXTERNAL CRYSTAL REQUIREMENTS [TYP CRYSTAL - EPSON MC146]								
PARAMETER	DESCRIPTION		MIN	TYP	MAX	UNIT		
Fosc	Nominal crystal resonant frequency			32.768		kHz		
Frequency Tolerance	ΔF/F _{OSC}		-20		20	ppm		
В	Parabolic Temp Co				0.04×10 ⁻⁶	1/°C ²		
ESR	Equivalent Series Resistance				65	kΩ		
C _{LOAD}	Load Capacitance			7		pF		
C _{SHUNT}	Shunt capacitance		0.5	0.8	1.2	pF		
P _{DRIVE}	Drive power			0.5	1	μW		
Aging			-3		3	ppm/Yr		

The jitter observed in the OUT32K pin is heavily dependent on the board layout close to the XTAL1 and XTAL2 pins. The following layout/assembly procedures are recommended:

- Layout a good ground plane around the oscillator pins.
- Prevent crosstalk from other clock or data lines into oscillator pins XIN and XOUT.

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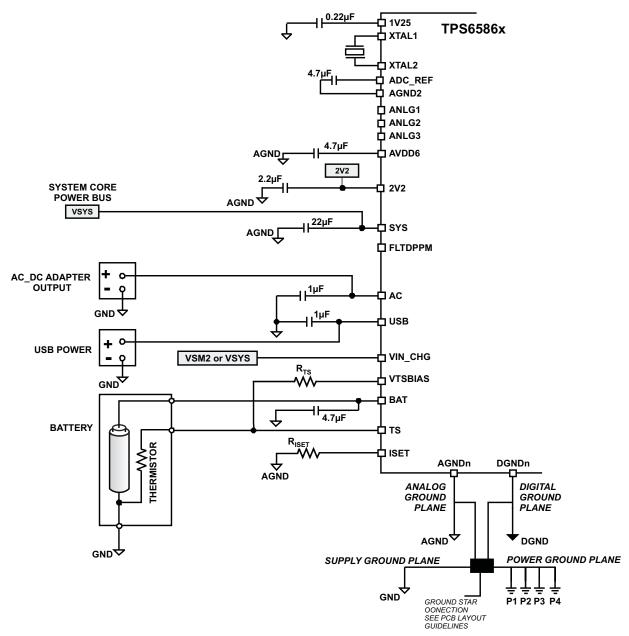


- Avoid running PCB traces underneath or adjacent to the XIN and XOUT pins.
- Use assembly materials and praxis to avoid any parasitic load on the oscillator XIN and XOUT pins.
- If conformal coating is used, ensure that it does not induce capacitive/resistive leakage between the oscillator pins.
- External capacitance is recommended for precision real-time clock applications.

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4.3 **APPLICATION CIRCUIT**

Power Path , Charger, ADC, RTC and Ground Plane 4.3.1

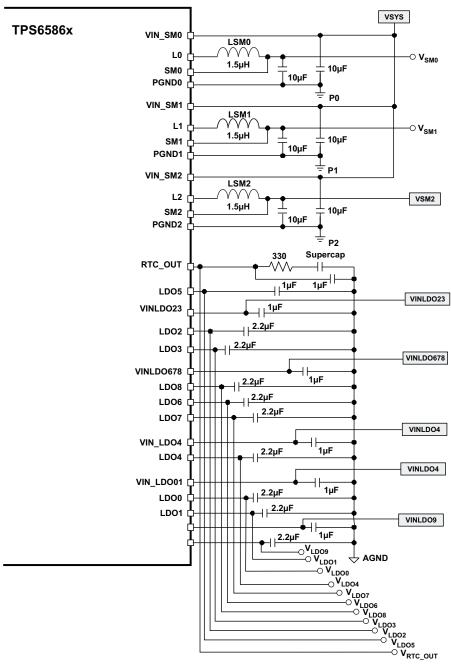


(1) VIN_CHG should be connected to VSYS when SM2 is not configured as the charger pre-regulator stage

Figure 4-1. Power Path, Charger, ADC, RTC Connections

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4.3.2 Integrated Supplies



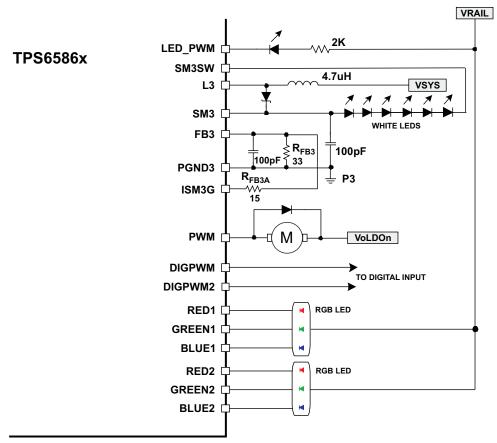
- (1) VIN_SMn pins must be always connected to VSYS .
- (2) The supply input pins must be connected to VSYS or to the output of a supply which is powered from VSYS

Figure 4-2. Supply Rail Connections



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4.3.3 Display and Peripherals

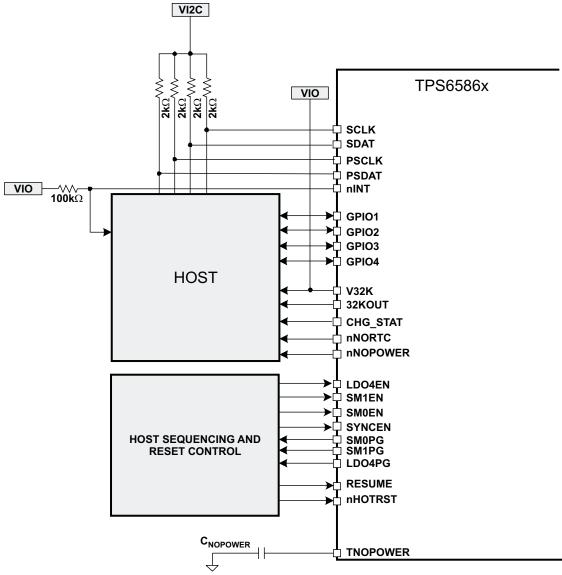


- (1) PWM pin shown as driving an external vibrator motor, with vibrator supply connected to LDOn output
- (2) VRAIL can be the output of any of the TPS658600 integrated supplies or the SYS pin
- (3) 1. DIGPWM, DIGPWM2 are push-pull outputs

Figure 4-3. Display and PWM Connections

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4.3.4 Host Connections



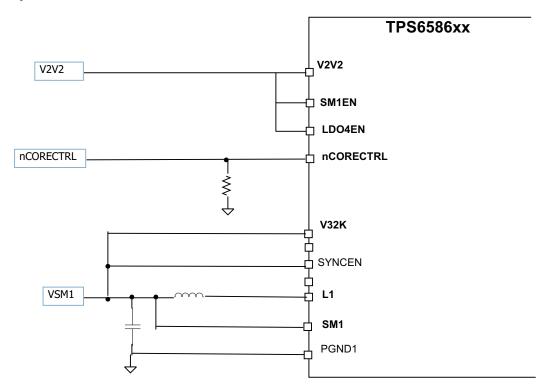
- (1) Those are generic connections only, see App Notes for host specific connectivity
- (2) VIO should be connected to the TPS658600 rail that powers the host I/O domain
- (3) VI2C should be connected to 2v2 or to the TPS658600 rail that powers the host I²C engine domain

Figure 4-4. Generic Host and Sequencing Circuit Connections



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4.3.5 Sequence Connections



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4.3.6 Sequence Timing (TPS658600)

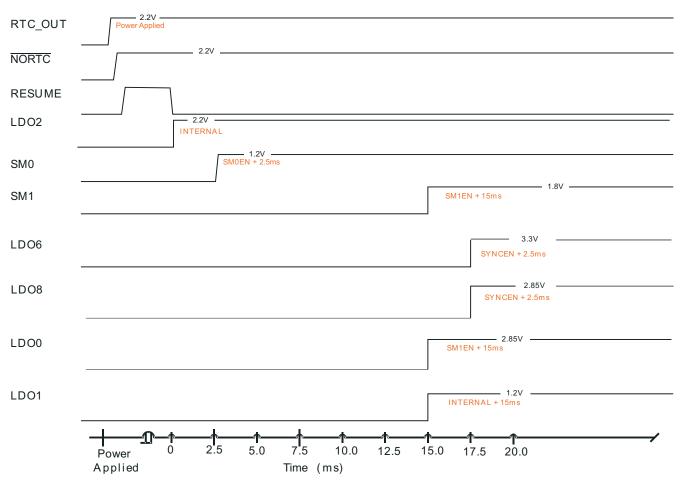


Figure 4-5. Sequence Timing

PACKAGE OPTION ADDENDUM

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PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TPS658600ZQZR	PREVIEW	BGA MI CROSTA R JUNI OR	ZQZ	120	2500	TBD	Call TI	Call TI
TPS658600ZQZT	PREVIEW	BGA MI CROSTA R JUNI OR	ZQZ	120	250	TBD	Call TI	Call TI

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

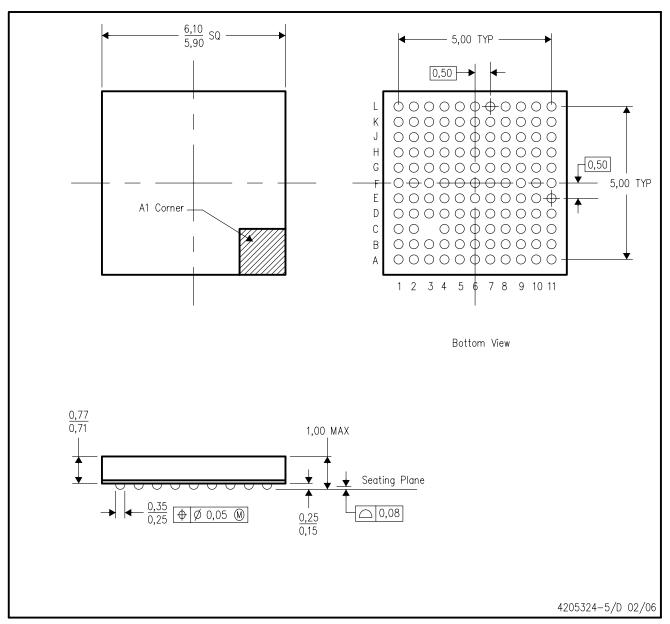
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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ZQZ (S-PBGA-N120)

PLASTIC BALL GRID ARRAY



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-225
- D. This package is lead-free.



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